



## Features

- Multi channel half-duplex transceiver with approximately  $\pm 2.5\text{MHz}$  programmable tuning range
- High FSK sensitivity:  $-106\text{dBm}$  at  $20\text{Kbit/s}$  /  $-109.5\text{dBm}$  at  $2.4\text{Kbit/s}$  ( $433.92\text{MHz}$ )
- High ASK sensitivity:  $-112.5\text{dBm}$  at  $10\text{Kbit/s}$  /  $-116.5\text{dBm}$  at  $2.4\text{Kbit/s}$  ( $433.92\text{MHz}$ )
- Low supply current:  $10.5\text{mA}$  in RX and TX Mode ( $3\text{V/TX}$  with  $5\text{dBm}$ )
- Data Rate: 1 to  $20\text{Kbit/s}$  Manchester FSK, 1 to  $10\text{Kbit/s}$  Manchester ASK
- ASK/FSK receiver uses a low-IF architecture with high selectivity, blocking, and low intermodulation (typical blocking  $55\text{dB}$  at  $\pm 750\text{kHz}$  /  $61\text{dB}$  at  $\pm 1.5\text{MHz}$  and  $70\text{dB}$  at  $\pm 10\text{MHz}$ , system I1dBCP =  $-30\text{dBm}$  / system IIP3 =  $-20\text{dBm}$ )
- $226\text{kHz}/237\text{kHz}$  IF frequency with  $30\text{dB}$  image rejection and  $170\text{kHz}$  usable IF bandwidth
- Transmitter uses closed loop fractional-N synthesizer for FSK modulation with a high PLL bandwidth and an excellent isolation between PLL/VCO and PA
- Tolerances of XTAL compensated by fractional-N synthesizer with  $800\text{Hz}$  RF resolution
- Integrated RX/TX-switch, single-ended RF input and output
- RSSI (Received Signal Strength Indicator)
- Communication to microcontroller with SPI interface working at max.  $500\text{kbit/s}$
- Configurable self polling and RX/TX protocol handling with FIFO-RAM buffering of received and transmitted data
- Five push button inputs and one wake-up input are active in power-down mode
- integrated XTAL capacitors
- PA efficiency: up to  $38\%$  ( $433.92\text{MHz}/10\text{dBm}/3\text{V}$ )
- Low in-band sensitivity change of typically  $\pm 1.8\text{dB}$  within  $\pm 58\text{kHz}$  center frequency change in the complete temperature and supply voltage range
- Supply voltage switch, supply voltage regulator, reset generation, clock/interrupt generation and low battery indicator for microcontroller

- Fully integrated PLL with low phase noise VCO, PLL loop filter and full support of multi-channel operation with arbitrary channel distance due to fractional-N synthesizer
- Sophisticated threshold control and quasi-peak detector circuit in the data slicer
- Power management via different operation modes
- 433.92MHz and 868.3MHz without external VCO and PLL components
- Inductive supply with voltage regulator if battery is empty (AUX mode)
- Efficient XTO start-up circuit ( $> -1.5k\Omega$  worst case real start-up impedance)
- Changing of modulation type ASK/FSK and data rate without component changes
- Minimal external circuitry requirements for complete system solution
- Adjustable output power: 0 to 10dBm adjusted and stabilized with external resistor
- ESD protection at all pins (1.5kV HBM, 200V MM, 1kV FCDM)
- Supply voltage range: 2.4V to 3.6V or 4.4V to 6.6V
- Temperature range:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$
- Small  $7 \times 7\text{mm}$  QFN48 package

## Applications

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- Consumer industrial segment
- Access control systems
- Remote control systems
- Alarm and telemetry systems
- Energy metering
- Home automation

## Benefits

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- Low system cost due to very high system integration level
- Only one crystal needed in system
- Less demanding specification for the microcontroller due to handling of power-down mode, delivering of clock, reset, low battery indication and complete handling of receive/transmit protocol and polling
- Single-ended design with high isolation of PLL/VCO from PA and the power supply allows a loop antenna in the remote control unit to surround the whole application

## 1. General Description

The ATA5428 is a highly integrated UHF ASK/FSK multi-channel half-duplex transceiver with low power consumption supplied in a small 7 x 7mm QFN48 package. The receive part is built as a fully integrated low-IF receiver, whereas direct PLL modulation with the fractional-N synthesizer is used for FSK transmission and switching of the power amplifier for ASK transmission.

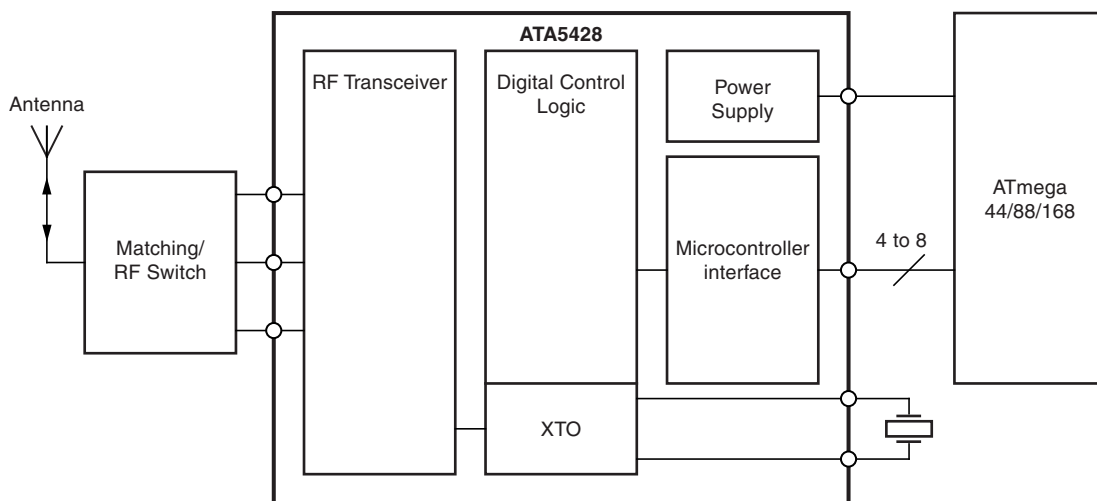
The device supports data rates of 1Kbit/s to 20Kbit/s (FSK) and 1Kbit/s to 10Kbit/s (ASK) in Manchester, Bi-phase and other codes in transparent mode. The ATA5428 can be used in the 431.5MHz to 436.5MHz and in the 862MHz to 872MHz bands. The very high system integration level results in a small number of external components needed.

Due to its blocking and selectivity performance, together with the additional 15dB to 20dB loss and the narrow bandwidth of a typical loop antenna in a remote control unit, a bulky blocking SAW is not needed in the remote control unit. Additionally, the building blocks needed for a typical remote control and access control system on both sides (the base and the mobile stations) are fully integrated.

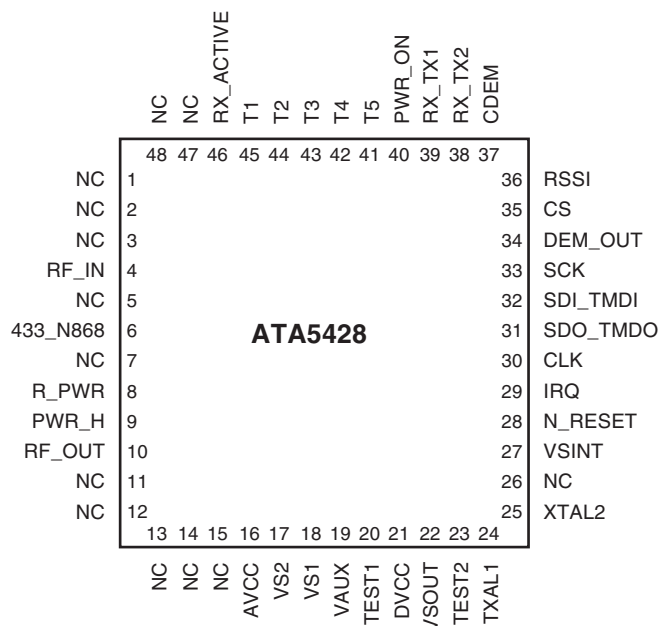
Its digital control logic with self-polling and protocol generation enables a fast challenge-response system without using a high-performance microcontroller. Therefore, the ATA5428 contains a FIFO buffer RAM and can compose and receive the physical messages themselves. This provides more time for the microcontroller to carry out other functions such as calculating crypto algorithms, composing the logical messages, and controlling other devices. Therefore, a standard 4-/8-bit microcontroller without special periphery and clocked with the CLK output of about 4.5MHz is sufficient to control the communication link. This is especially valid for passive entry and access control systems, where within less than 100ms several challenge-response communications with arbitration of the communication partner have to be handled.

It is hence possible to design bi-directional remote control and access control systems with a fast challenge-response crypto function, with the same PCB board size and with the same current consumption as uni-directional remote control systems.

**Figure 1-1. System Block Diagram**



**Figure 1-2. Pinning QFN48**



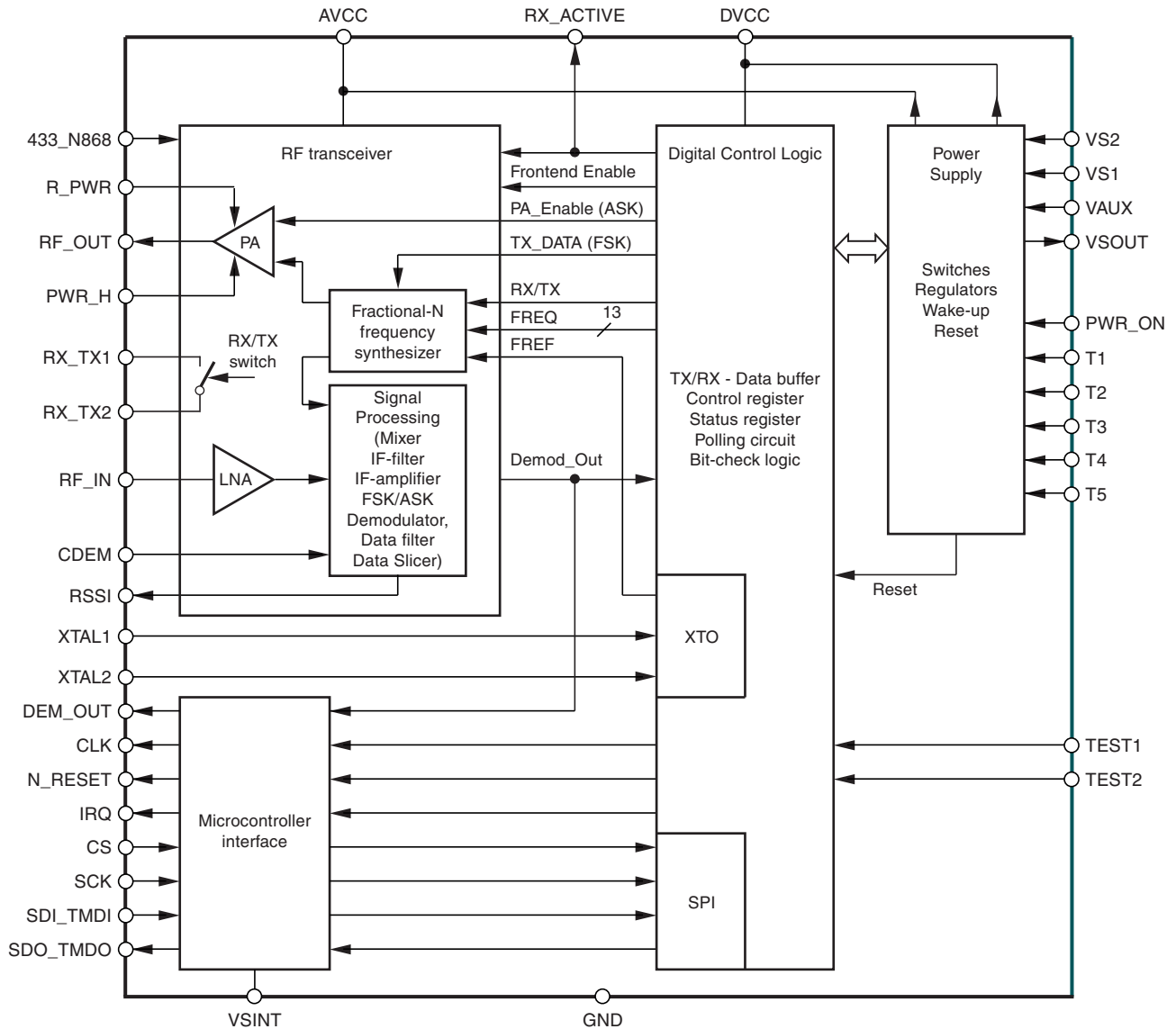
**Table 1-1. Pin Description**

| Pin | Symbol   | Function                                          |
|-----|----------|---------------------------------------------------|
| 1   | NC       | Not connected                                     |
| 2   | NC       | Not connected                                     |
| 3   | NC       | Not connected                                     |
| 4   | RF_IN    | RF input                                          |
| 5   | NC       | Not connected                                     |
| 6   | 433_N868 | Selects RF input/output frequency range           |
| 7   | NC       | Not connected                                     |
| 8   | R_PWR    | Resistor to adjust output power                   |
| 9   | PWR_H    | Pin to select output power                        |
| 10  | RF_OUT   | RF output                                         |
| 11  | NC       | Not connected                                     |
| 12  | NC       | Not connected                                     |
| 13  | NC       | Not connected                                     |
| 14  | NC       | Not connected                                     |
| 15  | NC       | Not connected                                     |
| 16  | AVCC     | Blocking of the analog voltage supply             |
| 17  | VS2      | Power supply input for voltage range 4.4V to 6.6V |
| 18  | VS1      | Power supply input for voltage range 2.4V to 3.6V |

**Table 1-1. Pin Description (Continued)**

| Pin | Symbol    | Function                                                            |
|-----|-----------|---------------------------------------------------------------------|
| 19  | VAUX      | Auxiliary supply voltage input                                      |
| 20  | TEST1     | Test input, at GND during operation                                 |
| 21  | DVCC      | Blocking of the digital voltage supply                              |
| 22  | VSOUT     | Output voltage power supply for external devices                    |
| 23  | TEST2     | Test input, at GND during operation                                 |
| 24  | XTAL1     | Reference crystal                                                   |
| 25  | XTAL2     | Reference crystal                                                   |
| 26  | NC        | Not connected                                                       |
| 27  | VSINT     | Microcontroller interface supply voltage                            |
| 28  | N_RESET   | Output pin to reset a connected microcontroller                     |
| 29  | IRQ       | Interrupt request                                                   |
| 30  | CLK       | Clock output to connect a microcontroller                           |
| 31  | SDO_TMDO  | Serial data out/transparent mode data out                           |
| 32  | SDI_TMDI  | Serial data in/transparent mode data in                             |
| 33  | SCK       | Serial clock                                                        |
| 34  | DEM_OUT   | Demodulator open drain output signal                                |
| 35  | CS        | Chip select for serial interface                                    |
| 36  | RSSI      | Output of the RSSI amplifier                                        |
| 37  | CDEM      | Capacitor to adjust the lower cut-off frequency data filter         |
| 38  | RX_TX2    | GND pin to decouple LNA in TX mode                                  |
| 39  | RX_TX1    | Switch pin to decouple LNA in TX mode                               |
| 40  | PWR_ON    | Input to switch on the system (active high)                         |
| 41  | T5        | Key input 5 (can also be used to switch on the system (active low)) |
| 42  | T4        | Key input 4 (can also be used to switch on the system (active low)) |
| 43  | T3        | Key input 3 (can also be used to switch on the system (active low)) |
| 44  | T2        | Key input 2 (can also be used to switch on the system (active low)) |
| 45  | T1        | Key input 1 (can also be used to switch on the system (active low)) |
| 46  | RX_ACTIVE | Indicates RX operation mode                                         |
| 47  | NC        | Not connected                                                       |
| 48  | NC        | Not connected                                                       |
|     | GND       | Ground/backplane                                                    |

**Figure 1-3. Block Diagram**

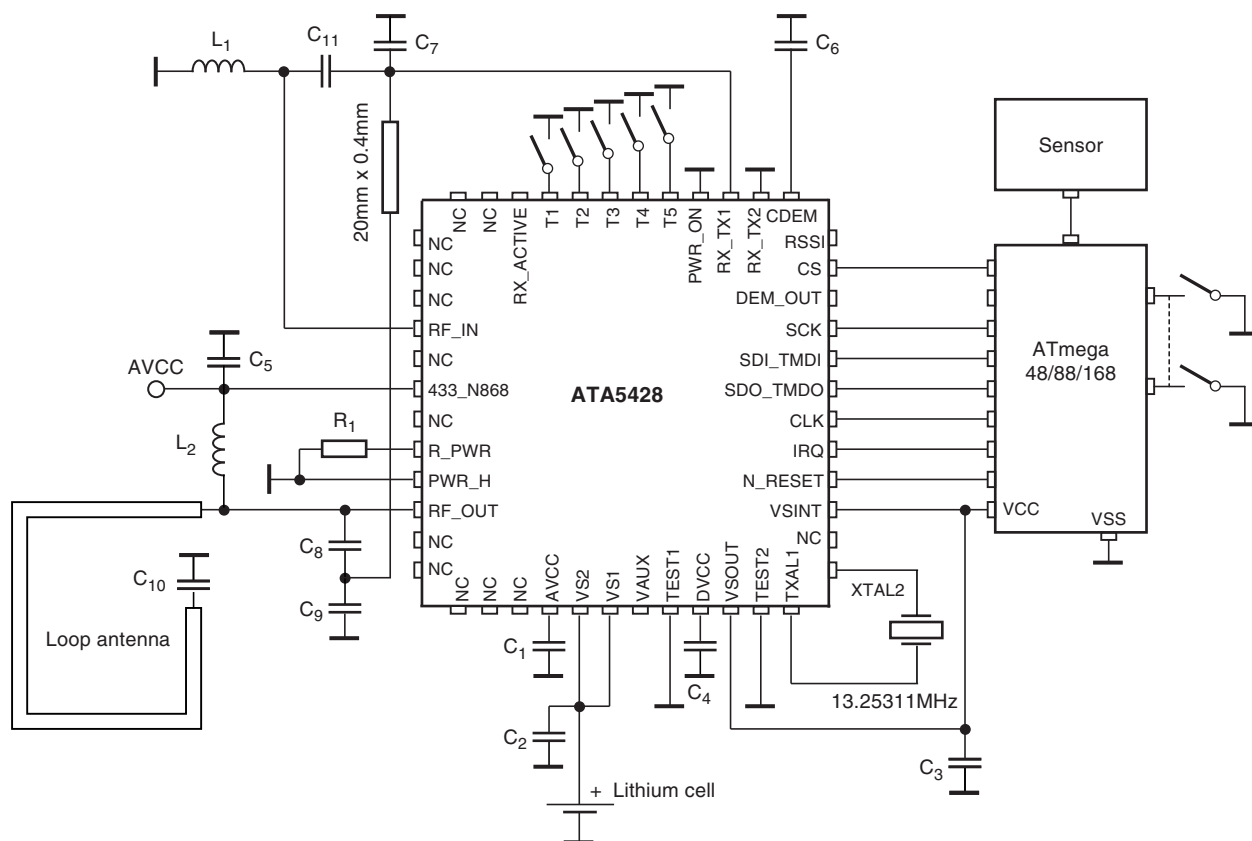


## 2. Application Circuits

### 2.1 Typical Remote Control Unit Application with 1 Li Battery (3V)

Figure 2-1 shows a typical 433.92MHz Remote Control Unit application with one battery. The external components are 11 capacitors, 1 resistor, 2 inductors and a crystal.  $C_1$  to  $C_4$  are 68nF voltage supply blocking capacitors.  $C_5$  is a 10nF supply blocking capacitor.  $C_6$  is a 15nF fixed capacitor used for the internal quasi-peak detector and for the high-pass frequency of the data filter.  $C_7$  to  $C_{11}$  are RF matching capacitors in the range of 1pF to 33pF.  $L_1$  is a matching inductor of about 5.6nH to 56nH.  $L_2$  is a feed inductor of about 120nH. A load capacitor of 9pF for the crystal is integrated.  $R_1$  is typically 22k $\Omega$  and sets the output power to about 5.5dBm. The loop antenna's quality factor is somewhat reduced by this application due to the quality factor of  $L_2$  and the RX/TX switch. On the other hand, this lower quality factor is necessary to have a robust design with a bandwidth that is broad enough for production tolerances. Due to the single-ended and ground-referenced design, the loop antenna can be a free-form wire around the application as it is usually employed in remote control uni-directional systems. The ATA5428 provides sufficient isolation and robust pulling behavior of internal circuits from the supply voltage as well as an integrated VCO inductor to allow this. Since the efficiency of a loop antenna is proportional to the square of the surrounded area it is beneficial to have a large loop around the application board with a lower quality factor in order to relax the tolerance specification of the RF components and to get a high antenna efficiency in spite of their lower quality factor.

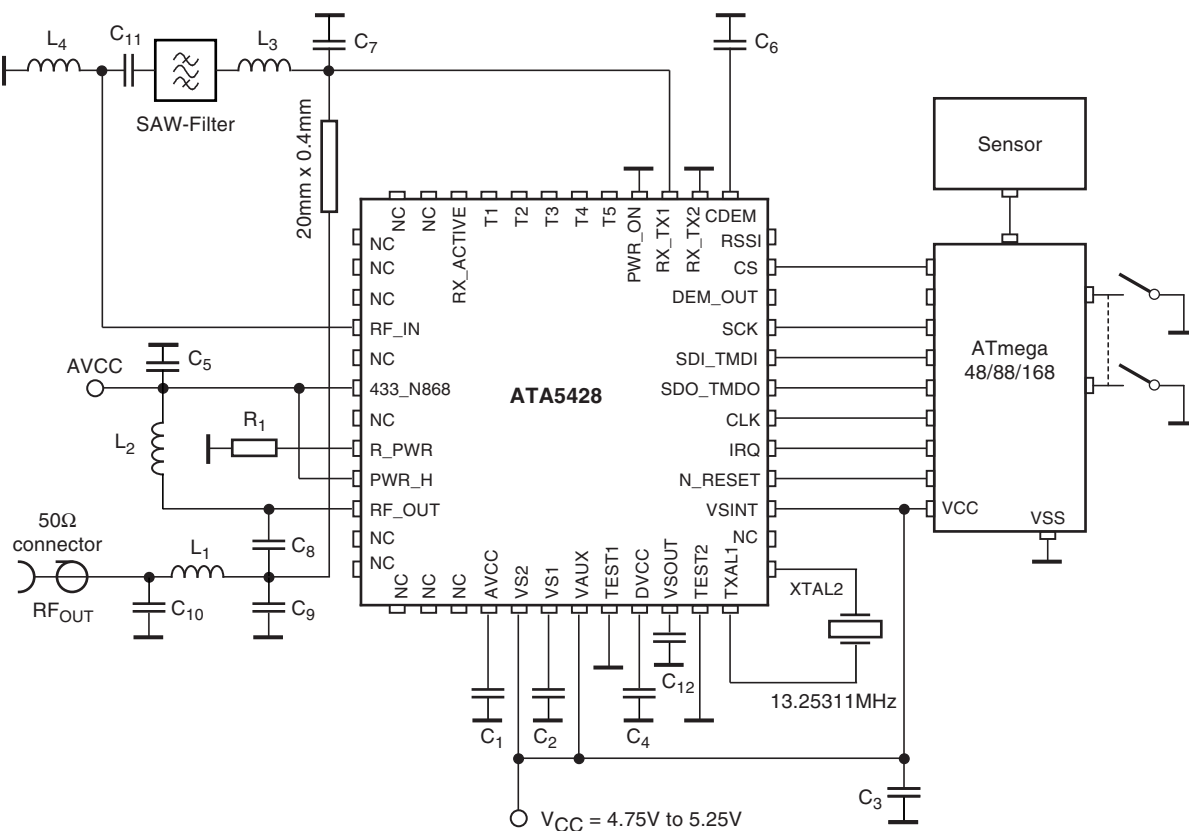
Figure 2-1. Typical Remote Control Unit Application, 433.92MHz, 1 Li Battery (3V)



## 2.2 Typical Base-station Application (5V)

Figure 2.2 shows a typical 433.92MHz  $V_{CC} = 4.75V$  to  $5.25V$  Base-station Application (5V). The external components are 12 capacitors, 1 resistor, 4 inductors, a SAW filter, and a crystal.  $C_1$  and  $C_3$  to  $C_4$  are 68nF voltage supply blocking capacitors.  $C_2$  and  $C_{12}$  are 2.2 $\mu F$  supply blocking capacitors for the internal voltage regulators.  $C_5$  is a 10nF supply blocking capacitor.  $C_6$  is a 15 nF fixed capacitor used for the internal quasi-peak detector and for the high-pass frequency of the data filter.  $C_7$  to  $C_{11}$  are RF matching capacitors in the range of 1pF to 33pF.  $L_2$  to  $L_4$  are matching inductors of about 5.6nH to 56nH. A load capacitor for the crystal of 9pF is integrated.  $R_1$  is typically 22k $\Omega$  and sets the output power at RF\_OUT to about 10dBm. Since a quarter wave or PCB antenna, which has high efficiency and wide band operation, is typically used here, it is recommended to use a SAW filter to achieve high sensitivity in case of powerful out-of-band blockers.  $L_1$ ,  $C_9$  and  $C_{10}$  together form a low-pass filter, which is needed to filter out the harmonics in the transmitted signal to meet regulations. An internally regulated voltage at pin VSOUT can be used in case the microcontroller only supports 3.3V operation, a blocking capacitor with a value of  $C_{12} = 2.2\mu F$  has to be connected to VSOUT in any case.

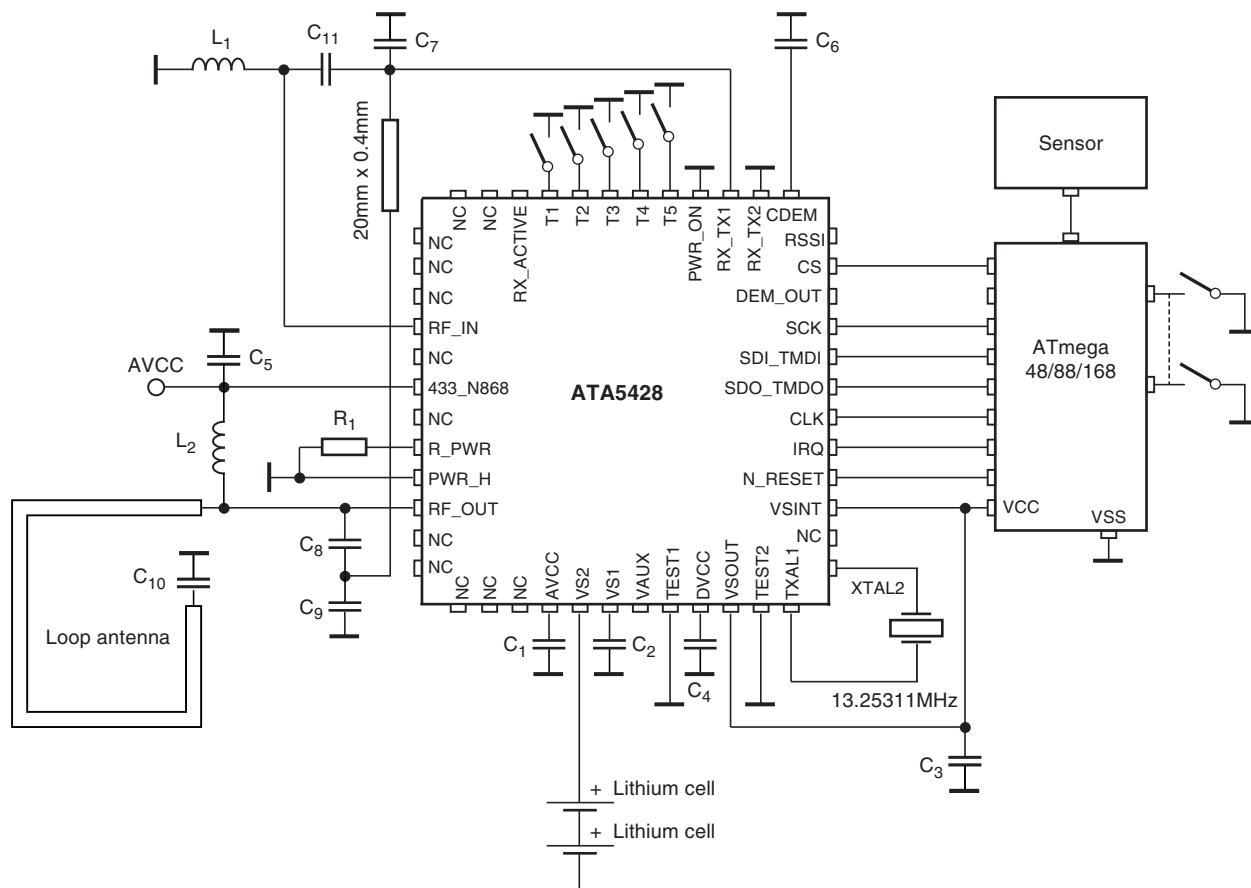
Figure 2-2. Typical Base-station Application (5V), 433.92MHz



### 2.3 Typical Remote Control Unit Application, 2 Li Batteries (6V)

Figure 2-3 shows a typical 433.92Hz 2 Li battery Remote Control Unit application. The external components are 11 capacitors, 1 resistor, 2 inductors and a crystal.  $C_1$  and  $C_4$  are 68nF voltage supply blocking capacitors.  $C_2$  and  $C_3$  are 2.2 $\mu$ F supply blocking capacitors for the internal voltage regulators.  $C_5$  is a 10nF supply blocking capacitor.  $C_6$  is a 15nF fixed capacitor used for the internal quasi-peak detector and for the high-pass frequency of the data filter.  $C_7$  to  $C_{11}$  are RF matching capacitors in the range of 1pF to 33pF.  $L_1$  is a matching inductor of about 5.6nH to 56nH.  $L_2$  is a feed inductor of about 120nH. A load capacitor for the crystal of 9pF is integrated.  $R_1$  is typically 22k $\Omega$  and sets the output power to about 5.5dBm.

**Figure 2-3. Typical Remote Control Unit Application, 433.92MHz, 2 Li Batteries (6V)**



### 3. RF Transceiver

As seen in [Figure 1-3 on page 6](#), the RF transceiver consists of an LNA (Low-noise Amplifier), PA (Power Amplifier), RX/TX switch, fractional-N frequency synthesizer and the signal processing part with mixer, IF filter, IF amplifier with analog RSSI, FSK/ASK demodulator, data filter, and data slicer.

In receive mode the LNA pre-amplifies the received signal which is converted down to 226kHz (ATA5428), filtered and amplified before it is fed into an FSK/ASK demodulator, data filter, and data slicer. The RSSI (Received Signal Strength Indicator) signal and the raw digital output signal of the demodulator are available at the pins RSSI and DEM\_OUT. The demodulated data signal Demod\_Out is fed to the digital control logic where it is evaluated and buffered as described in section “[Digital Control Logic](#)” on [page 31](#).

In transmit mode, the fractional-N frequency synthesizer generates the TX frequency which is fed to the PA. In ASK mode the PA is modulated by the signal PA\_Enable. In FSK mode the PA is enabled and the signal TX\_DATA (FSK) modulates the fractional-N frequency synthesizer. The frequency deviation is digitally controlled and internally fixed to about  $\pm 16$ kHz (see [Table 4-1 on page 23](#) for exact values). The transmit data can also be buffered as described in section “[Digital Control Logic](#)” on [page 31](#). A lock detector within the synthesizer ensures that the transmission will start only if the synthesizer is locked.

The RX/TX switch can be used to combine the LNA input and the PA output to a single antenna with a minimum of losses.

Transparent modes without buffering of RX and TX data are also available to allow protocols and coding schemes other than the internally supported Manchester encoding.

#### 3.1 Low-IF Receiver

The receive path consists of a fully integrated low-IF receiver. It fulfills the sensitivity, blocking, selectivity, supply voltage and supply current specification needed to manufacture, for example, an automotive remote control unit without the use of SAW blocking filter (see [Figure 2-1 on page 7](#)). In a Base-station Application (5V) the receiver can be used with an additional blocking SAW front-end filter as shown in [Figure 2.2 on page 8](#).

At 433.92MHz the receiver has a typical system noise figure of 7.0dB, a system I1dB of -30dBm and a system IIP3 of -20dBm. There is no AGC or switching of the LNA needed; thus, a better blocking performance is achieved. This receiver uses an IF (Intermediate Frequency) of 226kHz, the typical image rejection is 30dB and the typical 3dB IF filter bandwidth is 185kHz ( $f_{IF} = 226\text{kHz} \pm 92.5\text{kHz}$ ,  $f_{lo\_IF} = 133.5\text{kHz}$  and  $f_{hi\_IF} = 318.5\text{kHz}$ ). The demodulator needs a signal to Gaussian noise ratio of 8dB for 20Kbit/s Manchester with  $\pm 16$ kHz frequency deviation in FSK mode; thus, the resulting sensitivity at 433.92MHz is typically -106dBm at 20Kbit/s Manchester.

Due to the low phase noise and spurious emissions of the synthesizer in receive mode<sup>(1)</sup> together with the eighth order integrated IF filter, the receiver has a better selectivity and blocking performance than more complex double superhet receivers but without external components and without numerous spurious receiving frequencies.

A low-IF architecture is also less sensitive to second-order intermodulation (IIP2) than direct conversion receivers, where every pulse or AM-modulated signal (especially the signals from TDMA systems like GSM) demodulates to the receiving signal band at second-order non-linearities.

Note: 1. -120dBC/Hz at  $\pm 1$ MHz and -75dBC at  $\pm \text{FREF}$  at 433.92MHz

#### 3.2 Input Matching at RF\_IN

The measured input impedances as well as the values of a parallel equivalent circuit of these impedances can be seen in the [Table 3-1](#). The highest sensitivity is achieved with power matching of these impedances to the source impedance of 50 $\Omega$ .

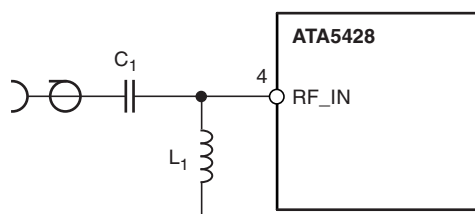
**Table 3-1. Measured Input Impedances of the RF\_IN Pin**

| $f_{RF}/\text{MHz}$ | $Z(\text{RF\_IN})$ | $R_p/C_p$           |
|---------------------|--------------------|---------------------|
| 433.92              | $(32-j169)\Omega$  | 925 $\Omega$ /2.1pF |
| 868.3               | $(21-j78)\Omega$   | 311 $\Omega$ /2.2pF |

The matching of the LNA Input to 50Ω was done with the circuit shown in [Figure 3-1](#) and with the values given in [Table 3-2 on page 11](#). The reflection coefficients were always  $\leq 10\text{dB}$ . Note that value changes of  $C_1$  and  $L_1$  may be necessary to compensate for individual board layouts. The measured typical FSK and ASK Manchester code sensitivities with a Bit Error Rate (BER) of  $10^{-3}$  are shown in [Table 3-3 on page 11](#) and [Table 3-4 on page 11](#). These measurements were done with inductors having a quality factor according to [Table 3-2 on page 11](#), resulting in estimated matching losses of 0.7dB at 433.92MHz, 0.7dB at 868.3MHz. These losses can be estimated when calculating the parallel equivalent resistance of the inductor with  $R_{\text{loss}} = 2 \times \pi \times f \times L \times Q_L$  and the matching loss with  $10 \log(1 + R_p/R_{\text{loss}})$ .

With an ideal inductor, for example, the sensitivity at 433.92MHz/FSK/20Kbit/s/±16kHz/Manchester can be improved from –106dBm to –106.7dBm. The sensitivity depends on the control logic which examines the incoming data stream. The examination limits must be programmed in control registers 5 and 6. The measurements in [Table 3-3 on page 11](#) and [Table 3-4 on page 11](#) are based on the values of registers 5 and 6 according to [Table 9-3 on page 54](#).

**Figure 3-1. Input Matching to 50Ω**



**Table 3-2. Input Matching to 50Ω**

| $f_{\text{RF}}/\text{MHz}$ | $C_1/\text{pF}$ | $L_1/\text{nH}$ | $Q_{L1}$ |
|----------------------------|-----------------|-----------------|----------|
| 433.92                     | 1.8             | 27              | 70       |
| 868.3                      | 1.2             | 6.8             | 50       |

**Table 3-3. Measured Sensitivity FSK, ±16kHz, Manchester, dBm, BER =  $10^{-3}$**

| RF Frequency | BR_Range_0<br>1.0Kbit/s | BR_Range_0<br>2.4Kbit/s | BR_Range_1<br>5.0Kbit/s | BR_Range_2<br>10Kbit/s | BR_Range_3<br>20Kbit/s |
|--------------|-------------------------|-------------------------|-------------------------|------------------------|------------------------|
| 433.92MHz    | –109.0dBm               | –109.5dBm               | –108.0dBm               | –107.0dBm              | –106.0dBm              |
| 868.3MHz     | –106.0dBm               | –106.5dBm               | –105.5dBm               | –104.0dBm              | –103.5dBm              |

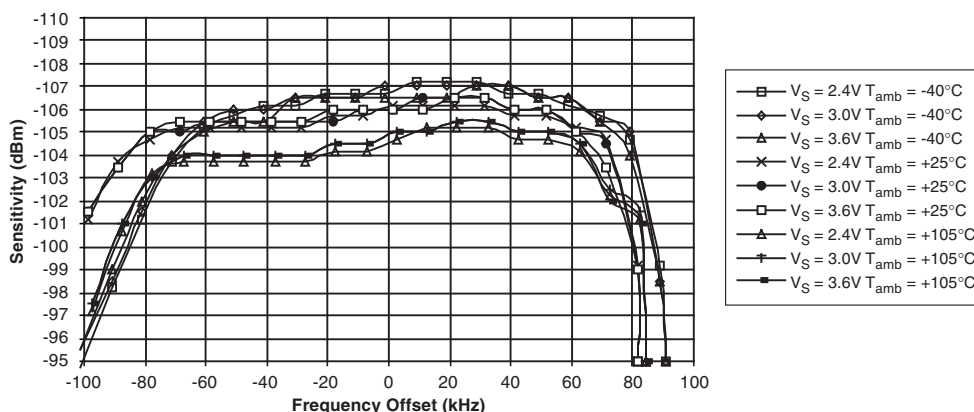
**Table 3-4. Measured Sensitivity 100% ASK, Manchester, dBm, BER =  $10^{-3}$**

| RF Frequency | BR_Range_0<br>1.0Kbit/s | BR_Range_0<br>2.4Kbit/s | BR_Range_1<br>5.0Kbit/s | BR_Range_2<br>10Kbit/s |
|--------------|-------------------------|-------------------------|-------------------------|------------------------|
| 433.92MHz    | –116.0dBm               | –116.5dBm               | –114.0dBm               | –112.5dBm              |
| 868.3MHz     | –112.5dBm               | –113.0dBm               | –111.5dBm               | –109.5dBm              |

### 3.3 Sensitivity versus Supply Voltage, Temperature and Frequency Offset

To calculate the behavior of a transmission system it is important to know the reduction of the sensitivity due to several influences. The most important are frequency offset due to crystal oscillator (XTO) and crystal frequency (XTAL) errors, temperature and supply voltage dependency of the noise figure and IF filter bandwidth of the receiver. Figure 3-2 shows the typical sensitivity at 433.92MHz/FSK/20Kbit/s/±16kHz/Manchester versus the frequency offset between transmitter and receiver with  $T_{amb} = -40^{\circ}\text{C}$ ,  $+25^{\circ}\text{C}$  and  $+105^{\circ}\text{C}$  and supply voltage  $V_{S1} = V_{S2} = 2.4\text{V}$ ,  $3.0\text{V}$  and  $3.6\text{V}$ .

**Figure 3-2. Measured Sensitivity 433.92MHz/FSK/20Kbit/s/±16kHz/Manchester versus Frequency Offset, Temperature and Supply Voltage**



As can be seen in Figure 3-2 on page 12 the supply voltage has almost no influence. The temperature has an influence of about  $+1.5/-0.7\text{dB}$ , and a frequency offset of  $\pm 65\text{kHz}$  also influences by about  $\pm 1\text{dB}$ . All these influences, combined with the sensitivity of a typical IC, are then within a range of  $-103.7\text{dBm}$  and  $-107.3\text{dBm}$  over temperature, supply voltage and frequency offset which is  $-105.5\text{dBm} \pm 1.8\text{dB}$ . The integrated IF filter has an additional production tolerance of only  $\pm 7\text{kHz}$ , hence, a frequency offset between the receiver and the transmitter of  $\pm 58\text{kHz}$  can be accepted for XTAL and XTO tolerances.

This small sensitivity spread over supply voltage, frequency offset and temperature is very unusual in such a receiver. It is achieved by an internal, very fast and automatic frequency correction in the FSK demodulator after the IF filter, which leads to a higher system margin. This frequency correction tracks the input frequency very quickly; if, however, the input frequency makes a larger step (for example, if the system changes between different communication partners), the receiver has to be restarted. This can be done by switching back to IDLE mode and then again to RX mode. For that purpose, an automatic mode is also available. This automatic mode switches to IDLE mode and back into RX mode every time a bit error occurs (see Section 7. on page 31).

### 3.4 Frequency Accuracy of the Crystals

The XTO is an amplitude regulated Pierce oscillator with integrated load capacitors. The initial tolerances (due to the frequency tolerance of the XTAL, the integrated capacitors on XTAL1, XTAL2 and the XTO's initial transconductance  $g_m$ ) can be compensated to a value within  $\pm 0.5\text{ppm}$  by measuring the CLK output frequency and programming the control registers 2 and 3 (see Table 7-7 on page 33 and Table 7-10 on page 34). The XTO then has a remaining influence of less than  $\pm 2\text{ppm}$  over temperature and supply voltage due to the band gap controlled  $g_m$  of the XTO.

The needed frequency stability of the used crystals over temperature and aging is hence

$$\pm 58\text{kHz}/433.92\text{MHz} - 2 \times \pm 2.5\text{ppm} = \pm 128.6\text{ppm for } 433.92\text{MHz},$$

$$\pm 58\text{kHz}/868.3\text{MHz} - 2 \times \pm 2.5\text{ppm} = \pm 61.8\text{ppm for } 868.3\text{MHz}.$$

Thus, the used crystals in receiver and transmitter each need to be better than  $\pm 64.3\text{ppm}$  for  $433.92\text{MHz}$ ,  $\pm 30.9\text{ppm}$  for  $868.3\text{MHz}$ . In access control systems it may be advantageous to have a more tight tolerance at the Base-station in order to relax the requirement for the remote control unit.

### 3.5 RX Supply Current versus Temperature and Supply Voltage

Table 3-5 shows the typical supply current at 433.92MHz of the transceiver in RX mode versus supply voltage and temperature with  $V_S = V_{S1} = V_{S2}$ . As can be seen, the supply current at 2.4V and  $-40^{\circ}\text{C}$  is less than the typical supply current; this is useful because this is also the operation point where a lithium cell has the worst performance. The typical supply current at 868.3MHz in RX mode is about the same as for 433.92MHz.

**Table 3-5. Measured 433.92 MHz Receive Supply Current in FSK Mode**

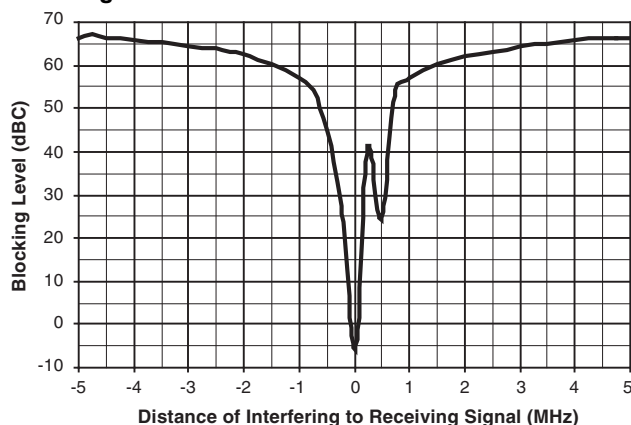
| $V_S = V_{S1} = V_{S2}$                | 2.4V   | 3.0V   | 3.6V   |
|----------------------------------------|--------|--------|--------|
| $T_{\text{amb}} = -40^{\circ}\text{C}$ | 8.4mA  | 8.8mA  | 9.2mA  |
| $T_{\text{amb}} = 25^{\circ}\text{C}$  | 9.9mA  | 10.3mA | 10.8mA |
| $T_{\text{amb}} = 85^{\circ}\text{C}$  | 10.9mA | 11.3mA | 11.8mA |

### 3.6 Blocking, Selectivity

As can be seen in Figure 3-3 and Figure 3-4 on page 13, the receiver can receive signals 3dB higher than the sensitivity level in the presence of very large blockers of  $-47\text{dBm}/-34\text{dBm}$  with small frequency offsets of  $\pm 1/\pm 10\text{MHz}$ .

Figure 3-3 shows narrow band blocking and Figure 3-4 wide band blocking characteristics. The measurements were done with a signal of 433.92MHz/FSK/20Kbit/s/ $\pm 16\text{kHz}$ /Manchester, and with a level of  $-106\text{dBm} + 3\text{dB} = -103\text{dBm}$  which is 3dB above the sensitivity level. The figures show how much larger than  $-103\text{dBm}$  a continuous wave signal can be before the BER is higher than  $10^{-3}$ . The measurements were done at the  $50\Omega$  input according to Figure 3-1 on page 11. At 1MHz, for example, the blocker can be 56dB higher than  $-103\text{dBm}$  which is  $-103\text{dBm} + 56\text{dB} = -47\text{dBm}$ . These values, together with the good intermodulation performance, avoid the need for a SAW filter in the remote control unit application.

**Figure 3-3. Narrow Band 3dB Blocking Characteristic at 433.92MHz**



**Figure 3-4. Wide Band 3dB Blocking Characteristic at 433.92MHz**

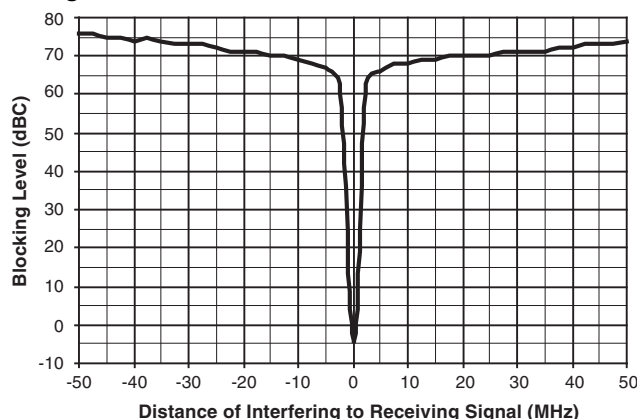


Figure 3-5 on page 14 shows the blocking measurement close to the received frequency to illustrate the selectivity and image rejection. This measurement was done 6dB above the sensitivity level with a useful signal of 433.92MHz/FSK/20Kbit/s/±16kHz/Manchester with a level of  $-106\text{dBm} + 6\text{dB} = -100\text{dBm}$ . The figure shows to which extent a continuous wave signal can surpass  $-100\text{dBm}$  until the BER is higher than  $10^{-3}$ . For example, at 1MHz the blocker can then be 59dB higher than  $-100\text{dBm}$  which is  $-100\text{dBm} + 59\text{dB} = -41\text{dBm}$ .

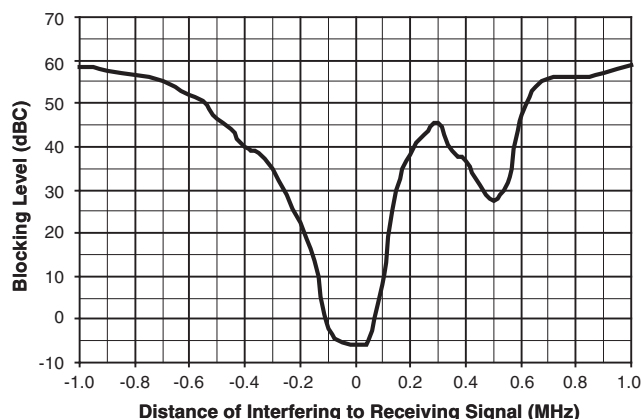
Table 3-6 on page 14 shows the blocking performance measured relative to  $-100\text{dBm}$  for some other frequencies. Note that sometimes the blocking is measured relative to the sensitivity level (dBS) instead of the carrier (dBC).

**Table 3-6. Blocking 6dB Above Sensitivity Level with BER <  $10^{-3}$**

| Frequency Offset | Blocker Level | Blocking    |
|------------------|---------------|-------------|
| +0.75MHz         | -45dBm        | 55dBC/61dBS |
| -0.75MHz         | -45dBm        | 55dBC/61dBS |
| +1.5MHz          | -38dBm        | 62dBC/68dBS |
| -1.5MHz          | -38dBm        | 62dBC/68dBS |
| +10MHz           | -30dBm        | 70dBC/76dBS |
| -10MHz           | -30dBm        | 70dBC/76dBS |

The ATA5428 can also receive FSK and ASK modulated signals if they are much higher than the I1dBCP. It can typically receive useful signals at 10dBm. This is often referred to as the nonlinear dynamic range which is the maximum to minimum receiving signal and is 116dB for 20Kbit/s Manchester. This value is useful if two transceivers have to communicate and are very close to each other.

**Figure 3-5. Close In 6dB Blocking Characteristic and Image Response at 433.92MHz**



This high blocking performance even makes it possible for some applications using quarter wave whip antennas to use a simple LC band-pass filter instead of a SAW filter in the receiver.

When designing such an LC filter take into account that the 3dB blocking at  $433.92\text{MHz}/2 = 216.96\text{MHz}$  is 43dBC and at  $433.92\text{MHz}/3 = 144.64\text{MHz}$  is 48dBC and at  $2 \times (433.92\text{MHz} + 226\text{kHz}) + -226\text{kHz} = 868.066\text{MHz}/868.518\text{MHz}$  is 56dBC.

And especially that at  $3 \times (433.92\text{MHz} + 226\text{kHz}) + 226\text{kHz} = 1302.664\text{MHz}$  the receiver has its second LO harmonic receiving frequency with only 12dBC blocking.

### 3.7 In-band Disturbors, Data Filter, Quasi-peak Detector, Data Slicer

If a disturbing signal falls into the received band or a blocker is not continuous wave, the performance of a receiver strongly depends on the circuits after the IF filter. The demodulator, data filter and data slicer are important, in that case.

The data filter of the ATA5428 implies a quasi-peak detector. This results in a good suppression of the above mentioned disturbors and exhibits a good carrier to Gaussian noise performance. The required useful signal to disturbing signal ratio to be received with a BER of  $10^{-3}$  is less than 12dB in ASK mode and less than 3dB (BR\_Range\_0 to BR\_Range\_2)/6dB (BR\_Range\_3) in FSK mode.

Due to the many different waveforms possible these numbers are measured for signal as well as for disturbers with peak amplitude values. Note that these values are worst case values and are valid for any type of modulation and modulating frequency of the disturbing signal as well as the receiving signal. For many combinations, lower carrier to disturbing signal ratios are needed.

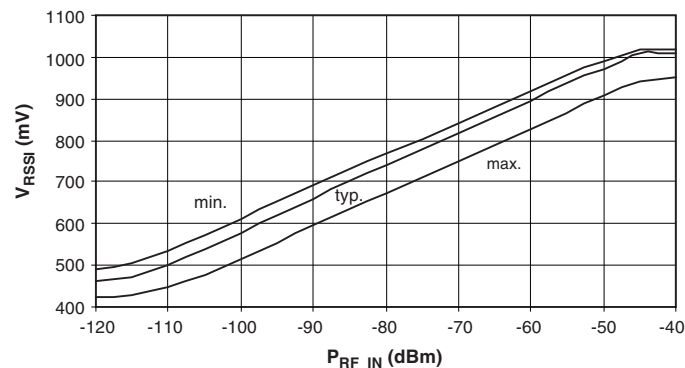
### 3.8 DEM\_OUT Output

The internal raw output signal of the demodulator Demod\_Out is available at pin DEM\_OUT. DEM\_OUT is an open drain output and must be connected to a pull-up resistor if it is used (typically 100k $\Omega$ ) otherwise no signal is present at that pin.

### 3.9 RSSI Output

The output voltage of the pin RSSI is an analog voltage, proportional to the input power level. Using the RSSI output signal, the signal strength of different transmitters can be distinguished. The usable dynamic range of the RSSI amplifier is 70dB, the input power range  $P(RF_{IN})$  is -115dBm to -45dBm and the gain is 8mV/dB. Figure 3-6 shows the RSSI characteristic of a typical device at 433.92MHz with  $VS1 = VS2 = 2.4V$  to  $3.6V$  and  $T_{amb} = -40^{\circ}C$  to  $+85^{\circ}C$  with a matched input according to Table 3-2 on page 11 and Figure 3-1 on page 11. At 868.3MHz about 2.7dB more signal level is needed for the same RSSI results.

**Figure 3-6. Typical RSSI Characteristic versus Temperature and Supply Voltage**



### 3.10 Frequency Synthesizer

The synthesizer is a fully integrated fractional-N design with internal loop filters for receive and transmit mode. The XTO frequency  $f_{XTO}$  is the reference frequency FREF for the synthesizer. The bits FR0 to FR12 in control registers 2 and 3 (see Table 7-7 on page 33 and Table 7-10 on page 34) are used to adjust the deviation of  $f_{XTO}$ . In transmit mode, at 433.92MHz, the carrier has a phase noise of -111dBC/Hz at 1MHz and spurious emissions at FREF of -66dBC with a high PLL loop bandwidth allowing the direct modulation of the carrier with 20Kbit/s Manchester data. Due to the closed loop modulation any spurious emissions caused by this modulation are effectively filtered out as can be seen in Figure 3-9 on page 17. In RX mode the synthesizer has a phase noise of -120dBC/Hz at 1MHz and spurious emissions of -75dBC.

The initial tolerances of the crystal oscillator due to crystal tolerances, internal capacitor tolerances and the parasitics of the board have to be compensated at manufacturing setup with control registers 2 and 3 as can be seen in Table 4-1 on page 23. The other control words for the synthesizer needed for ASK, FSK and receive/transmit switching are calculated internally. The RF (Radio Frequency) resolution is equal to the XTO frequency divided by 16384 which is 808.9Hz at 433.92MHz, 818.6Hz at 868.3MHz.

For the multi-channel system the frequency control word FREQ in control registers 2 and 3 can be programmed in the range of 1000 to 6900, this is equivalent to a programmable tuning range of  $\pm 2.5$ MHz hence every frequency within the 433MHz, 868MHz ISM bands can be programmed as receive and as transmit frequency, and the position of channels within these ISM bands can be chosen arbitrarily (see Table 4-1 on page 23).

Care must be taken as to the harmonics of the CLK output signal as well as to the harmonics produced by a microprocessor clocked with it, since these harmonics can disturb the reception of signals. In a single-channel system, using FREQ = 3803 to 4053 ensures that harmonics of this signal do not disturb the receive mode.

### 3.11 FSK/ASK Transmission

Due to the fast modulation capability of the synthesizer and the high resolution, the carrier can be internally FSK modulated, which simplifies the application of the transceiver. The deviation of the transmitted signal is  $\pm 20$  digital frequency steps of the synthesizer which is equal to  $\pm 16.17\text{kHz}$  for  $433.92\text{MHz}$ ,  $\pm 16.37\text{kHz}$  for  $868.3\text{MHz}$ .

Due to closed loop modulation with PLL filtering the modulated spectrum is very clean, meeting ETSI and CEPT regulations when using a simple LC filter for the power amplifier harmonics as it is shown in [Figure 2.2 on page 8](#). In ASK mode the frequency is internally connected to the center of the FSK transmission and the power amplifier is switched on and off to perform the modulation. [Figure 3-7](#) to [Figure 3-9 on page 17](#) show the spectrum of the FSK modulation with pseudo-random data with  $20\text{Kbit/s}/\pm 16.17\text{kHz}/\text{Manchester}$  and  $5\text{dBm}$  output power.

**Figure 3-7. FSK-modulated TX Spectrum ( $433.92\text{MHz}/20\text{Kbit/s}/\pm 16.17\text{kHz}/\text{Manchester Code}$ )**

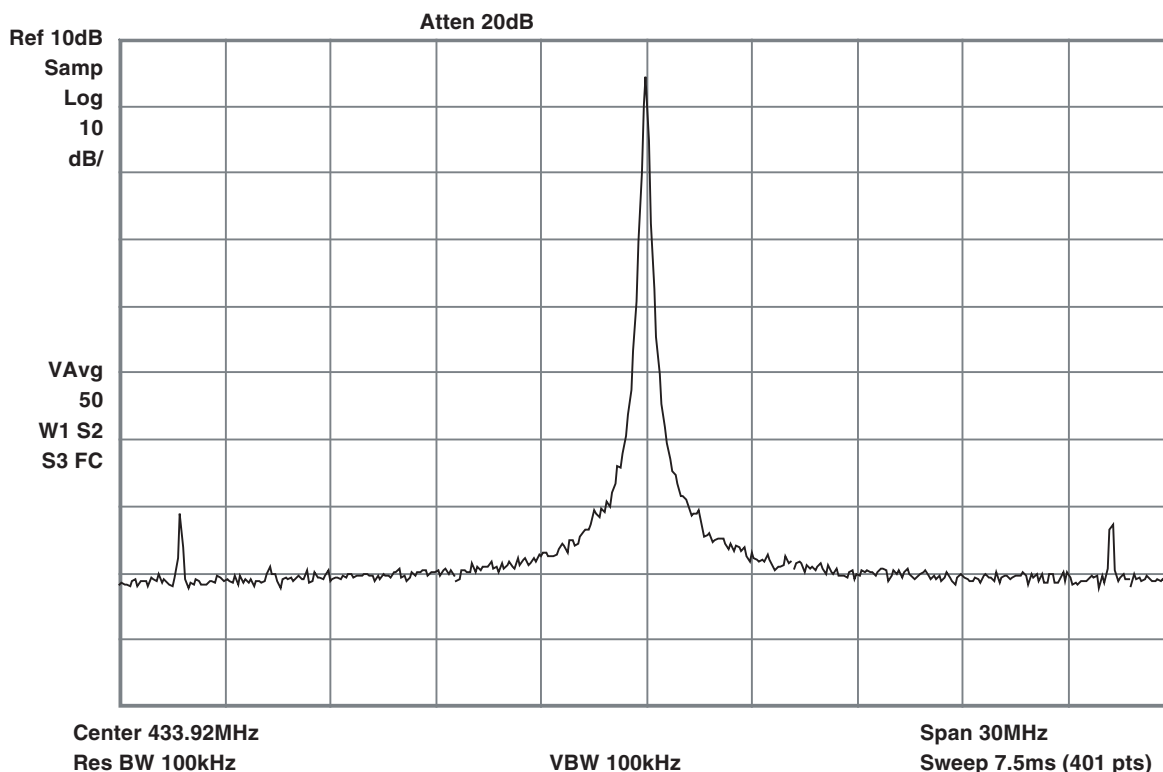


Figure 3-8. Unmodulated TX Spectrum 433.92MHz – 16.17kHz ( $f_{FSK\_L}$ )

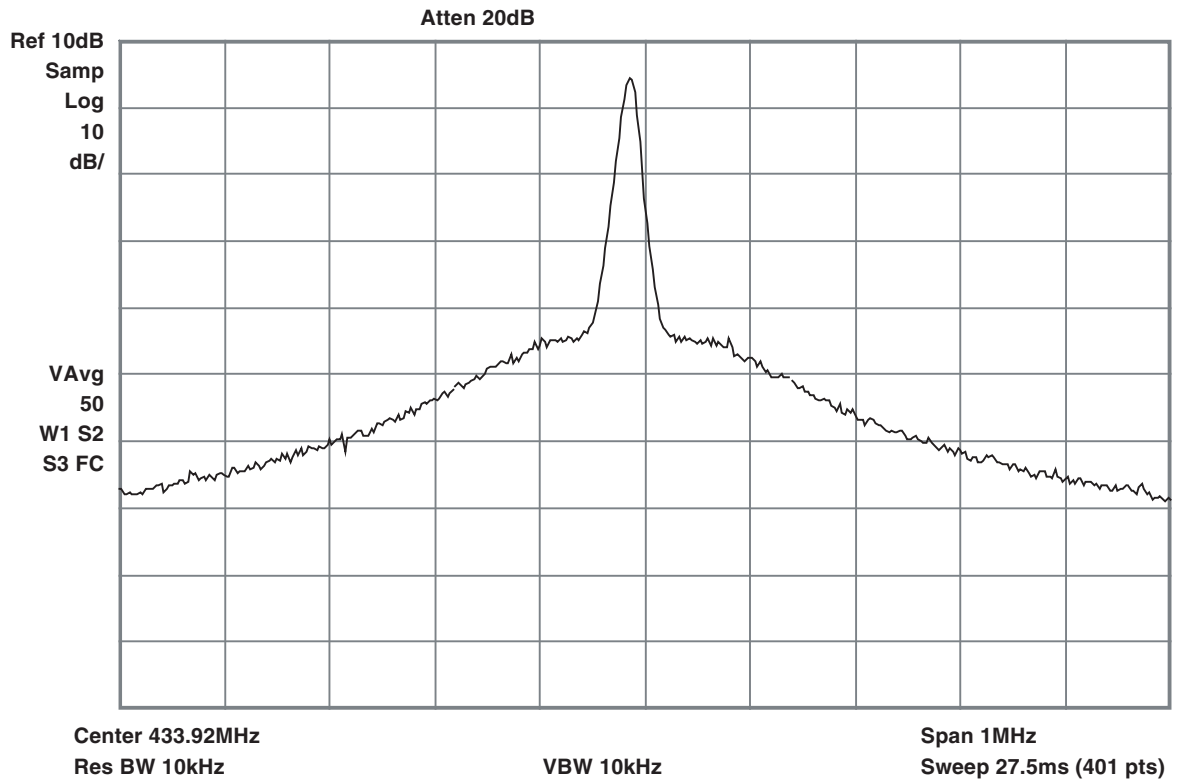
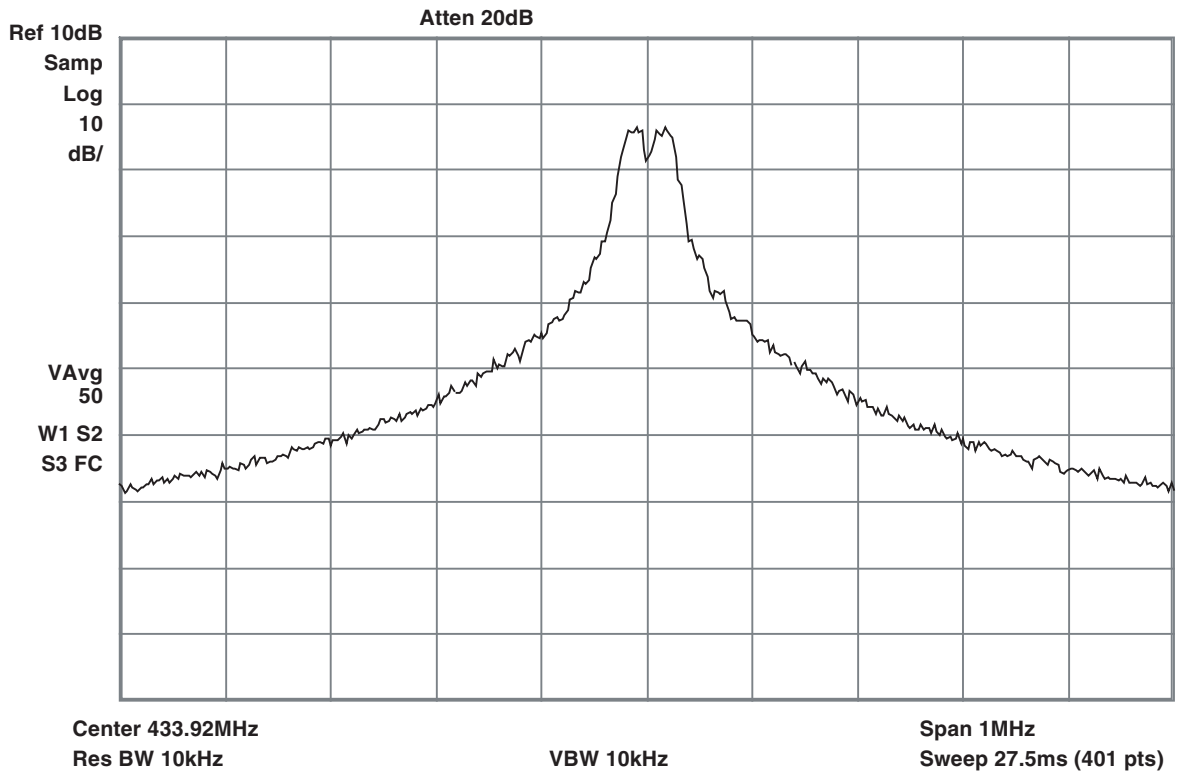


Figure 3-9. FSK-modulated TX Spectrum (433.92MHz/20Kbit/s/±16.17kHz/Manchester Code)



### 3.12 Output Power Setting and PA Matching at RF\_OUT

The Power Amplifier (PA) is a single-ended open collector stage which delivers a current pulse which is nearly independent of supply voltage, temperature and tolerances due to band gap stabilization. Resistor  $R_1$ , see Figure 3-10, sets a reference current which controls the current in the PA. A higher resistor value results in a lower reference current, a lower output power and a lower current consumption of the PA. The usable range of  $R_1$  is 15k $\Omega$  to 56k $\Omega$ . Pin PWR\_H switches the output power range between about 0dBm to 5dBm (PWR\_H = GND) and 5dBm to 10dBm (PWR\_H = AVCC) by multiplying this reference current by a factor 1 (PWR\_H = GND) and 2.5 (PWR\_H = AVCC), which corresponds to about 5dB more output power.

If the PA is switched off in TX mode, the current consumption without output stage with  $VS1 = VS2 = 3V$ ,  $T_{amb} = 25^\circ C$  is typically 6.5mA for 868.3MHz and 6.95mA for 433.92MHz.

The maximum output power is achieved with optimum load resistances  $R_{Lopt}$  according to Table 3-7 on page 19 with compensation of the 1.0pF output capacitance of the RF\_OUT pin by absorbing it into the matching network consisting of  $L_1$ ,  $C_1$ ,  $C_3$  as shown in Figure 3-10 on page 18. There must also be a low resistive DC path to AVCC to deliver the DC current of the power amplifier's last stage. The matching of the PA output was done with the circuit shown in Figure 3-10 on page 18 with the values in Table 3-7 on page 19. Note that value changes of these elements may be necessary to compensate for individual board layouts.

#### Example:

According to Table 3-7 on page 19, with a frequency of 433.92 MHz and output power of 11dBm the overall current consumption is typically 17.8mA; hence, the PA needs 17.8mA - 6.95mA = 10.85mA in this mode, which corresponds to an overall power amplifier efficiency of the PA of  $(10^{(11dBm/10)} \times 1 \text{ mW}) / (3V \times 10.85mA) \times 100\% = 38.6\%$  in this case.

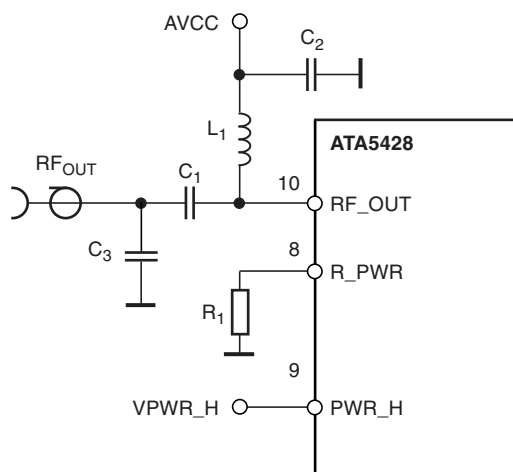
Using a higher resistor in this example of  $R_1 = 1.091 \times 22k\Omega = 24k\Omega$  results in 9.1% less current in the PA of 10.85mA/1.091 = 9.95mA and  $10 \times \log(1.091) = 0.38dB$  less output power if using a new load resistance of  $300\Omega \times 1.091 = 327\Omega$ . The resulting output power is then 11dBm - 0.38dB = 10.6dBm and the overall current consumption is 6.95mA + 9.95mA = 16.9mA.

The values of Table 3-7 on page 19 were measured with standard multi-layer chip inductors with quality factors Q according to Table 3-7 on page 19. Looking to the 433.92MHz/11dBm case with the quality factor of  $Q_{L1} = 43$  the loss in this inductor is estimated with the parallel equivalent resistance of the inductor  $R_{loss} = 2 \times \pi \times f \times L \times Q_{L1}$  and the matching loss with  $10 \log(1 + R_{Lopt}/R_{loss})$  which is equal to 0.32dB losses in this inductor. Taking this into account, the PA efficiency is then 42% instead of 38.6%.

Be aware that the high power mode (PWR\_H = AVCC) can only be used with a supply voltage higher than 2.7V, whereas the low power mode (PWR\_H = GND) can be used down to 2.4V as can be seen in the "Electrical Characteristics: General" on page 59.

The supply blocking capacitor  $C_2$  (10nF) has to be placed close to the matching network because of the RF current flowing through it.

Figure 3-10. Power Setting and Output Matching



**Table 3-7. Measured Output Power and Current Consumption with VS1 = VS2 = 3V, T<sub>amb</sub> = 25°C**

| Frequency (MHz) | TX Current (mA) | Output Power (dBm) | R1 (kΩ) | VPWR_H | R <sub>Lopt</sub> (Ω) | L1 (nH) | Q <sub>L1</sub> | C1 (pF) | C3 (pF) |
|-----------------|-----------------|--------------------|---------|--------|-----------------------|---------|-----------------|---------|---------|
| 433.92          | 8.6             | 0.1                | 56      | GND    | 2300                  | 56      | 40              | 0.75    | 0       |
| 433.92          | 11.2            | 6.2                | 22      | GND    | 890                   | 47      | 38              | 1.5     | 0       |
| 433.92          | 17.8            | 11                 | 22      | AVCC   | 300                   | 33      | 43              | 2.7     | 0       |
| 868.3           | 9.3             | -0.3               | 33      | GND    | 1170                  | 12      | 58              | 1.0     | 3.3     |
| 868.3           | 11.5            | 5.4                | 15      | GND    | 471                   | 15      | 54              | 1.0     | 0       |
| 868.3           | 16.3            | 9.5                | 22      | AVCC   | 245                   | 10      | 57              | 1.5     | 0       |

### 3.13 Output Power and TX Supply Current versus Supply Voltage and Temperature

Table 3-8 shows the measurement of the output power for a typical device with VS = VS1 = VS2 in the 433.92MHz and 6.2dBm case versus temperature and supply voltage measured according to Figure 3-10 on page 18 with components according to Table 3-7. As opposed to the receiver sensitivity, the supply voltage has here the major impact on output power variations because of the large signal behavior of a power amplifier. Thus, a two battery system with voltage regulator or a 5V system shows much less variation than a 2.4V to 3.6V one battery system because the supply voltage is then well within 3.0V and 3.6V.

The reason is that the amplitude at the output RF\_OUT with optimum load resistance is AVCC – 0.4V and the power is proportional to (AVCC – 0.4V)<sup>2</sup> if the load impedance is not changed. This means that the theoretical output power reduction if reducing the supply voltage from 3.0V to 2.4V is  $10 \log ((3V - 0.4V)^2 / (2.4V - 0.4V)^2) = 2.2\text{dB}$ . Table 3-8 shows that principle behavior in the measurement. This is not the same case for higher voltages, since here increasing the supply voltage from 3V to 3.6V should theoretical increase the power by 1.8dB; but a gain of only 0.8dB in the measurement shows that the amplitude does not increase with the supply voltage because the load impedance is optimized for 3V and the output amplitude stays more constant.

**Table 3-8. Measured Output Power and Supply Current at 433.92MHz, PWR\_H = GND**

| VS =                     | 2.4 V             | 3.0 V             | 3.6 V             |
|--------------------------|-------------------|-------------------|-------------------|
| T <sub>amb</sub> = –40°C | 10.19mA<br>3.8dBm | 10.19mA<br>5.5dBm | 10.78mA<br>6.2dBm |
| T <sub>amb</sub> = +25°C | 10.62mA<br>4.6dBm | 11.19mA<br>6.2dBm | 11.79mA<br>7.1dBm |
| T <sub>amb</sub> = +85°C | 11.4mA<br>3.9dBm  | 12.02mA<br>5.5dBm | 12.73mA<br>6.6dBm |

Table 3-9 shows the relative changes of the output power of a typical device compared to 3.0V/25°C. As can be seen, a temperature change to –40°C as well as to +85°C reduces the power by less than 1dB due to the band gap regulated output current. Measurements of all the cases in Table 3-7 on page 19 over temperature and supply voltage have shown about the same relative behavior as shown in Table 3-9.

**Table 3-9. Measurements of Typical Output Power Relative to 3V/25°C**

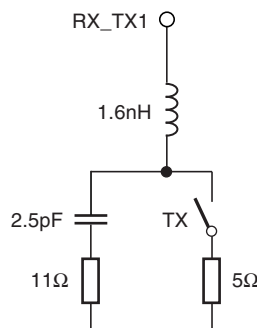
| VS =                     | 2.4V   | 3.0V   | 3.6V   |
|--------------------------|--------|--------|--------|
| T <sub>amb</sub> = -40°C | -2.4dB | -0.7dB | 0dB    |
| T <sub>amb</sub> = +25°C | -1.6dB | 0dB    | +0.9dB |
| T <sub>amb</sub> = +85°C | -2.3dB | -0.7dB | +0.4dB |

### 3.14 RX/TX Switch

The RX/TX switch decouples the LNA from the PA in TX mode, and directs the received power to the LNA in RX mode. To do this, it has a low impedance to GND in TX mode and a high impedance to GND in RX mode. To design a proper RX/TX decoupling, a linear simulation tool for radio frequency design together with the measured device impedances of [Table 3-1 on page 10](#), [Table 3-7 on page 19](#), [Table 3-10](#) and [Table 3-11 on page 21](#) should be used, but the exact element values have to be found on-board. [Figure 3-11](#) shows an approximate equivalent circuit of the switch. The principal switching operation is described here according to the application of [Figure 2-1 on page 7](#). The application of [Figure 2.2 on page 8](#) works similarly.

**Table 3-10. Impedance of the RX/TX Switch RX\_TX2 Shorted to GND**

| Frequency | Z(RX_TX1) TX Mode     | Z(RX_TX1) RX Mode      |
|-----------|-----------------------|------------------------|
| 433.92MHz | (4.5 + j4.3) $\Omega$ | (10.3 - j153) $\Omega$ |
| 868.3MHz  | (5 + j9) $\Omega$     | (8.9 - j73) $\Omega$   |

**Figure 3-11. Equivalent Circuit of the Switch**

### 3.15 Matching Network in TX Mode

In TX mode the 20mm long and 0.4mm wide transmission line which is much shorter than  $\lambda/4$  is approximately switched in parallel to the capacitor  $C_9$  to GND. The antenna connection between  $C_8$  and  $C_9$  has an impedance of about 50 $\Omega$  looking from the transmission line into the loop antenna with pin RF\_OUT,  $L_2$ ,  $C_{10}$ ,  $C_8$  and  $C_9$  connected (using a  $C_9$  without the added 7.6pF as discussed later). The transmission line can be approximated with a 16nH inductor in series with a 1.5 $\Omega$  resistor, the closed switch can be approximated according to [Table 3-10](#) with the series connection of 1.6nH and 5 $\Omega$  in this mode. To have a parallel resonant high impedance circuit with little RF power going into it looking from the loop antenna into the transmission line a capacitor of about 7.6pF to GND is needed at the beginning of the transmission line (this capacitor is later absorbed into  $C_9$  which is then higher, as needed for 50 $\Omega$  transformation). To keep the 50 $\Omega$  impedance in RX mode at the end of this transmission line,  $C_7$  also has to be about 7.6pF. This reduces the TX power by about 0.5dB at 433.92MHz compared to the case where the LNA path is completely disconnected.

### 3.16 Matching Network in RX Mode

In RX mode the RF\_OUT pin has a high impedance of about 7kΩ in parallel with 1.0pF at 433.92MHz as can be seen in Table 3-11. This, together with the losses of the inductor  $L_2$  with 120nH and  $Q_{L2} = 25$ , gives about 3.7kΩ loss impedance at RF\_OUT. Since the optimum load impedance in TX mode for the power amplifier at RF\_OUT is 890Ω the loss associated with the inductor  $L_2$  and the RF\_OUT pin can be estimated to be  $10 \times \log(1 + 890/3700) = 0.95\text{dB}$  compared to the optimum matched loop antenna without  $L_2$  and RF\_OUT. The switch represents, in this mode at 433.92MHz, approximately an inductor of 1.6nH in series with the parallel connection of 2.5pF and 2.0kΩ. Since the impedance level at pin RX\_TX1 in RX mode is about 50Ω this only negligibly dampens the received signal (by about 0.1dB). When matching the LNA to the loop antenna, the transmission line and the 7.6pF part of  $C_9$  have to be taken into account when choosing the values of  $C_{11}$  and  $L_1$  so that the impedance seen from the loop antenna into the transmission line with the 7.6pF capacitor connected is 50Ω. Since the loop antenna in RX mode is loaded by the LNA input impedance, the loaded Q of the loop antenna is lowered by about a factor of 2 in RX mode; hence the antenna bandwidth is higher than in TX mode.

**Table 3-11. Impedance RF\_OUT Pin in RX Mode**

| Frequency | Z(RF_OUT)RX   | $R_p/C_p$ |
|-----------|---------------|-----------|
| 433.92MHz | 19Ω – j 366Ω  | 7kΩ/1.0pF |
| 868.3MHz  | 2.8Ω – j 141Ω | 7kΩ/1.3pF |

Note that if matching to 50Ω, like in Figure 2.2 on page 8, a high Q wire-wound inductor with a  $Q > 70$  should be used for  $L_2$  to minimize its contribution to RX losses that will otherwise be dominant. The RX and TX losses will be in the range of 1.0dB there.

## 4. XTO

The XTO is an amplitude-regulated Pierce oscillator type with integrated load capacitances ( $2 \times 18\text{pF}$  with a tolerance of  $\pm 17\%$ ) hence  $C_{Lmin} = 7.4\text{pF}$  and  $C_{Lmax} = 10.6\text{pF}$ . The XTO oscillation frequency  $f_{XTO}$  is the reference frequency FREF for the fractional-N synthesizer. When designing the system in terms of receiving and transmitting frequency offset, the accuracy of the crystal and XTO have to be considered.

The synthesizer can adjust the local oscillator frequency for the initial frequency error in  $f_{XTO}$ . This is done at nominal supply voltage and temperature with the control registers 2 and 3 (see Table 7-7 on page 33 and Table 7-10 on page 34). The remaining local oscillator tolerance at nominal supply voltage and temperature is then  $< \pm 0.5\text{ppm}$ . The XTO's gm has very low influence of less than  $\pm 2\text{ppm}$  on the frequency at nominal supply voltage and temperature.

In a single channel system less than  $\pm 150\text{ppm}$  should be corrected to avoid that harmonics of the CLK output disturb the receive mode. If the CLK is not used or if it is carefully laid out on the application PCB (as needed for multi channel systems), more than  $\pm 150\text{ppm}$  can be compensated.

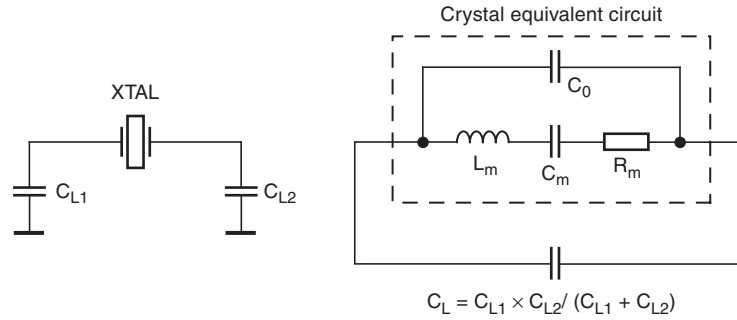
Over temperature and supply voltage, the XTO's additional pulling is only  $\pm 2\text{ppm}$ . The XTAL versus temperature and its aging is then the main source of frequency error in the local oscillator.

The XTO frequency depends on XTAL properties and the load capacitances  $C_{L1,2}$  at pin XTAL1 and XTAL2. The pulling of  $f_{XTO}$  from the nominal  $f_{XTAL}$  is calculated using the following formula:

$$P = \frac{C_m}{2} \times \frac{C_{LN} - C_L}{(C_0 + C_{LN}) \times (C_0 + C_L)} \times 10^6 \text{ ppm.}$$

$C_m$  is the crystal's motional,  $C_0$  the shunt and  $C_{LN}$  the nominal load capacitance of the XTAL found in its data sheet.  $C_L$  is the total actual load capacitance of the crystal in the circuit and consists of  $C_{L1}$  and  $C_{L2}$  in series connection.

**Figure 4-1. XTAL with Load Capacitance**



With  $C_m \leq 14\text{fF}$ ,  $C_0 \geq 1.5\text{pF}$ ,  $C_{LN} = 9\text{pF}$  and  $C_L = 7.4\text{pF}$  to  $10.6\text{pF}$ , the pulling amounts to  $P \leq \pm 100\text{ppm}$  and with  $C_m \leq 7\text{fF}$ ,  $C_0 \geq 1.5\text{pF}$ ,  $C_{LN} = 9\text{pF}$  and  $C_L = 7.4\text{pF}$  to  $10.6\text{pF}$ , the pulling is  $P \leq \pm 50\text{ppm}$ .

Since typical crystals have less than  $\pm 50\text{ppm}$  tolerance at  $25^\circ\text{C}$ , the compensation is not critical, and can in both cases be done with the  $\pm 150\text{ppm}$ .

$C_0$  of the XTAL has to be lower than  $C_{Lmin}/2 = 3.7\text{pF}$  for a Pierce oscillator type in order to not enter the steep region of pulling versus load capacitance where there is a risk of an unstable oscillation.

To ensure proper start-up behavior the small signal gain, and thus the negative resistance, provided by this XTO at start is very large; for example, oscillation starts up even in worst case with a crystal series resistance of  $1.5\text{k}\Omega$  at  $C_0 \leq 2.2\text{pF}$  with this XTO. The negative resistance is approximately given by

$$\text{Re}\{Z_{\text{XTOcore}}\} = \text{Re}\left\{\frac{Z_1 \times Z_3 + Z_2 \times Z_3 + Z_1 \times Z_2 \times Z_3 \times g_m}{Z_1 + Z_2 + Z_3 + Z_1 \times Z_2 \times g_m}\right\}$$

with  $Z_1, Z_2$  as complex impedances at pin XTAL1 and XTAL2, hence

$$Z_1 = -j/(2 \times \pi \times f_{\text{XTO}} \times C_{L1}) + 5\Omega \text{ and } Z_2 = -j/(2 \times \pi \times f_{\text{XTO}} \times C_{L2}) + 5\Omega$$

$Z_3$  consists of crystals  $C_0$  in parallel with an internal  $110\text{ k}\Omega$  resistor hence

$$Z_3 = -j/(2 \times \pi \times f_{\text{XTO}} \times C_0) // 110\text{k}\Omega, g_m \text{ is the internal transconductance between XTAL1 and XTAL2 with typically } 19\text{mS at } 25^\circ\text{C}.$$

With  $f_{\text{XTO}} = 13.5\text{MHz}$ ,  $g_m = 19\text{mS}$ ,  $C_L = 9\text{pF}$ , and  $C_0 = 2.2\text{pF}$ , this results in a negative resistance of about  $2\text{k}\Omega$ . The worst case for technological, temperature and supply voltage variations is then for  $C_0 \leq 2.2\text{pF}$  always higher than  $1.5\text{k}\Omega$ .

Due to the large gain at startup, the XTO is able to meet a very low start-up time. The oscillation start-up time can be estimated with the time constant  $\tau$ .

$$\tau = \frac{2}{4 \times \pi^2 \times f_m^2 \times C_m \times (\text{Re}(Z_{\text{XTOcore}}) + R_m)}$$

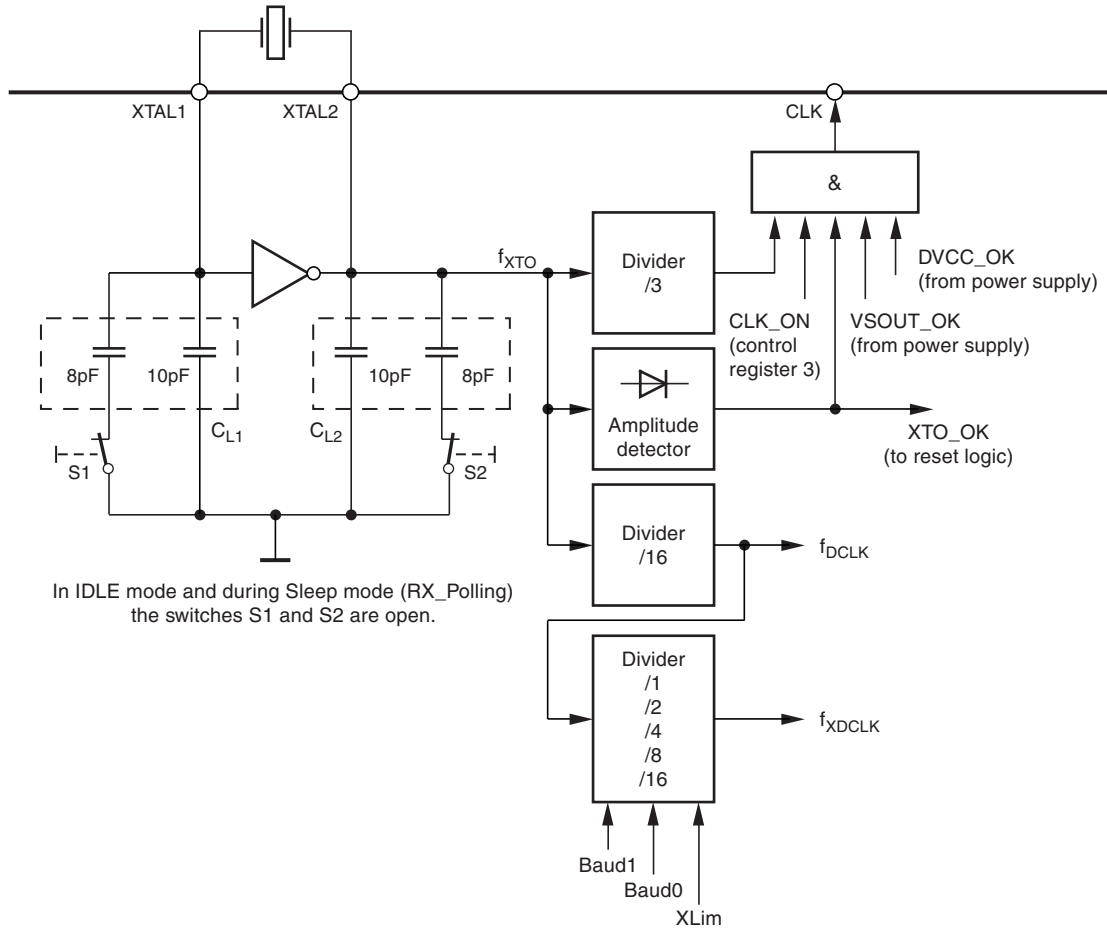
After  $10\tau$  to  $20\tau$  an amplitude detector detects the oscillation amplitude and sets XTO\_OK to High if the amplitude is large enough. This sets N\_RESET to High and activates the CLK output if CLK\_ON in control register 3 is High (see [Table 7-7 on page 33](#)). Note that the necessary conditions of the VSOUT and DVCC voltage also have to be fulfilled (see [Figure 4-2 on page 23](#) and [Figure 5-1 on page 25](#)).

To save current in IDLE and Sleep modes, the load capacitors are partially switched off in these modes with S1 and S2, as seen in [Figure 4-2 on page 23](#).

It is recommended to use a crystal with  $C_m = 3.0\text{fF}$  to  $7.0\text{fF}$ ,  $C_{LN} = 9\text{pF}$ ,  $R_m < 120\Omega$  and  $C_0 = 1.0\text{pF}$  to  $2.2\text{pF}$ .

Lower values of  $C_m$  can be used, this increases the start-up time slightly. Lower values of  $C_0$  or higher values of  $C_m$  (up to  $15\text{fF}$ ) can also be used, this has only little influence on pulling.

**Figure 4-2. XTO Block Diagram**



To find the right values used in control registers 2 and 3 (see [Table 7-7 on page 33](#) and [Table 7-10 on page 34](#)), the relationship between  $f_{XTO}$  and the  $f_{RF}$  is shown in [Table 4-1 on page 23](#). To determine the right content, the frequency at pin CLK as well as the output frequency at RF\_OUT in ASK mode can be measured, then the FREQ value can be calculated according to [Table 4-1 on page 23](#) so that  $f_{RF}$  is exactly the desired radio frequency.

**Table 4-1. Calculation of  $f_{RF}$**

| Frequency (MHz) | Pin 6 433_N868 | CREG1 Bit(4) FS | $f_{XTO}$ (MHz) | $f_{RF} = f_{TX\_ASK} = f_{RX}$                                  | $f_{TX\_FSK\_L}$           | $f_{TX\_FSK\_H}$           | Frequency Resolution |
|-----------------|----------------|-----------------|-----------------|------------------------------------------------------------------|----------------------------|----------------------------|----------------------|
| 433.92          | AVCC           | 0               | 13.25311        | $f_{XTO} \times \left( 32.5 + \frac{FREQ + 20.5}{16384} \right)$ | $f_{RF} - 16.17\text{kHz}$ | $f_{RF} + 16.17\text{kHz}$ | 808.9Hz              |
| 868.3           | GND            | 0               | 13.41191        | $f_{XTO} \times \left( 64.5 + \frac{FREQ + 20.5}{16384} \right)$ | $f_{RF} - 16.37\text{kHz}$ | $f_{RF} + 16.37\text{kHz}$ | 818.6Hz              |

The variable FREQ depends on FREQ2 and FREQ3, which are defined by the bits FR0 to FR12 in control register 2 and 3, and is calculated as follows:

$$\text{FREQ} = \text{FREQ2} + \text{FREQ3}$$

Care must be taken to the harmonics of the CLK output signal  $f_{\text{CLK}}$  as well as to the harmonics produced by an microprocessor clocked with it, since these harmonics can disturb the reception of signals if they get to the RF input. In a single channel system, using FREQ = 3803 to 4053 ensures that the harmonics of this signal do not disturb the receive mode. In a multichannel system, the CLK signal can either be not used or carefully laid out on the application PCB. The supply voltage of the microcontroller must also be carefully blocked in a multichannel system.

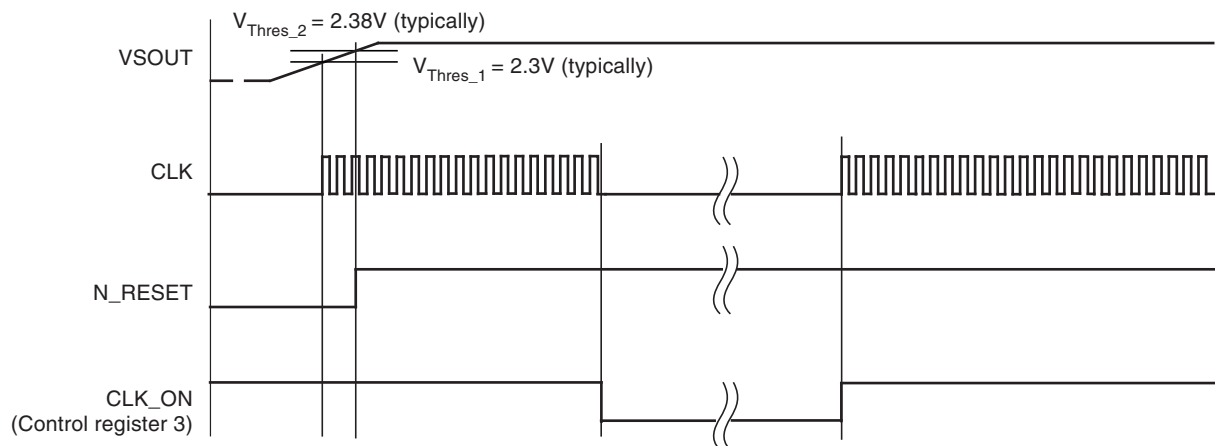
## 4.1 Pin CLK

Pin CLK is an output to clock a connected microcontroller. The clock frequency  $f_{\text{CLK}}$  is calculated as follows:

$$f_{\text{CLK}} = \frac{f_{\text{XTO}}}{3}$$

Because the enabling of pin CLK is asynchronous, the first clock cycle may be incomplete. The signal at CLK output has a nominal 50% duty cycle.

**Figure 4-3. Clock Timing**



## 4.2 Basic Clock Cycle of the Digital Circuitry

The complete timing of the digital circuitry is derived from one clock. As shown in [Figure 4-2 on page 23](#), this clock cycle  $T_{\text{DCLK}}$  is derived from the crystal oscillator (XTO) in combination with a divider.

$$f_{\text{DCLK}} = \frac{f_{\text{XTO}}}{16}$$

$T_{\text{DCLK}}$  controls the following application relevant parameters:

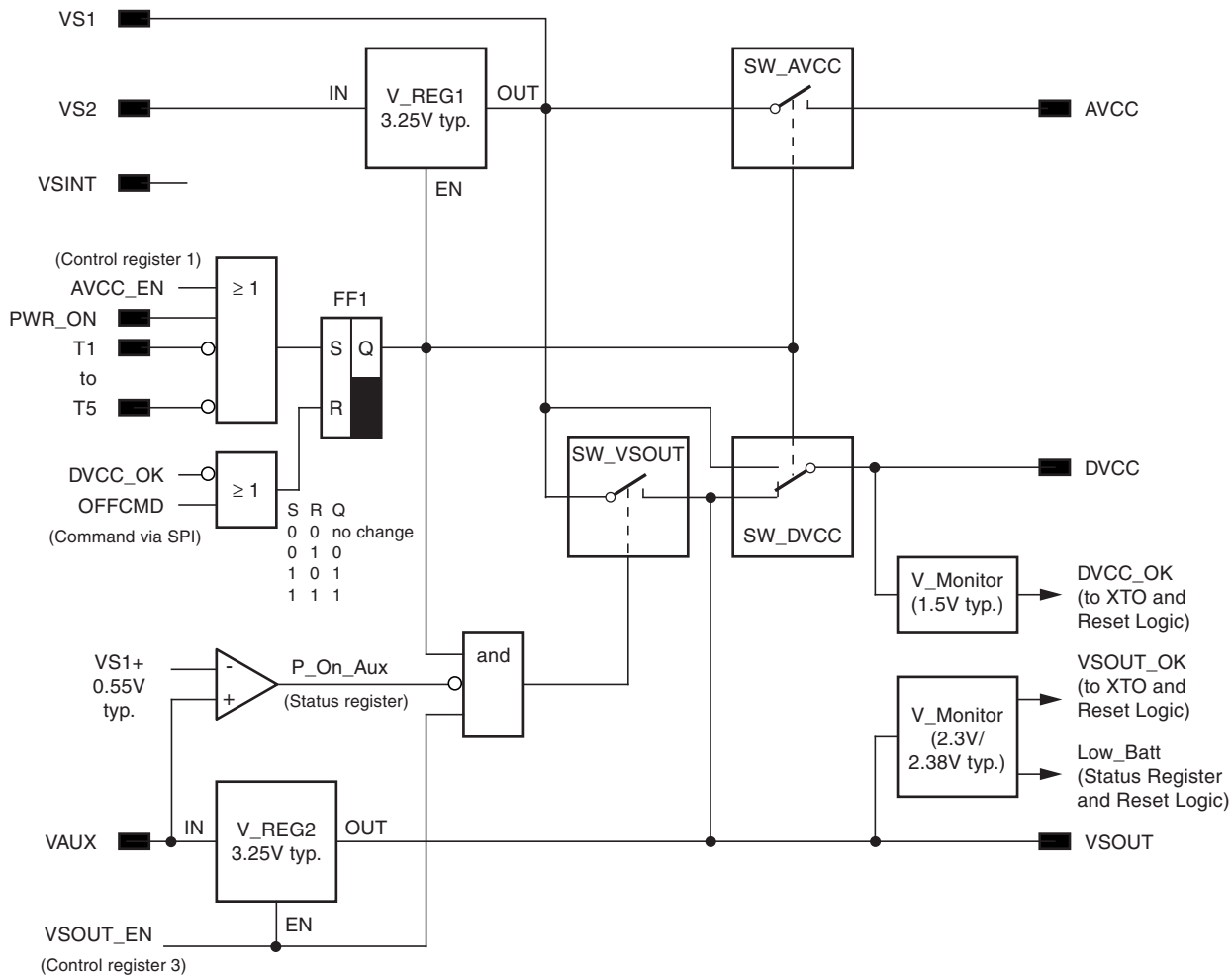
- Timing of the polling circuit including bit check
- TX bit rate

The clock cycle of the bit check and the TX bit rate depends on the selected bit-rate range (BR\_Range) which is defined in control register 6 (see [Table 7-20 on page 36](#)) and XLim which is defined in control register 4 (see [Table 7-13 on page 34](#)). This clock cycle  $T_{\text{XDCLK}}$  is defined by the following formulas for further reference:

$$\begin{aligned} \text{BR\_Range} \Rightarrow & \text{BR\_Range 0: } T_{\text{XDCLK}} = 8 \times T_{\text{DCLK}} \times X_{\text{Lim}} \\ & \text{BR\_Range 1: } T_{\text{XDCLK}} = 4 \times T_{\text{DCLK}} \times X_{\text{Lim}} \\ & \text{BR\_Range 2: } T_{\text{XDCLK}} = 2 \times T_{\text{DCLK}} \times X_{\text{Lim}} \\ & \text{BR\_Range 3: } T_{\text{XDCLK}} = 1 \times T_{\text{DCLK}} \times X_{\text{Lim}} \end{aligned}$$

**5.**

### Figure 5-1. Power Supply



The supply voltage range of the ATA5428 is 2.4V to 3.6V or 4.4V to 6.6V.

Pin VS1 is the supply voltage input for the range 2.4V to 3.6V and is used in 1 Li battery applications (3V) using a single lithium 3V cell. Pin VS2 is the voltage input for the range 4.4V to 6.6V (2 Li battery application (6V) and Base-station Application (5V); in this case, the voltage regulator V\_REG1 regulates VS1 to typically 3.25V. If the voltage regulator is active, a blocking capacitor of 2.2μF has to be connected to VS1.

Pin VAUX is an input for an additional auxiliary voltage supply and can be connected, for example, to an inductive supply (see [Figure 5-6 on page 30](#)). This input can only be used together with a rectifier or as in the application shown in [Figure 2.2 on page 8](#) and must otherwise be left open.

Pin VSINT is the voltage input for the Microcontroller\_Interface and must be connected to the power supply of the microcontroller. The voltage range of  $V_{VSINT}$  is 2.4V to 5.25V (see [Figure 5-5 on page 30](#) and [Figure 5-6 on page 30](#)).

AVCC is the internal operation voltage of the RF transceiver and is fed by VS1 via the switch SW\_AVCC. AVCC must be blocked with a 68nF capacitor (see [Figure 2-1 on page 7](#), [Figure 2.2 on page 8](#) and [Figure 2-3 on page 9](#)).

DVCC is the internal operation voltage of the digital control logic and is fed by VS1 or VSOUT via the switch SW\_DVCC. DVCC must be blocked on pin DVCC with 68 nF (see [Figure 2-1 on page 7](#), [Figure 2.2 on page 8](#) and [Figure 2-3 on page 9](#)).

Pin VSOUT is a power supply output voltage for external devices (for example, microcontrollers) and is fed by VS1 via the switch SW\_VSOUT, or by the auxiliary voltage supply VAUX via V\_REG2. The voltage regulator V\_REG2 regulates VSOUT to typically 3.25V. If the voltage regulator is active, a blocking capacitor of 2.2μF has to be connected to VSOUT. VSOUT can be switched off by the VSOUT\_EN bit in control register 3 and is then reactivated by conditions found in [Figure 5-2 on page 27](#).

Pin N\_RESET is set to low if the voltage  $V_{VSOUT}$  at pin VSOUT drops below 2.3V (typically) and can be used as a reset signal for a connected microcontroller (see [Figure 5-3 on page 29](#) and [Figure 5-4 on page 29](#)).

Pin PWR\_ON is an input to switch on the transceiver (active high).

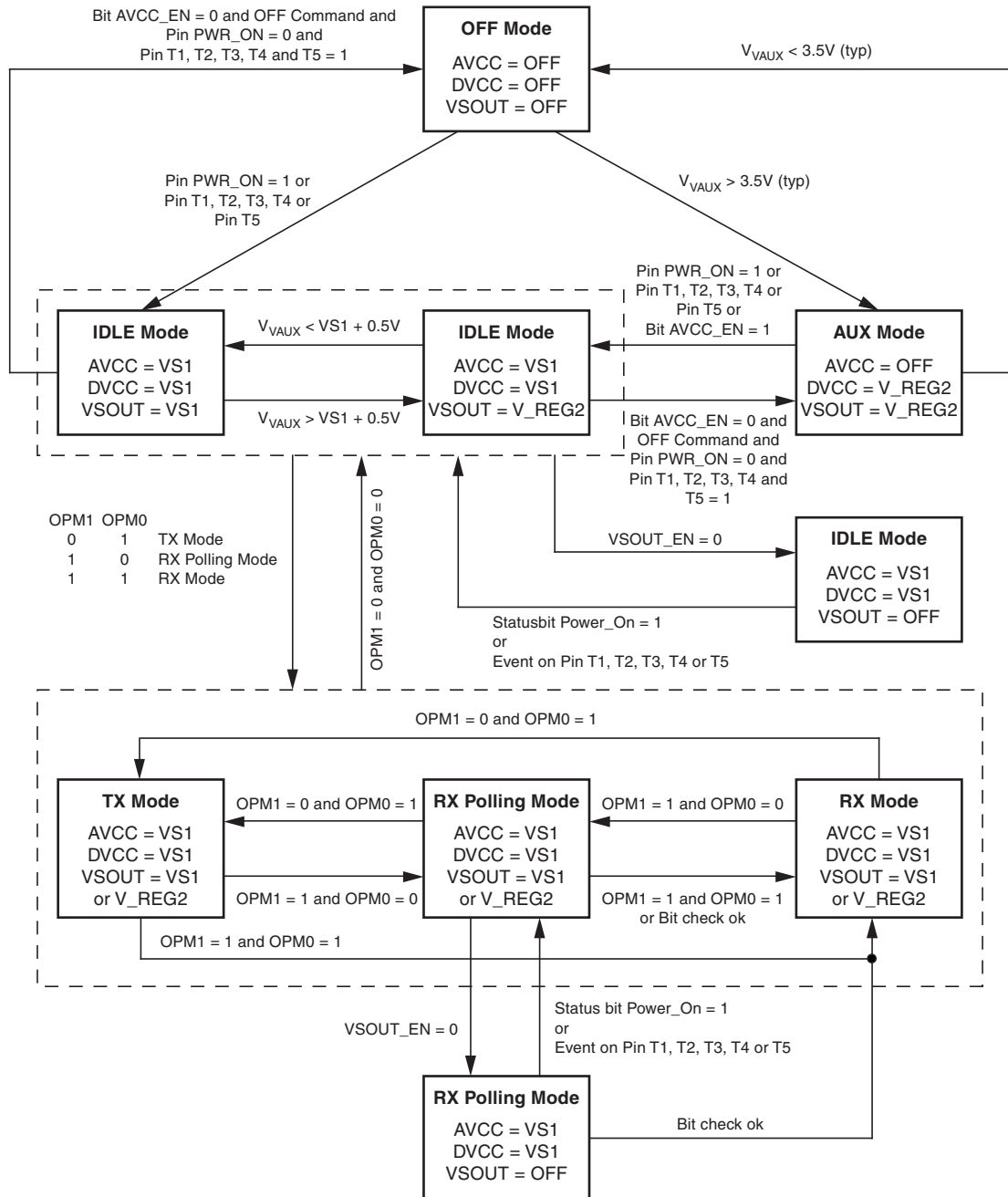
Pin T1 to T5 are inputs for push buttons and can also be used to switch on the transceiver (active low).

For current consumption reasons it is recommended to set T1 to T5 to GND, or PWR\_ON to VCC only temporarily. Otherwise, an additional current flows because of a 50kΩ pull-up resistor.

There are two voltage monitors generating the following signals (see [Figure 5-1 on page 25](#)):

- DVCC\_OK if DVCC > 1.5V typically
- VSOUT\_OK if VSOUT >  $V_{Thres1}$  (2.3V typically)
- Low\_Batt if VSOUT <  $V_{Thres2}$  (2.38V typically)

**Figure 5-2. Operation Modes Flow Chart**



## 5.1 OFF Mode

If the power supply (battery) is connected to pin VS1 and/or VS2, and if the voltage on pin VAUX  $V_{VAUX} < 3.5V$  (typically), then the transceiver is in OFF mode. In OFF mode AVCC, DVCC and VSOUT are disabled, resulting in very low power consumption ( $I_{S\_OFF}$  is typically 10nA). In OFF mode the transceiver is not programmable via the 4-wire serial interface.

## 5.2 AUX Mode

The transceiver changes from OFF mode to AUX mode if the voltage at pin VAUX  $V_{VAUX} > 3.5V$  (typically). In AUX mode DVCC and VSOUT are connected to the auxiliary power supply input (VAUX) via the voltage regulator V\_REG2. In AUX mode the transceiver is programmable via the 4-wire serial interface, but no RX or TX operations are possible because AVCC = OFF.

The state transition OFF mode to AUX mode is indicated by an interrupt at pin IRQ and the status bit P\_On\_Aux = 1.

## 5.3 IDLE Mode

In IDLE mode AVCC and DVCC are connected to the battery voltage (VS1).

From OFF mode the transceiver changes to IDLE mode if pin PWR\_ON is set to 1 or pin T1, T2, T3, T4 or T5 is set to "0". This state transition is indicated by an interrupt at pin IRQ and the status bits Power\_On = 1 or ST1, ST2, ST3, ST4 or ST5 = 1.

From AUX mode the transceiver changes to IDLE mode by setting AVCC\_EN = 1 in control register 1 via the 4-wire serial interface or if pin PWR\_ON is set to "1" or pin T1, T2, T3, T4 or T5 is set to "0".

VSOUT is either connected to VS1 or to the auxiliary power supply (V\_REG2).

If  $V_{VAUX} < VS1 + 0.5V$ , VSOUT is connected to VS1. If  $V_{VAUX} > VS1 + 0.5V$ , VSOUT is connected to V\_REG2 and the status bit P\_On\_Aux is set to "1".

In IDLE mode, the RF transceiver is disabled and the power consumption  $I_{S\_IDLE}$  is about 230  $\mu A$  (VSOUT OFF and CLK output OFF and VS = VS1 = VS2 = 3V). The exact value of this current is strongly dependent on the application and the exact operation mode, therefore check the section ["Electrical Characteristics: General" on page 59](#) for the appropriate application case.

Via the 4-wire serial interface a connected microcontroller can program the required parameter and enable the TX, RX polling or RX mode.

The transceiver can be set back to OFF mode by an OFF command via the 4-wire serial interface (the bit AVCC\_EN must be set to "0", the input level of pin PWR\_ON must be "0" and pin T1, T2, T3, T4 and T5 = 1 before writing the OFF command).

**Table 5-1. Control Register 1**

| OPM1 | OPM0 | Function  |
|------|------|-----------|
| 0    | 0    | IDLE mode |

## 5.4 Reset Timing and Reset Logic

If the transceiver is switched on (OFF mode to IDLE mode, OFF mode to AUX mode) DVCC and VSOUT ramp up as illustrated in [Figure 5-3 on page 29](#) (AVCC only ramps up if the transceiver is set to the IDLE mode). The internal signal DVCC\_RESET resets the digital control logic and sets the control register to default values.

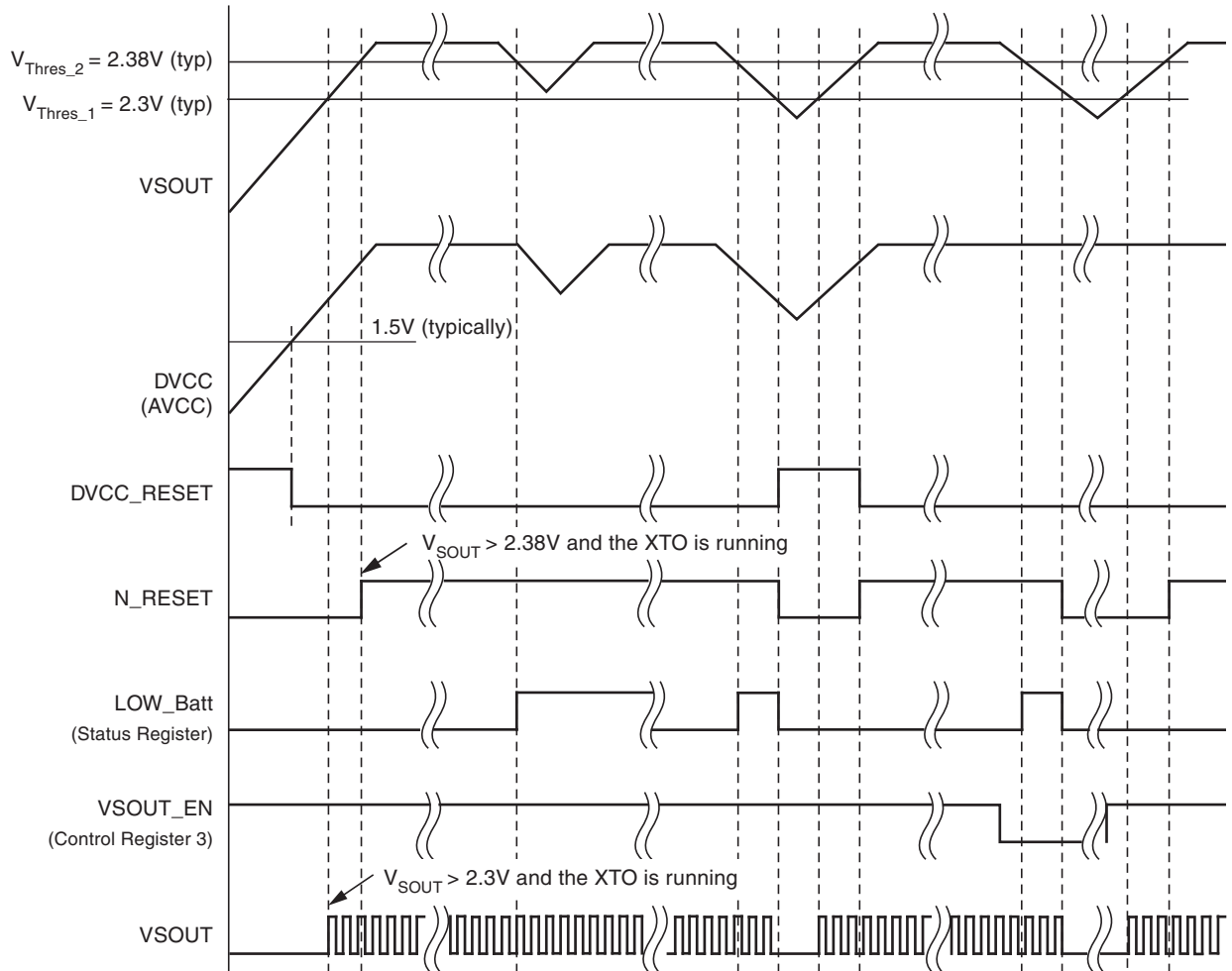
A voltage monitor generates a low level at pin N\_RESET until the voltage at pin VSOUT exceeds 2.38V (typically) and the start-up time of the XTO has elapsed (amplitude detector, see [Figure 4-2 on page 23](#)). After the voltage at pin VSOUT exceeds 2.3V (typically) and the start-up time of the XTO has elapsed, the output clock at pin CLK is available. Because the enabling of pin CLK is asynchronous, the first clock cycle may be incomplete.

The status bit Low\_Batt is set to "1" if the voltage at pin VSOUT  $V_{VSOUT}$  drops below  $V_{Thres\_2}$  (typically 2.38V). Low\_Batt is set to "0" if  $V_{VSOUT}$  exceeds  $V_{Thres\_2}$  and the status register is read via the 4-wire serial interface or N\_RESET is set to low.

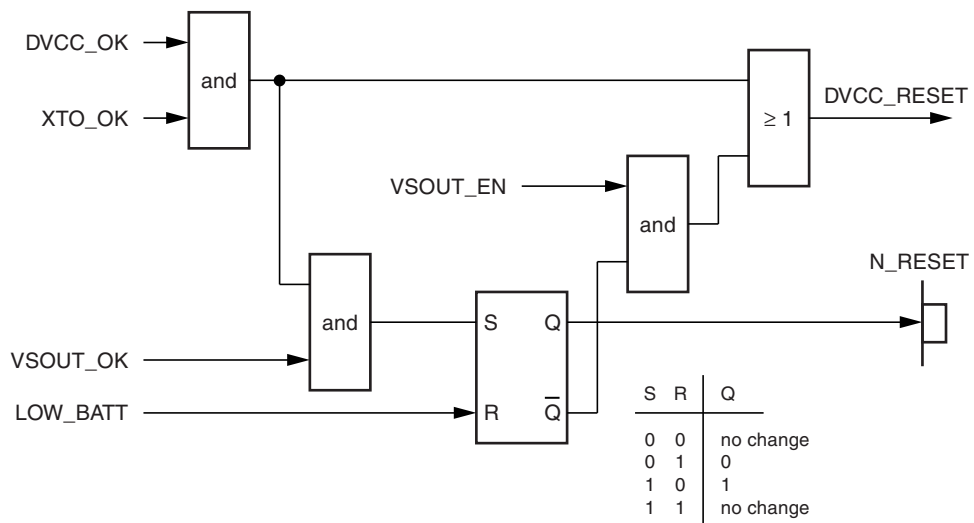
If  $V_{VSOUT}$  drops below  $V_{Thres\_1}$  (typically 2.3V), N\_RESET is set to low. If bit VSOUT\_EN in control register 3 is "1", a DVCC\_RESET is also generated. If  $V_{VSOUT}$  was already disabled by the connected microcontroller by setting bit VSOUT\_EN = 0, no DVCC\_RESET is generated.

Note: If  $VSOUT < V_{Thres\_1}$  (typically 2.3 V) the output of the pin CLK is low, the Microcontroller\_Interface is disabled and the transceiver is not programmable via the 4-wire serial interface.

**Figure 5-3. Reset Timing**



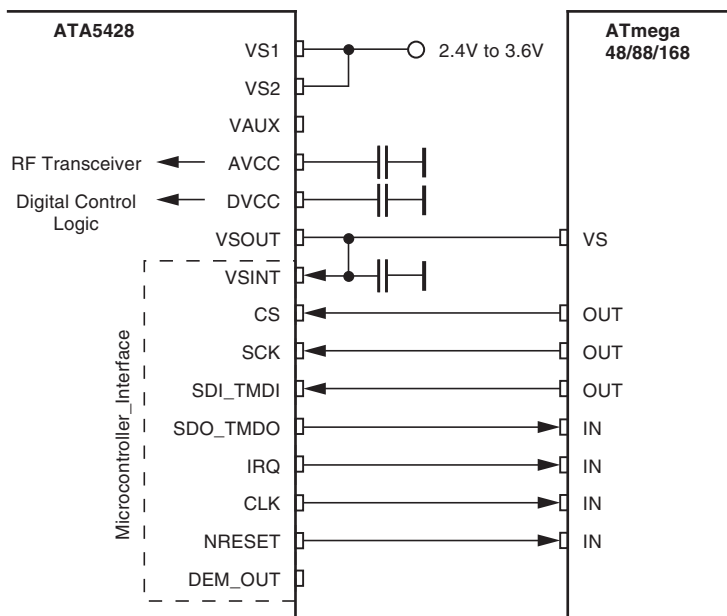
**Figure 5-4. Reset Logic, SR Latch Generates the Hysteresis in the NRESET Signal**



## 5.5 1 Li Battery Application (3V)

The supply voltage range is 2.4V to 3.6V and VAUX is not used.

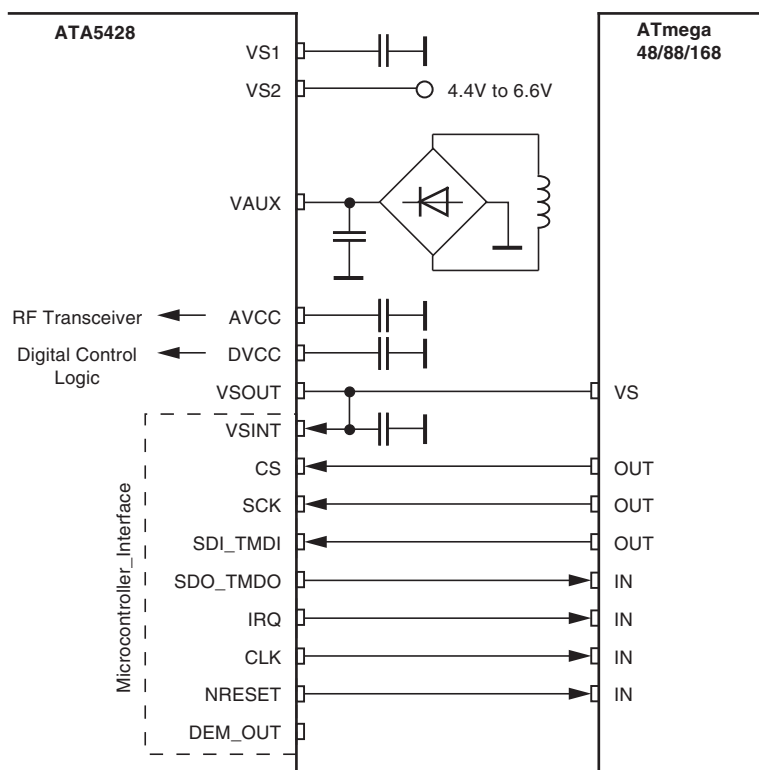
Figure 5-5. 1 Li Battery Application (3V)



## 5.6 2 Li Battery Application (6V)

The supply voltage range is 4.4V to 6.6V and VAUX is connected to an inductive supply.

Figure 5-6. 2 Li Battery Application (6V) with Inductive Emergency Supply



## 6. Microcontroller Interface

The microcontroller interface is a level converter which converts all internal digital signals that are referred to the DVCC voltage into the voltage used by the microcontroller. Therefore, the pin VSINT has to be connected to the supply voltage of the microcontroller.

This makes it possible to use the internal voltage regulator/switch at pin VSOUT as in [Figure 2-1 on page 7](#) and [Figure 2-3 on page 9](#) or to connect the microcontroller and the pin VSINT directly to the supply voltage of the microcontroller as in [Figure 2.2 on page 8](#).

## 7. Digital Control Logic

### 7.1 Register Structure

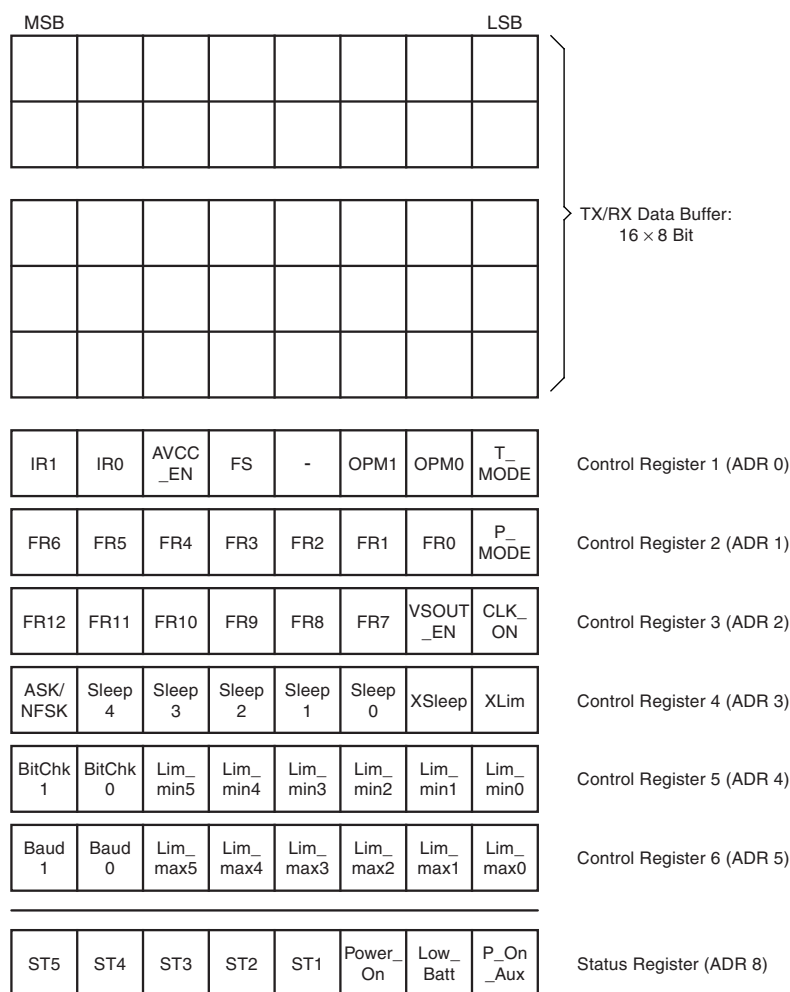
The configuration of the transceiver is stored in RAM cells. The RAM contains a  $16 \times 8$ -bit TX/RX data buffer and a  $6 \times 8$ -bit control register and is writable and readable via a 4-wire serial interface (CS, SCK, SDI\_TMDI, SDO\_TMDO).

The  $1 \times 8$ -bit status register is not part of the RAM and is readable via the 4-wire serial interface.

The RAM and the status information are stored as long as the transceiver is in any active mode (DVCC = VS1 or DVCC = V\_REG2) and are lost when the transceiver switches to OFF mode (DVCC = OFF).

After the transceiver is turned on via pin PWR\_ON = High, T1 = Low, T2 = Low, T3 = Low, T4 = Low or T5 = Low or the voltage at pin VAUX  $V_{VAUX} > 3.5V$  (typically), the control registers are in the default state.

**Figure 7-1. Register Structure**



## 7.2 TX/RX Data Buffer

The TX/RX data buffer is used to handle the data transfer during RX and TX operations.

## 7.3 Control Register

To use the transceiver in different applications, it can be configured by a connected microcontroller via the 4-wire serial interface.

### 7.3.1 Control Register 1 (ADR 0)

**Table 7-1. Control Register 1 (Function of Bit 7 and Bit 6 in RX Mode)**

| IR1 | IR0 | Function (RX Mode)                                                                                              |
|-----|-----|-----------------------------------------------------------------------------------------------------------------|
| 0   | 0   | Pin IRQ is set to “1” if 4 received bytes are in the TX/RX data buffer or a receiving error occurred            |
| 0   | 1   | Pin IRQ is set to “1” if 8 received bytes are in the TX/RX data buffer or a receiving error occurred            |
| 1   | 0   | Pin IRQ is set to “1” if 12 received bytes are in the TX/RX data buffer or a receiving error occurred (default) |
| 1   | 1   | Pin IRQ is set to “1” if a receiving error occurred                                                             |

**Table 7-2. Control Register 1 (Function of Bit 7 and Bit 6 in TX Mode)**

| IR1 | IR0 | Function (TX Mode)                                                                                         |
|-----|-----|------------------------------------------------------------------------------------------------------------|
| 0   | 0   | Pin IRQ is set to “1” if 4 bytes remain in the TX/RX data buffer or the TX data buffer is empty            |
| 0   | 1   | Pin IRQ is set to “1” if 8 bytes remain in the TX/RX data buffer or the TX data buffer is empty            |
| 1   | 0   | Pin IRQ is set to “1” if 12 bytes remain in the TX/RX data buffer or the TX data buffer is empty (default) |
| 1   | 1   | Pin IRQ is set to “1” if the TX data buffer is empty                                                       |

**Table 7-3. Control Register 1 (Function of Bit 5)**

| AVCC_EN | Function  |
|---------|-----------|
| 0       | (default) |

**Table 7-4. Control Register 1 (Function of Bit 4)**

| FS | Function (RX Mode, TX Mode)             |
|----|-----------------------------------------|
| 0  | Selected frequency 433/868MHz (default) |

**Table 7-5. Control Register 1 (Function of Bit 2 and Bit 1)**

| OPM1 | OPM0 | Function            |
|------|------|---------------------|
| 0    | 0    | IDLE mode (default) |
| 0    | 1    | TX mode             |
| 1    | 0    | RX polling mode     |
| 1    | 1    | RX mode             |

**Table 7-6. Control Register 1 (Function of Bit 0)**

| T_MODE | Function                                                                                                                             |
|--------|--------------------------------------------------------------------------------------------------------------------------------------|
| 0      | TX and RX function via TX/RX data buffer (default)                                                                                   |
| 1      | Transparent mode, TX/RX data buffer disabled, TX modulation data stream via pin SDI_TMDI, RX modulation data stream via pin SDO_TMDO |

### 7.3.2 Control Register 2 (ADR 1)

**Table 7-7. Control Register 2 (Function of Bit 7, Bit 6, Bit 5, Bit 4, Bit 3, Bit 2 and Bit 1)**

| FR6<br>2 <sup>6</sup> | FR5<br>2 <sup>5</sup> | FR4<br>2 <sup>4</sup> | FR3<br>2 <sup>3</sup> | FR2<br>2 <sup>2</sup> | FR1<br>2 <sup>1</sup> | FR0<br>2 <sup>0</sup> | Function             |
|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|----------------------|
| 0                     | 0                     | 0                     | 0                     | 0                     | 0                     | 0                     | FREQ2 = 0            |
| 0                     | 0                     | 0                     | 0                     | 0                     | 0                     | 1                     | FREQ2 = 1            |
| .                     | .                     | .                     | .                     | .                     | .                     | .                     |                      |
| 1                     | 0                     | 1                     | 1                     | 0                     | 0                     | 0                     | FREQ2 = 88 (default) |
| .                     | .                     | .                     | .                     | .                     | .                     | .                     |                      |
| 1                     | 1                     | 1                     | 1                     | 1                     | 1                     | 1                     | FREQ2 = 127          |

Note: Tuning of  $f_{RF}$  LSBs (total 13 bits), frequency trimming resolution of  $f_{RF}$  is  $f_{XTO}/16384$ , which is approximately 800Hz (see section "XTO", [Table 4-1 on page 23](#))

**Table 7-8. Control Register 2 (Function of Bit 0 in RX Mode)**

| P_MODE | Function (RX Mode)                                             |
|--------|----------------------------------------------------------------|
| 0      | Pin IRQ is set to "1" if the bit check is successful (default) |
| 1      | No effect on pin IRQ if the bit check is successful            |

**Table 7-9. Control Register 2 (Function of Bit 0 in TX Mode)**

| P_MODE | Function (TX Mode)                  |
|--------|-------------------------------------|
| 0      | Manchester modulator on (default)   |
| 1      | Manchester modulator off (NRZ mode) |

### 7.3.3 Control Register 3 (ADR 2)

**Table 7-10. Control Register 3 (Function of Bit 7, Bit 6, Bit 5, Bit 4, Bit 3 and Bit 2)**

| FR12<br>2 <sup>12</sup> | FR11<br>2 <sup>11</sup> | FR10<br>2 <sup>10</sup> | FR9<br>2 <sup>9</sup> | FR8<br>2 <sup>8</sup> | FR7<br>2 <sup>7</sup> | Function               |
|-------------------------|-------------------------|-------------------------|-----------------------|-----------------------|-----------------------|------------------------|
| 0                       | 0                       | 0                       | 0                     | 0                     | 0                     | FREQ3 = 0              |
| 0                       | 0                       | 0                       | 0                     | 0                     | 1                     | FREQ3 = 128            |
| 0                       | 0                       | 0                       | 0                     | 1                     | 0                     | FREQ3 = 256            |
| .                       | .                       | .                       | .                     | .                     | .                     | .                      |
| 0                       | 1                       | 1                       | 1                     | 1                     | 0                     | FREQ3 = 3840 (default) |
| .                       | .                       | .                       | .                     | .                     | .                     | .                      |
| 1                       | 1                       | 1                       | 1                     | 1                     | 0                     | FREQ3 = 7936           |
| 1                       | 1                       | 1                       | 1                     | 1                     | 1                     | FREQ3 = 8064           |

Note: Tuning of  $f_{RF}$  MSBs

**Table 7-11. Control Register 3 (Function of Bit 1)**

| VSOUT_EN | Function                                                                                                                                                                                                               |
|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0        | Output voltage power supply for external devices off (pin VSOUT)                                                                                                                                                       |
| 1        | Output voltage power supply for external devices on (default)                                                                                                                                                          |
| Note:    | This bit is set to "1" if the bit check is OK (RX_Polling, RX mode), an event at pin T1, T2, T3, T4 or T5 occurs or the bit Power_On in the status register is "1".<br>Setting VSOUT_EN = 0 in AUX mode is not allowed |

**Table 7-12. Control Register\_3 (Function of Bit 0)**

| CLK_ON | Function                                                                                                                                                            |
|--------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0      | Clock output off (pin CLK)                                                                                                                                          |
| 1      | Clock output on (default)                                                                                                                                           |
| Note:  | This bit is set to "1" if the bit check is OK (RX_Polling, RX mode), an event at pin T1, T2, T3, T4 or T5 occurs or the bit Power_On in the status register is "1". |

### 7.3.4 Control Register 4 (ADR 3)

**Table 7-13. Control Register 4 (Function of Bit 7)**

| ASK_NFSK | Function (TX Mode, RX Mode) |
|----------|-----------------------------|
| 0        | FSK mode (default)          |
| 1        | ASK mode                    |

**Table 7-14. Control Register 4 (Function of Bit 6, Bit 5, Bit 4, Bit 3 and Bit 2)**

| Sleep4<br>2 <sup>4</sup> | Sleep3<br>2 <sup>3</sup> | Sleep2<br>2 <sup>2</sup> | Sleep1<br>2 <sup>1</sup> | Sleep0<br>2 <sup>0</sup> | Function (RX Mode)<br>Sleep<br>( $T_{Sleep} = Sleep \times 1024 \times T_{DCLK} \times X_{Sleep}$ ) |
|--------------------------|--------------------------|--------------------------|--------------------------|--------------------------|-----------------------------------------------------------------------------------------------------|
| 0                        | 0                        | 0                        | 0                        | 0                        | 0                                                                                                   |
| 0                        | 0                        | 0                        | 0                        | 1                        | 1                                                                                                   |
| .                        | .                        | .                        | .                        | .                        |                                                                                                     |
| 0                        | 1                        | 0                        | 1                        | 0                        | 10<br>( $T_{Sleep} = 10 \times 1024 \times T_{DCLK} \times X_{Sleep}$ )<br>(default)                |
| .                        | .                        | .                        | .                        | .                        |                                                                                                     |
| 1                        | 1                        | 1                        | 1                        | 1                        | 31                                                                                                  |

**Table 7-15. Control Register 4 (Function of Bit 1)**

| XSleep | Function                                             |
|--------|------------------------------------------------------|
| 0      | $X_{Sleep} = 1$ ; extended $T_{Sleep}$ off (default) |
| 1      | $X_{Sleep} = 8$ ; extended $T_{Sleep}$ on            |

**Table 7-16. Control Register 4 (Function of Bit 0)**

| XLim | Function                                                               |
|------|------------------------------------------------------------------------|
| 0    | $X_{Lim} = 1$ ; extended $T_{Lim\_min}$ , $T_{Lim\_max}$ off (default) |
| 1    | $X_{Lim} = 2$ ; extended $T_{Lim\_min}$ , $T_{Lim\_max}$ on            |

### 7.3.5 Control Register 5 (ADR 4)

**Table 7-17. Control Register 5 (Function of Bit 7 and Bit 6)**

| BitChk1 | BitChk0 | Function                                                        |
|---------|---------|-----------------------------------------------------------------|
| 0       | 0       | $N_{Bit-check} = 0$ (0 bits checked during bit check)           |
| 0       | 1       | $N_{Bit-check} = 3$ (3 bits checked during bit check) (default) |
| 1       | 0       | $N_{Bit-check} = 6$ (6 bits checked during bit check)           |
| 1       | 1       | $N_{Bit-check} = 9$ (9 bits checked during bit check)           |

**Table 7-18. Control Register 5 (Function of Bit 5, Bit 4, Bit 3, Bit 2, Bit 1 and Bit 0 in RX Mode)**

| Lim_min5 | Lim_min4 | Lim_min3 | Lim_min2 | Lim_min1 | Lim_min0 | Function (RX Mode)<br>Lim_min<br>(Lim_min < 10 are not applicable)<br>( $T_{Lim\_min} = Lim\_min \times T_{XDCLK}$ ) |
|----------|----------|----------|----------|----------|----------|----------------------------------------------------------------------------------------------------------------------|
| 0        | 0        | 1        | 0        | 1        | 0        | 10                                                                                                                   |
| 0        | 0        | 1        | 0        | 1        | 1        | 11                                                                                                                   |
| .        | .        | .        | .        | .        | .        |                                                                                                                      |
| 0        | 1        | 0        | 0        | 0        | 0        | 16<br>( $T_{Lim\_min} = 16 \times T_{XDCLK}$ )<br>(default)                                                          |
| .        | .        | .        | .        | .        | .        |                                                                                                                      |
| 1        | 1        | 1        | 1        | 1        | 1        | 63                                                                                                                   |

**Table 7-19. Control Register 5 (Function of Bit 5, Bit 4, Bit 3, Bit 2, Bit 1 and Bit 0 in TX Mode)**

| Lim_min5 | Lim_min4 | Lim_min3 | Lim_min2 | Lim_min1 | Lim_min0 | Function (TX Mode) Lim_min<br>(Lim_min < 10 are not applicable)<br>( $TX\_Bitrate = 1/((Lim\_min + 1) \times T_{XDCLK} \times 2)$ ) |
|----------|----------|----------|----------|----------|----------|-------------------------------------------------------------------------------------------------------------------------------------|
| 0        | 0        | 1        | 0        | 1        | 0        | 10                                                                                                                                  |
| 0        | 0        | 1        | 0        | 1        | 1        | 11                                                                                                                                  |
| .        | .        | .        | .        | .        | .        |                                                                                                                                     |
| 0        | 1        | 0        | 0        | 0        | 0        | 16<br>( $TX\_Bitrate = 1/((16 + 1) \times T_{XDCLK} \times 2)$ )<br>(default)                                                       |
| .        | .        | .        | .        | .        | .        |                                                                                                                                     |
| 1        | 1        | 1        | 1        | 1        | 1        | 63                                                                                                                                  |

### 7.3.6 Control Register 6 (ADR 5)

**Table 7-20. Control Register 6 (Function of Bit 7 and Bit 6)**

| Baud1 | Baud0 | Function                                                                                                                                                               |
|-------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0     | 0     | Bit-rate range 0 (B0) 1.0 Kbit/s to 2.5 Kbit/s;<br>$T_{XDCLK} = 8 \times T_{DCLK} \times X_{Lim}$                                                                      |
| 0     | 1     | Bit-rate range 1 (B1) 2.0 Kbit/s to 5.0 Kbit/s;<br>$T_{XDCLK} = 4 \times T_{DCLK} \times X_{Lim}$                                                                      |
| 1     | 0     | Bit-rate range 2 (B2) 4.0 Kbit/s to 10.0 Kbit/s;<br>$T_{XDCLK} = 2 \times T_{DCLK} \times X_{Lim}$ ; (default)                                                         |
| 1     | 1     | Bit-rate range 3 (B3) 8.0 Kbit/s to 20.0 Kbit/s;<br>$T_{XDCLK} = 1 \times T_{DCLK} \times X_{Lim}$<br>Note that the receiver does not work with >10 Kbit/s in ASK mode |

Table 7-21. Control Register 6 (Function of Bit 5, Bit 4, Bit 3, Bit 2, Bit 1 and Bit 0)

| Lim_max5 | Lim_max4 | Lim_max3 | Lim_max2 | Lim_max1 | Lim_max0 | Function Lim_max<br>(Lim_max < 12 is not Applicable)<br>( $T_{Lim\_max} = (Lim\_max - 1) \times T_{XDCLK}$ ) |
|----------|----------|----------|----------|----------|----------|--------------------------------------------------------------------------------------------------------------|
| 0        | 0        | 1        | 1        | 0        | 0        | 12                                                                                                           |
| 0        | 0        | 1        | 1        | 0        | 1        | 13                                                                                                           |
| .        | .        | .        | .        | .        | .        |                                                                                                              |
| 0        | 1        | 1        | 1        | 0        | 0        | 28<br>( $T_{Lim\_max} = (28 - 1) \times T_{XDCLK}$ )<br>(default)                                            |
| .        | .        | .        | .        | .        | .        |                                                                                                              |
| 1        | 1        | 1        | 1        | 1        | 1        | 63                                                                                                           |

## 7.4 Status Register

The status register indicates the current status of the transceiver and is readable via the 4-wire serial interface. Setting Power\_On or P\_On\_Aux or an event on ST1, ST2, ST3, ST4 or ST5 is indicated by an IRQ.

Reading the status register resets the bits Power\_On, Low\_Batt, P\_On\_Aux and the IRQ.

### 7.4.1 Status Register (ADR 8)

Table 7-22. Status Register

| Status Bit | Function                                                                                                         |
|------------|------------------------------------------------------------------------------------------------------------------|
| ST5        | Status of pin T5<br>Pin T5 = 0 → ST5 = 1<br>Pin T5 = 1 → ST5 = 0<br>(see <a href="#">Figure 7-3 on page 39</a> ) |
| ST4        | Status of pin T4<br>Pin T4 = 0 → ST4 = 1<br>Pin T4 = 1 → ST4 = 0<br>(see <a href="#">Figure 7-3 on page 39</a> ) |
| ST3        | Status of pin T3<br>Pin T3 = 0 → ST3 = 1<br>Pin T3 = 1 → ST3 = 0<br>(see <a href="#">Figure 7-3 on page 39</a> ) |
| ST2        | Status of pin T2<br>Pin T2 = 0 → ST2 = 1<br>Pin T2 = 1 → ST2 = 0<br>(see <a href="#">Figure 7-3 on page 39</a> ) |
| ST1        | Status of pin T1<br>Pin T1 = 0 → ST1 = 1<br>Pin T1 = 1 → ST1 = 0<br>(see <a href="#">Figure 7-3 on page 39</a> ) |

**Table 7-22. Status Register (Continued)**

| Status Bit | Function                                                                                                                                                                                                                                                                                         |
|------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Power_On   | Indicates that the transceiver was woken up by pin PWR_ON (rising edge on pin PWR_ON). During Power_On = 1, the bits VSOUT_EN and CLK_ON in control register 3 are set to “1”. (see <a href="#">Figure 7-4 on page 40</a> )                                                                      |
| Low_Batt   | Indicates that output voltage on pin VSOUT is too low ( $V_{VSOUT} < 2.38V$ typically), (see <a href="#">Figure 7-5 on page 41</a> )                                                                                                                                                             |
| P_On_Aux   | Indicates that the auxiliary supply voltage on pin VAUX is high enough to operate.<br>State transition:<br>a) OFF mode → AUX mode (see <a href="#">Figure 5-2 on page 27</a> )<br>b) IDLE mode ( $VSOUT = VS1$ ) → IDLE mode ( $VSOUT = V_{REG2}$ ) (see <a href="#">Figure 7-6 on page 42</a> ) |

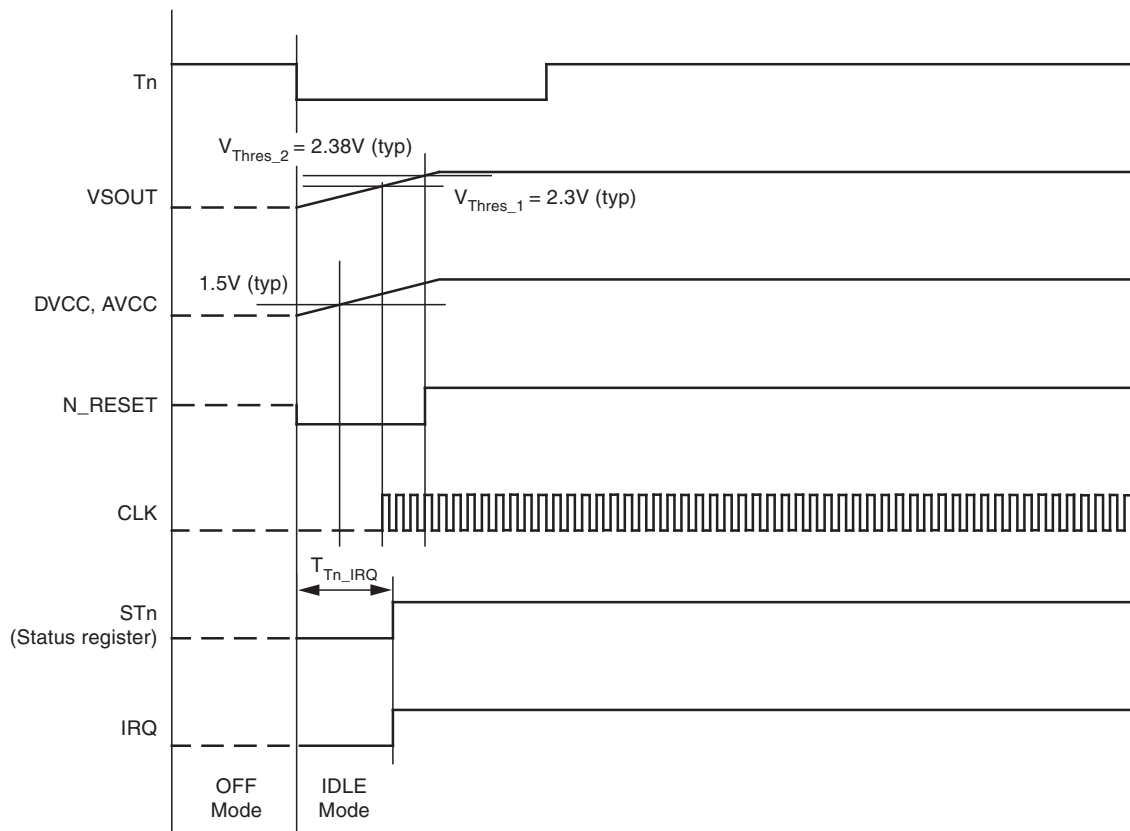
## 7.5 Pin Tn

To switch the transceiver from OFF to IDLE mode, pin Tn must be set to “0” (maximum  $0.2 \times V_{VS2}$ ) for at least  $T_{Tn\_IRQ}$  (see [Figure 7-2](#)). The transceiver recognizes the negative edge, sets pin N\_RESET to low and switches on DVCC, AVCC and the power supply for external devices VSOUT.

If  $V_{DVCC}$  exceeds 1.5V (typically) and the XTO is settled, the digital control logic is active and sets the status bit STn to “1” and an interrupt is issued ( $T_{Tn\_IRQ}$ ).

After the voltage on pin VSOUT exceeds 2.3V (typically) and the start-up time of the XTO is elapsed, the output clock on pin CLK is available. Because the enabling of pin CLK is asynchronous, the first clock cycle may be incomplete. N\_RESET is set to high if  $V_{VSOUT}$  exceeds 2.38V (typically) and the XTO is settled.

**Figure 7-2. Timing Pin Tn, Status Bit STn**



If the transceiver is in any active mode (IDLE, AUX, TX, RX, RX\_Polling), an integrated debounce logic is active. If there is an event on pin Tn a debounce counter is set to 0 ( $T = 0$ ) and started. The status is updated, an interrupt is issued and the debounce counter is stopped after reaching the counter value  $T = 8195 \times T_{DCLK}$ .

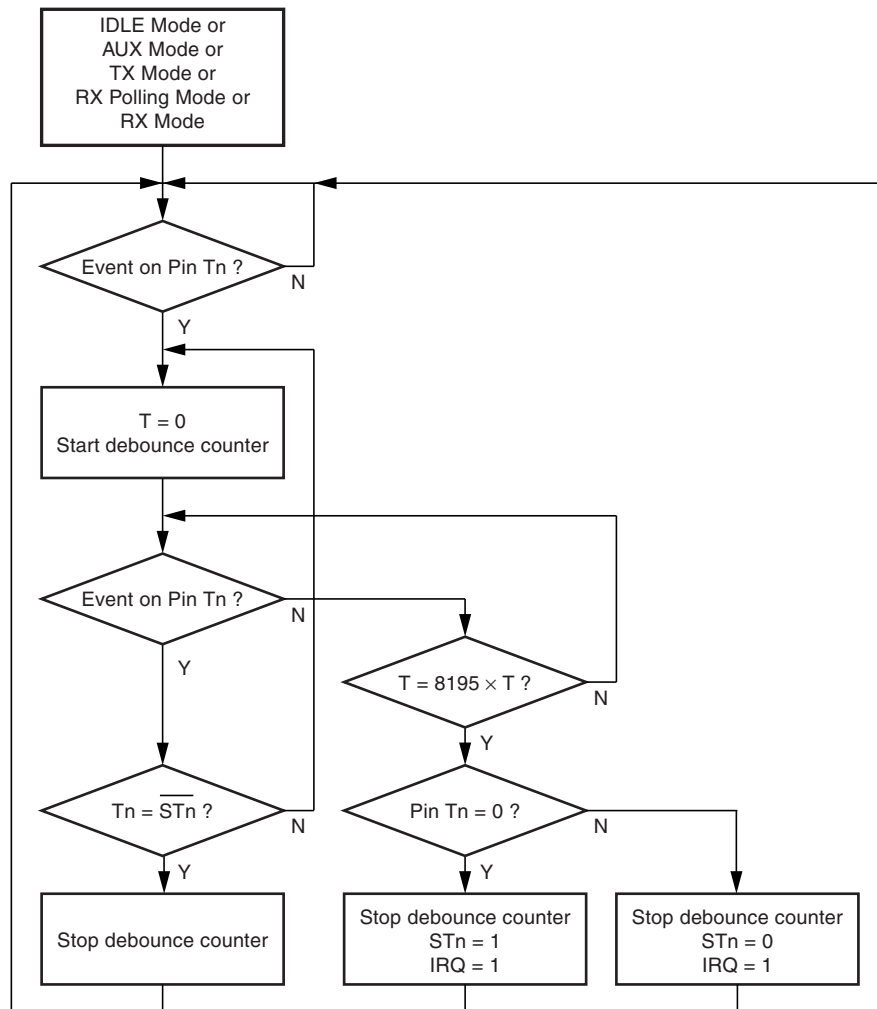
An event on the same key input before reaching  $T = 8195 \times T_{DCLK}$  stops the debounce counter. An event on an other key input before reaching  $T = 8195 \times T_{DCLK}$  resets and restarts the debounce counter.

While the debounce counter is running, the bits VSOUT\_EN and CLK\_ON in control register 3 are set to "1".

The interrupt is deleted after reading the status register or executing the command Delete\_IRQ.

If pin Tn is not used, it can be left open because of an internal pull-up resistor (typically 50k $\Omega$ ).

**Figure 7-3. Timing Flow Pin Tn, Status Bit STn**



## 7.6 Pin PWR\_ON

To switch the transceiver from OFF to IDLE mode, pin PWR\_ON must be set to “1” (minimum  $0.8 \times V_{VS2}$ ) for at least  $T_{PWR\_ON}$  (see Figure 7-4). The transceiver recognizes the positive edge, sets pin N\_RESET to low, and switches on DVCC, AVCC and the power supply for external devices VSOUT.

If  $V_{DVCC}$  exceeds 1.5V (typically) and the XTO is settled, the digital control logic is active and sets the status bit Power\_On to “1” and an interrupt is issued ( $T_{PWR\_ON\_IRQ\_1}$ ).

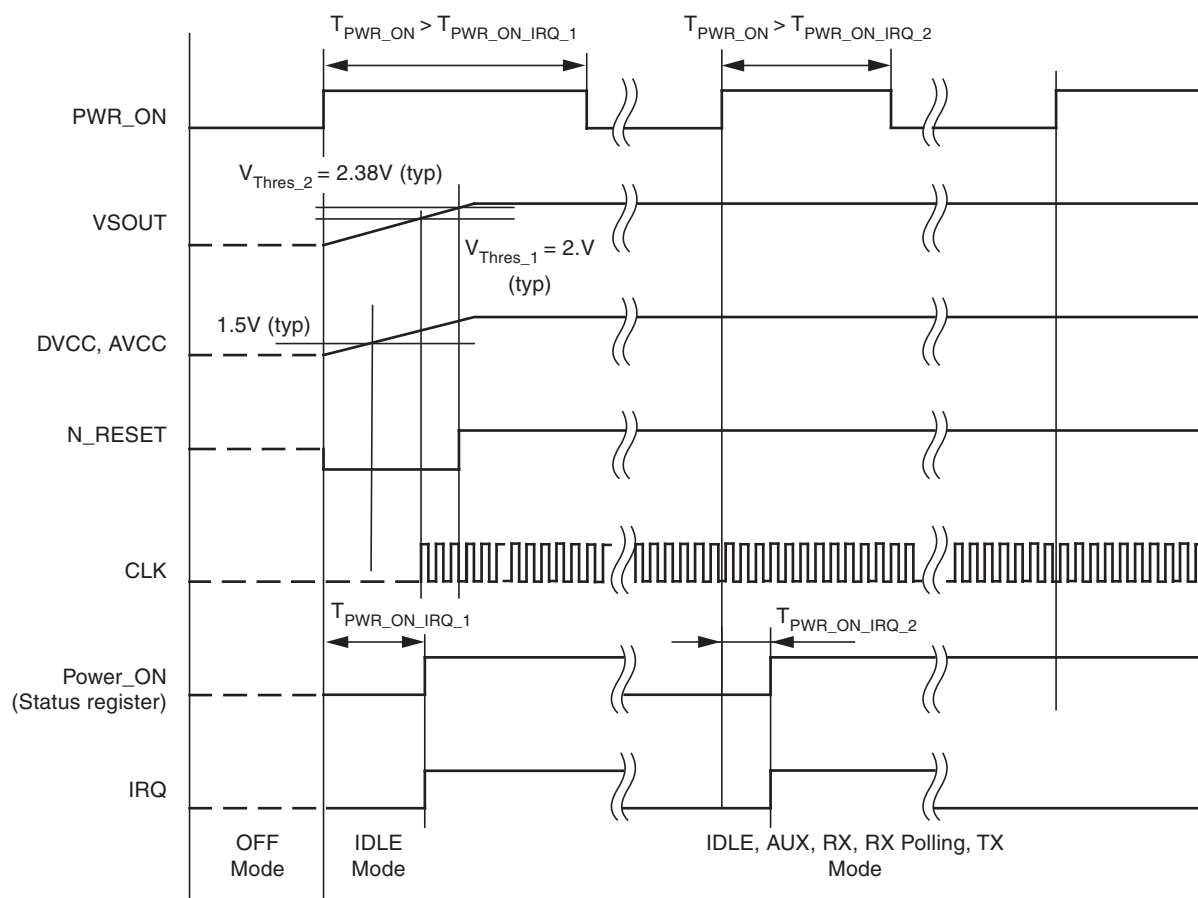
After the voltage on pin VSOUT exceeds 2.3V (typically) and the start-up time of the XTO is elapsed the output clock on pin CLK is available. Because the enabling of pin CLK is asynchronous, the first clock cycle may be incomplete. N\_RESET is set to high if  $V_{VSOUT}$  exceeds 2.38V (typically) and the XTO is settled.

If the transceiver is in any active mode (IDLE, AUX, RX, RX\_Polling, TX), a positive edge on pin PWR\_ON sets Power\_On to “1” (after  $T_{PWR\_ON\_IRQ\_2}$ ). The state transition Power\_On 0 → 1 generates an interrupt. If Power\_On is still “1” during the positive edge on pin PWR\_ON no interrupt is issued. Power\_On and the interrupt are deleted after reading the status register.

During Power\_On = 1, the bits VSOUT\_EN and CLK\_ON in control register 3 are set to “1”.

Note: It is not possible to set the transceiver to OFF mode by setting pin PWR\_ON to “0”. If pin PWR\_ON is not used, it must be connected to GND.

**Figure 7-4. Timing Pin PWR\_ON, Status Bit Power\_On**

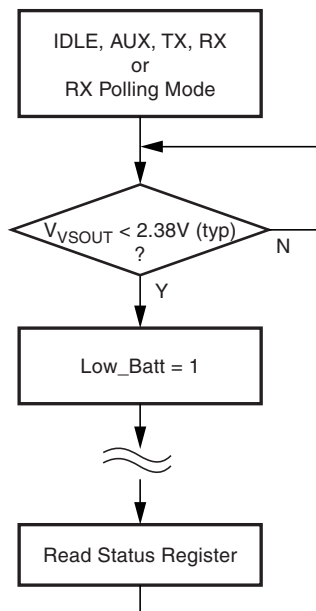


## 7.7 Low Battery Indicator

The status bit Low\_Batt is set to “1” if the voltage  $V_{VSOUT}$  on pin VSOUT drops below 2.38V (typically).

Low\_Batt is set to “0” if  $V_{VSOUT}$  exceeds  $V_{Thres\_2}$  and the status register is read via the 4-wire serial interface (see [Figure 5-3 on page 29](#)).

**Figure 7-5. Timing Status Bit Low\_Batt**



## 7.8 Pin VAUX

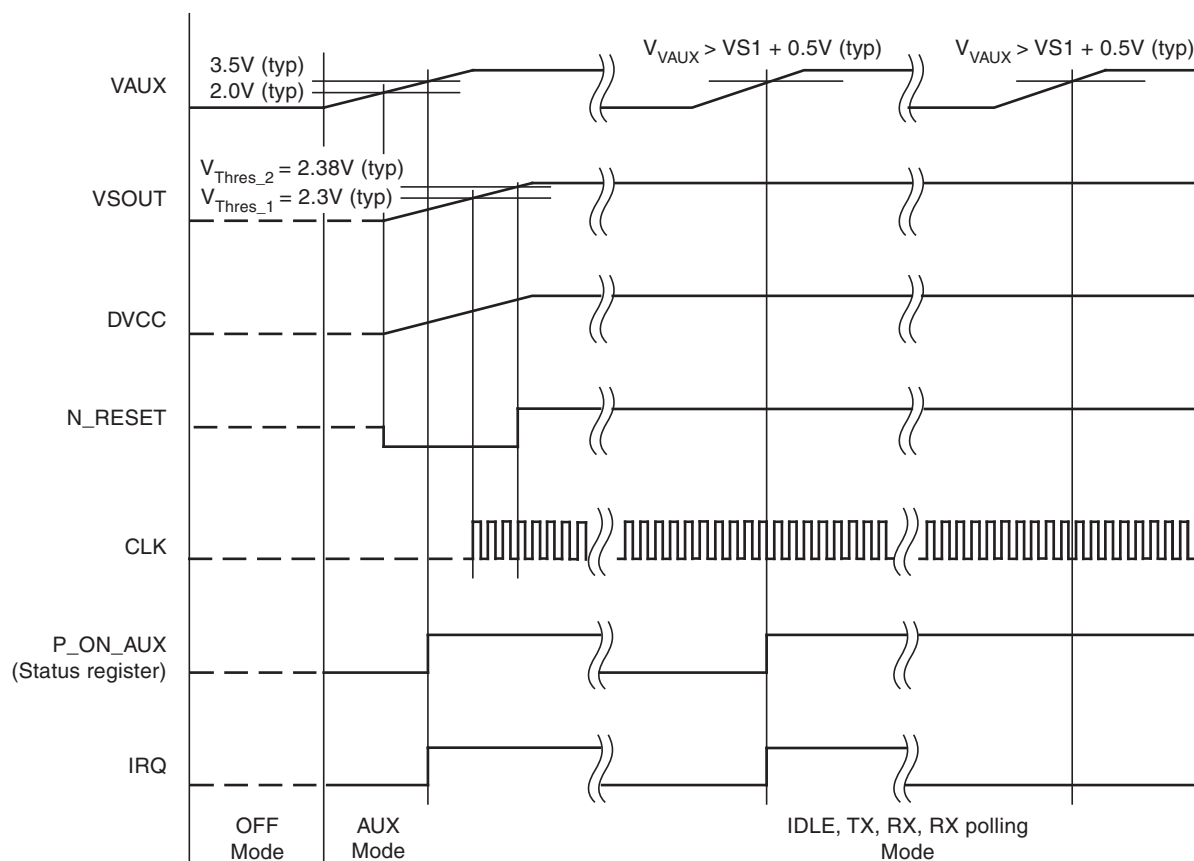
To switch the transceiver from OFF to AUX mode, the voltage  $V_{VAUX}$  on pin VAUX must exceed 3.5V (typically) (see [Figure 7-6 on page 42](#)). If  $V_{VAUX}$  exceeds 2V (typically) pin N\_RESET is set to low, and DVCC and the power supply for external devices VSOUT are switched on.

If  $V_{VAUX}$  exceeds 3.5V (typically) the status bit P\_On\_Aux is set to “1” and an interrupt is issued.

After the voltage on pin VSOUT exceeds 2.3V (typically) and the start-up time of the XTO is elapsed, the output clock on pin CLK is available. Because the enabling of pin CLK is asynchronous, the first clock cycle may be incomplete. N\_RESET is set to high if  $V_{VSOUT}$  exceeds 2.38V (typically) and the XTO is settled.

If the transceiver is in any active mode (IDLE, TX, RX, RX\_Polling), a positive edge on pin VAUX and  $V_{VAUX} > VS1 + 0.5V$  sets P\_On\_Aux to “1”. The state transition P\_On\_Aux 0 → 1 generates an interrupt. If P\_On\_Aux is still “1” during the positive edge on pin VAUX no interrupt is issued. P\_On\_Aux and the interrupt are deleted after reading the status register.

**Figure 7-6. Timing Pin VAUX, Status Bit P\_On\_Aux**



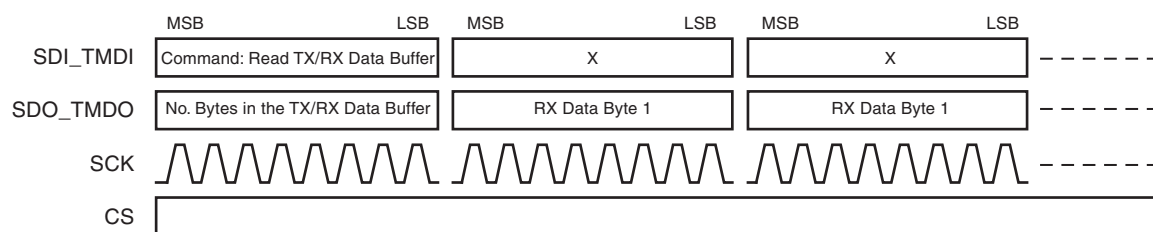
## 8. Transceiver Configuration

The configuration of the transceiver takes place via a 4-wire serial interface (CS, SCK, SDI\_TMDI, SDO\_TMDO) and is organized in 8-bit units. The configuration is initiated with an 8-bit command. While shifting the command into pin SDI\_TMDI, the number of bytes in the TX/RX data buffer are available on pin SDO\_TMDO. The read and write commands are followed by one or more 8-bit data units. Each 8-bit data transmission begins with the MSB. The serial interface is in the reset state if the level on pin CS = Low.

### 8.1 Command: Read TX/RX Data Buffer

During a RX operation, the user can read the received bytes in the TX/RX data buffer successively.

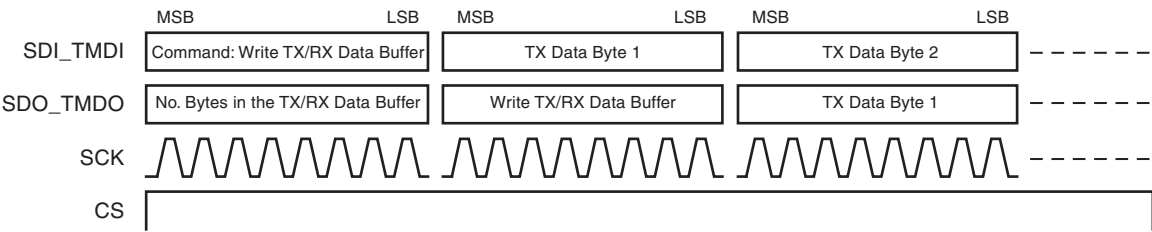
**Figure 8-1. Read TX/RX Data Buffer**



8.2 Command: Write TX/RX Data Buffer

During a TX operation the user can write the bytes in the TX/RX data buffer successively. An echo of the command and the TX data bytes are provided for the microcontroller on pin SDO\_TMDO.

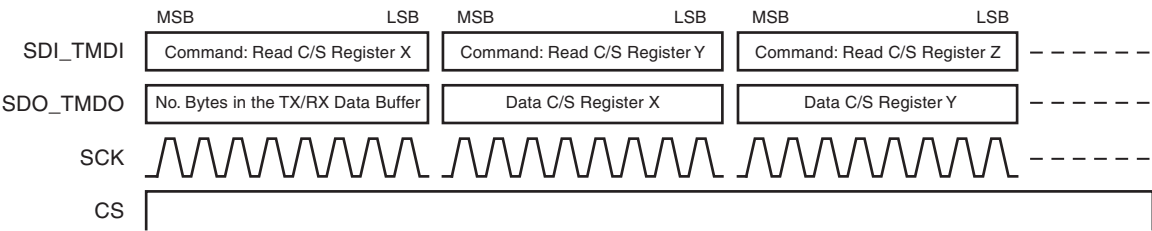
Figure 8-2. Write TX/RX Data Buffer



8.3 Command: Read Control/Status Register

The control and status registers can be read individually or successively.

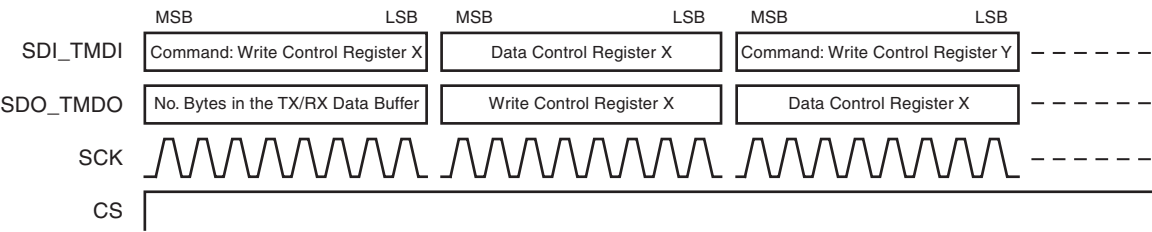
Figure 8-3. Read Control/Status Register



8.4 Command: Write Control Register

The control registers can be written individually or successively. An echo of the command and the data bytes are provided for the microcontroller on pin SDO\_TMDO.

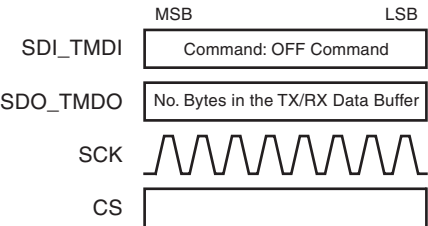
Figure 8-4. Write Control Register



8.5 Command: OFF Command

If AVCC\_EN in control register 1 is “0”, the input level on pin PWR\_ON is low and on the key inputs Tn is high, then the OFF command sets the transceiver in the OFF mode.

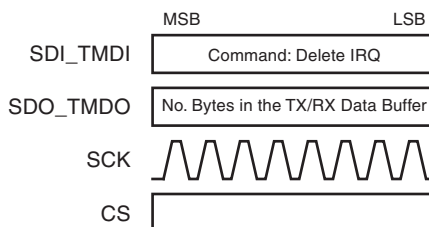
Figure 8-5. OFF Command



## 8.6 Command: Delete IRQ

The delete IRQ command sets pin IRQ to low.

**Figure 8-6. Delete IRQ**



## 8.7 Command Structure

The three most significant bits of the command (bit 5 to bit 7) indicate the command type. Bit 0 to bit 4 describe the target address when reading or writing a control or status register. In all other commands bit 0 to bit 4 have no effect and should be set to “0” for compatibility with future products.

**Table 8-1. Command Structure**

| Command                      | MSB   |       |       |       |       |       |       | LSB   |
|------------------------------|-------|-------|-------|-------|-------|-------|-------|-------|
|                              | Bit 7 | Bit 6 | Bit 5 | Bit 4 | Bit 3 | Bit 2 | Bit 1 | Bit 0 |
| Read TX/RX data buffer       | 0     | 0     | 0     | x     | x     | x     | x     | x     |
| Write TX/RX data buffer      | 0     | 0     | 1     | x     | x     | x     | x     | x     |
| Read control/status register | 0     | 1     | 0     | A4    | A3    | A2    | A1    | A0    |
| Write control register       | 0     | 1     | 1     | A4    | A3    | A2    | A1    | A0    |
| OFF command                  | 1     | 0     | 0     | X     | X     | X     | X     | X     |
| Delete IRQ                   | 1     | 0     | 1     | X     | X     | X     | X     | X     |
| Not used                     | 1     | 1     | 0     | X     | X     | X     | X     | X     |
| Not used                     | 1     | 1     | 1     | X     | X     | X     | X     | X     |

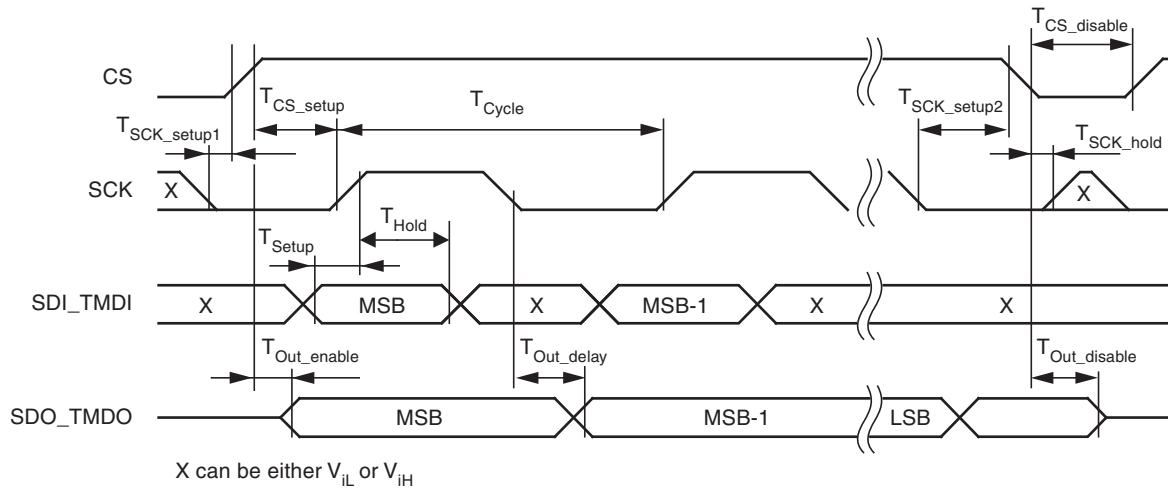
## 8.8 4-wire Serial Interface

The 4-wire serial interface consists of the Chip Select (CS), the Serial Clock (SCK), the Serial Data Input (SDI\_TMDI) and the Serial Data Output (SDO\_TMDO). Data is transmitted/received bit by bit in synchronization with the serial clock.

**Note:** If the output level on pin N\_RESET is low, no data communication with the microcontroller is possible.

When CS is low and the transparent mode is inactive (T\_MODE = 0), SDO\_TMDO is in a high impedance state. When CS is low and the transparent mode is active (T\_MODE = 1), the RX data stream is available on pin SDO\_TMDO.

**Figure 8-7. Serial Timing**



## 9. Operation Modes

### 9.1 RX Operation

The transceiver is set to RX operation with the bits OPM0 and OPM1 in control register 1.

**Table 9-1. Control Register 1**

| OPM1 | OPM0 | Function        |
|------|------|-----------------|
| 1    | 0    | RX polling mode |
| 1    | 1    | RX mode         |

The transceiver is designed to consume less than 1mA in RX operation while remaining sensitive to signals from a corresponding transmitter. This is achieved via the polling circuit. This circuit enables the signal path periodically for a short time. During this time the bit-check logic verifies the presence of a valid transmitter signal. Only if a valid signal is detected does the transceiver remain active and transfer the data to the connected microcontroller. This transfer takes place either via the TX/RX data buffer or via the pin SDO\_TMDO. When there is no valid signal present, the transceiver is in sleep mode most of the time, resulting in low current consumption. This condition is called RX polling mode. A connected microcontroller can be disabled during this time.

All relevant parameters of the polling logic can be configured by the connected microcontroller. This flexibility enables the user to meet the specifications in terms of current consumption, system response time, data rate, etc.

In RX mode the RF transceiver is enabled permanently and the bit-check logic verifies the presence of a valid transmitter signal. When a valid signal is detected the transceiver transfers the data to the connected microcontroller. This transfer takes place either via the TX/RX data buffer or via the pin SDO\_TMDO.

### 9.1.1 RX Polling Mode

When the transceiver is in RX polling mode it stays in a continuous cycle of three different modes. In sleep mode the RF transceiver is disabled for the time period  $T_{\text{Sleep}}$  while consuming low current of  $I_S = I_{\text{IDLE\_X}}$ . During the start-up period,  $T_{\text{Startup\_PLL}}$  and  $T_{\text{Startup\_Sig\_Proc}}$ , all signal processing circuits are enabled and settled. In the following bit-check mode, the incoming data stream is analyzed bit by bit to see if it is a valid transmitter signal. If no valid signal is present, the transceiver is set back to sleep mode after the period  $T_{\text{Bit-check}}$ . This period varies check by check as it is a statistical process. An average value for  $T_{\text{Bit-check}}$  is given in the electrical characteristics. During  $T_{\text{Startup\_PLL}}$  the current consumption is  $I_S = I_{\text{Startup\_PLL\_X}}$ . During  $T_{\text{Startup\_Sig\_Proc}}$  and  $T_{\text{Bit-check}}$  the current consumption is  $I_S = I_{\text{RX\_X}}$ . The condition of the transceiver is indicated on pin  $\text{RX\_ACTIVE}$  (see [Figure 9-1 on page 47](#) and [Figure 9-2 on page 48](#)). The average current consumption in RX polling mode  $I_P$  is different in 1 Li battery application (3V), 2 Li battery application (6V) or Base-station Application (5V). To calculate  $I_P$  the index X must be replaced by VS1, VS2 in 1 Li battery application (3V), VS2 in 2 Li battery application (6V) or VS2, VAUX in Base-station Application (5V) (see section “[Electrical Characteristics: General](#)” on page 59).

$$I_P = \frac{I_{\text{IDLE\_X}} \times T_{\text{Sleep}} + I_{\text{Startup\_PLL\_X}} \times T_{\text{Startup\_PLL}} + I_{\text{RX\_X}} \times (T_{\text{Startup\_Sig\_Proc}} + T_{\text{Bit-check}})}{T_{\text{Sleep}} + T_{\text{Startup\_PLL}} + T_{\text{Startup\_Sig\_Proc}} + T_{\text{Bit-check}}}$$

To save current it is recommended that CLK and  $V_{\text{VSOUT}}$  be disabled during RX polling mode.  $I_P$  does not include the current of the Microcontroller\_Interface,  $I_{\text{VSINT}}$ , or the current of an external device connected to pin VSOUT (for example, microcontroller). If CLK and/or VSOUT is enabled during RX polling mode the current consumption is calculated as follows:

$$I_{\text{S\_Poll}} = I_P + I_{\text{VSINT}} + I_{\text{EXT}}$$

During  $T_{\text{Sleep}}$ ,  $T_{\text{Startup\_PLL}}$  and  $T_{\text{Startup\_Sig\_Proc}}$ , the transceiver is not sensitive to a transmitter signal. To guarantee the reception of a transmitted command, the transmitter must start the telegram with an adequate preburst. The required length of the preburst,  $T_{\text{Preamble}}$ , depends on the polling parameters  $T_{\text{Sleep}}$ ,  $T_{\text{Startup\_PLL}}$ ,  $T_{\text{Startup\_Sig\_Proc}}$  and  $T_{\text{Bit-check}}$ . Thus,  $T_{\text{Bit-check}}$  depends on the actual bit rate and the number of bits ( $N_{\text{Bit-check}}$ ) to be tested.

$$T_{\text{Preamble}} \geq T_{\text{Sleep}} + T_{\text{Startup\_PLL}} + T_{\text{Startup\_Sig\_Proc}} + T_{\text{Bit-check}}$$

### 9.1.2 Sleep Mode

The length of period  $T_{\text{Sleep}}$  is defined by the 5-bit word sleep in control register 4, the extension factor  $X_{\text{Sleep}}$  defined by the bit  $X_{\text{Sleep}}$  in control register 4, and the basic clock cycle  $T_{\text{DCLK}}$ . It is calculated to be:

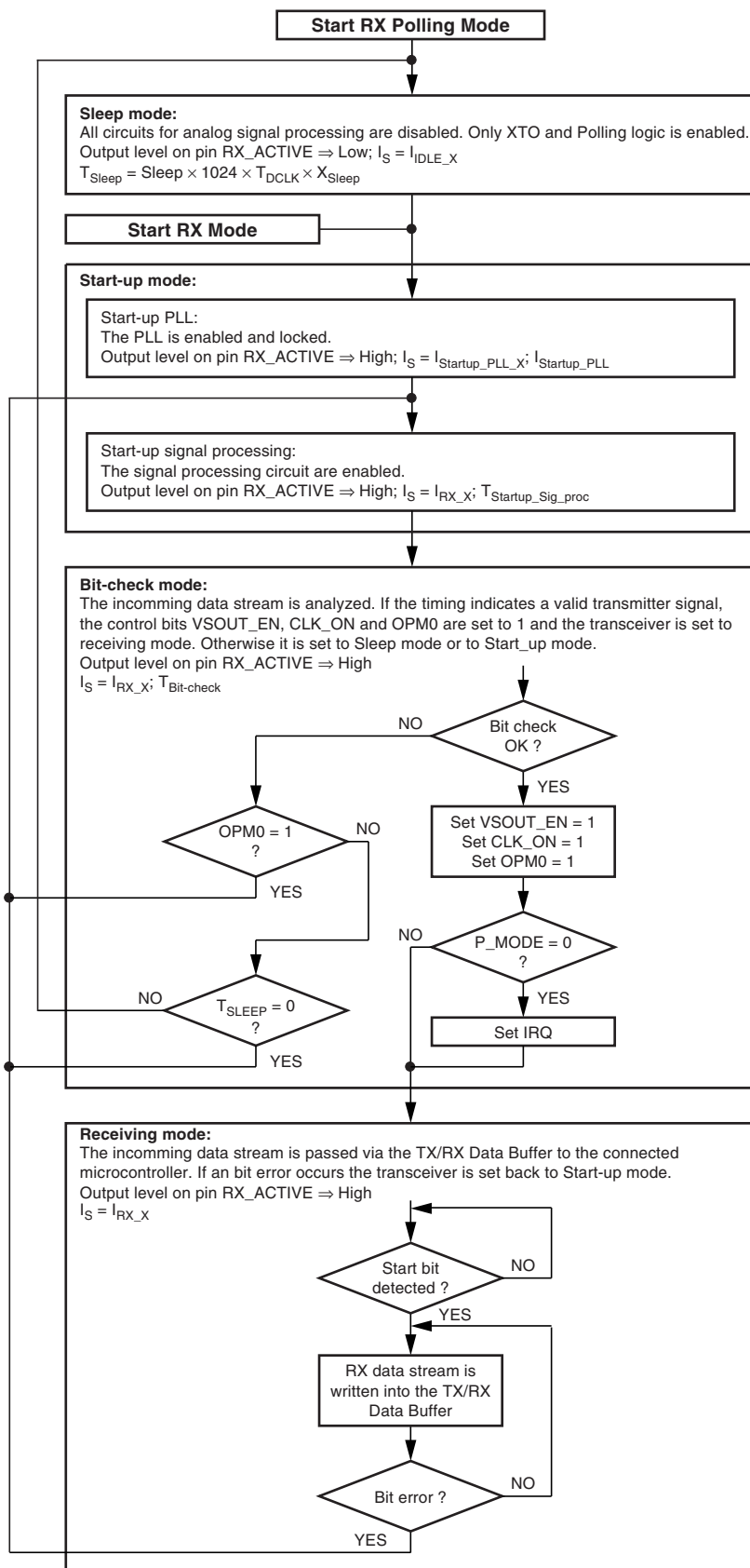
$$T_{\text{Sleep}} = \text{Sleep} \times 1024 \times T_{\text{DCLK}} \times X_{\text{Sleep}}$$

In US and European applications, the maximum value of  $T_{\text{Sleep}}$  is about 38ms if  $X_{\text{Sleep}}$  is set to 1 (which is done by setting the bit  $X_{\text{Sleep}}$  in control register 4 to “0”). The time resolution is about 1.2ms in that case. The sleep time can be extended to about 300ms by setting  $X_{\text{Sleep}}$  to 8 (which is done by setting  $X_{\text{Sleep}}$  in control register 4 to “1”), the time resolution is then about 9.6ms.

### 9.1.3 Start-up Mode

During  $T_{\text{Startup\_PLL}}$  the PLL is enabled and starts up. If the PLL is locked, the signal processing circuit starts up ( $T_{\text{Startup\_Sig\_Proc}}$ ). After the start-up time all circuits are in stable condition and ready to receive.

**Figure 9-1. Flow Chart Polling Mode/RX Mode ( $T\_MODE = 0$ , Transparent Mode Inactive)**



Sleep: Defined by bits Sleep 0 to Sleep 4 in Control Register 4

$X_{Sleep}$ : Defined by bit XSleep in Control register 4

$T_{DCLK}$ : Basic clock cycle

$T_{Startup\_PLL}$ :  $798.5 \times T_{DCLK}$  (typ)

$T_{Startup\_Sig\_Proc}$ :  $882 \times T_{DCLK}$  (BR\_Range 0)  
 $498 \times T_{DCLK}$  (BR\_Range 1)  
 $306 \times T_{DCLK}$  (BR\_Range 2)  
 $210 \times T_{DCLK}$  (BR\_Range 3)

Is defined by the selected baud rate range and  $T_{DCLK}$ . The baud-rate range is defined by bit Baud 0 and Baud 1 in Control Register 6.

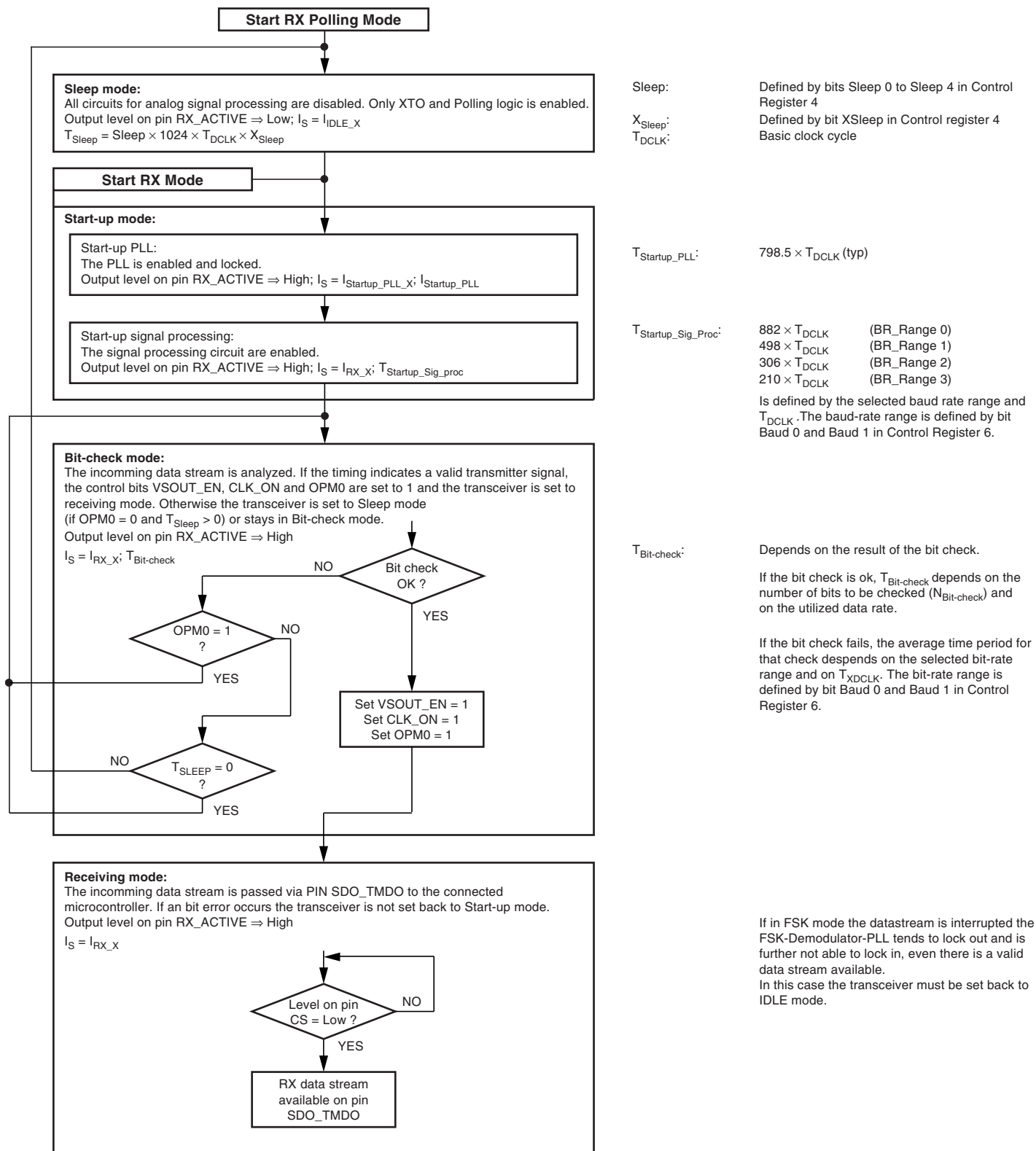
$T_{Bit-check}$ : Depends on the result of the bit check.

If the bit check is ok,  $T_{Bit-check}$  depends on the number of bits to be checked ( $N_{Bit-check}$ ) and on the utilized data rate.

If the bit check fails, the average time period for that check depends on the selected bit-rate range and on  $T_{DCLK}$ . The bit-rate range is defined by bit Baud 0 and Baud 1 in Control Register 6.

If the transceiver detects a bit error after a successful bit check and before the start bit is detected pin IRQ will be set to high (only if  $P\_MODE = 0$ ) and the transceiver is set back to start-up mode.

**Figure 9-2. Flow Chart Polling Mode/RX Mode (T\_MODE = 1, Transparent Mode Active)**



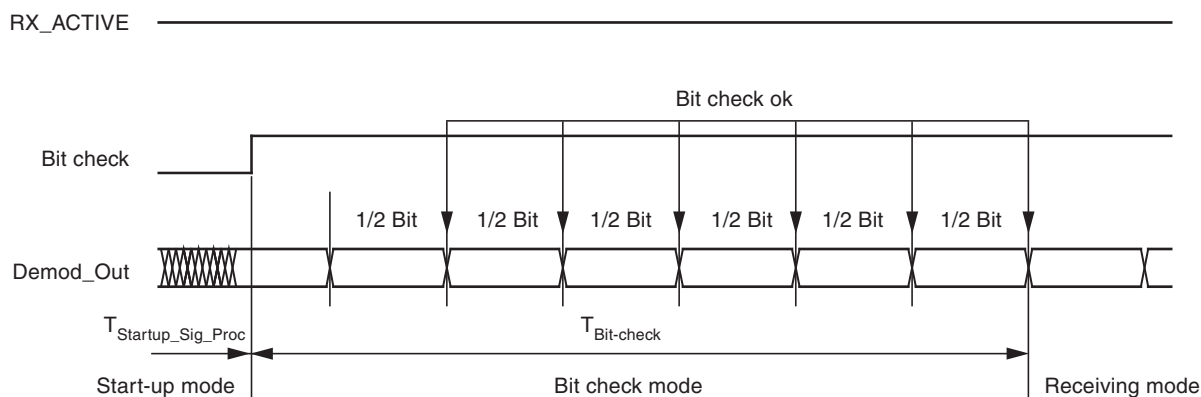
### 9.1.4 Bit-check Mode

In bit-check mode the incoming data stream is examined to distinguish between a valid signal from a corresponding transmitter and signals due to noise. This is done by subsequent time frame checks where the distance between 2 signal edges are continuously compared to a programmable time window. The maximum count of this edge-to-edge test before the transceiver switches to receiving mode is also programmable.

### 9.1.5 Configuration of the Bit Check

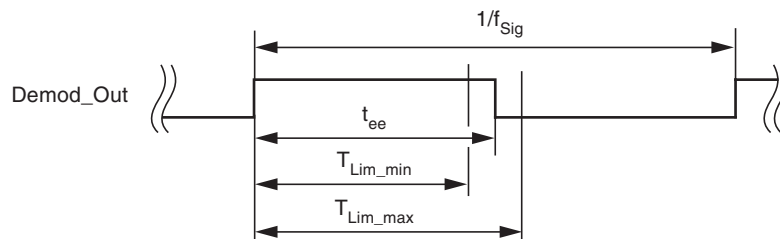
Assuming a modulation scheme that contains two edges per bit, two time frame checks verify one bit. This is valid for Manchester, Bi-phase and most other modulation schemes. The maximum count of bits to be checked can be set to 0, 3, 6 or 9 bits via the variable  $N_{\text{Bit-check}}$  in control register 5. This implies 0, 6, 12 and 18 edge-to-edge checks, respectively. If  $N_{\text{Bit-check}}$  is set to a higher value, the transceiver is less likely to switch to receiving mode due to noise. In the presence of a valid transmitter signal, the bit check takes less time if  $N_{\text{Bit-check}}$  is set to a lower value. In RX polling mode, the bit-check time is not dependent on  $N_{\text{Bit-check}}$  if no valid signal is present. Figure 9-3 shows an example where three bits are tested successfully.

**Figure 9-3. Timing Diagram for Complete Successful Bit Check (Number of Checked Bits: 3)**



As seen in Figure 9-4, the time window for the bit check is defined by two separate time limits. If the edge-to-edge time  $t_{ee}$  is in between the lower bit-check limit  $T_{\text{Lim\_min}}$  and the upper bit-check limit  $T_{\text{Lim\_max}}$ , the check will be continued. If  $t_{ee}$  is smaller than limit  $T_{\text{Lim\_min}}$  or exceeds  $T_{\text{Lim\_max}}$ , the bit check will be terminated and the transceiver switches to sleep mode.

**Figure 9-4. Valid Time Window for Bit Check**



For the best noise immunity, use of a low span between  $T_{Lim\_min}$  and  $T_{Lim\_max}$  is recommended. This is achieved using a fixed frequency at a 50% duty cycle for the transmitter preburst: a “11111...” or a “10101...” sequence in Manchester or Bi-phase is a good choice. A good compromise between sensitivity and susceptibility to noise regarding the expected edge-to-edge time,  $t_{ee}$ , is a time window of  $\pm 38\%$ ; to get the maximum sensitivity the time window should be  $\pm 50\%$  and then  $N_{Bit-check} \geq 6$ . Using preburst patterns that contain various edge-to-edge time periods, the bit-check limits must be programmed according to the required span.

The bit-check limits are determined by means of the formula below:

$$T_{Lim\_min} = Lim\_min \times T_{XDCLK}$$

$$T_{Lim\_max} = (Lim\_max - 1) \times T_{XDCLK}$$

$Lim\_min$  is defined by the bits  $Lim\_min$  0 to  $Lim\_min$  5 in control register 5.

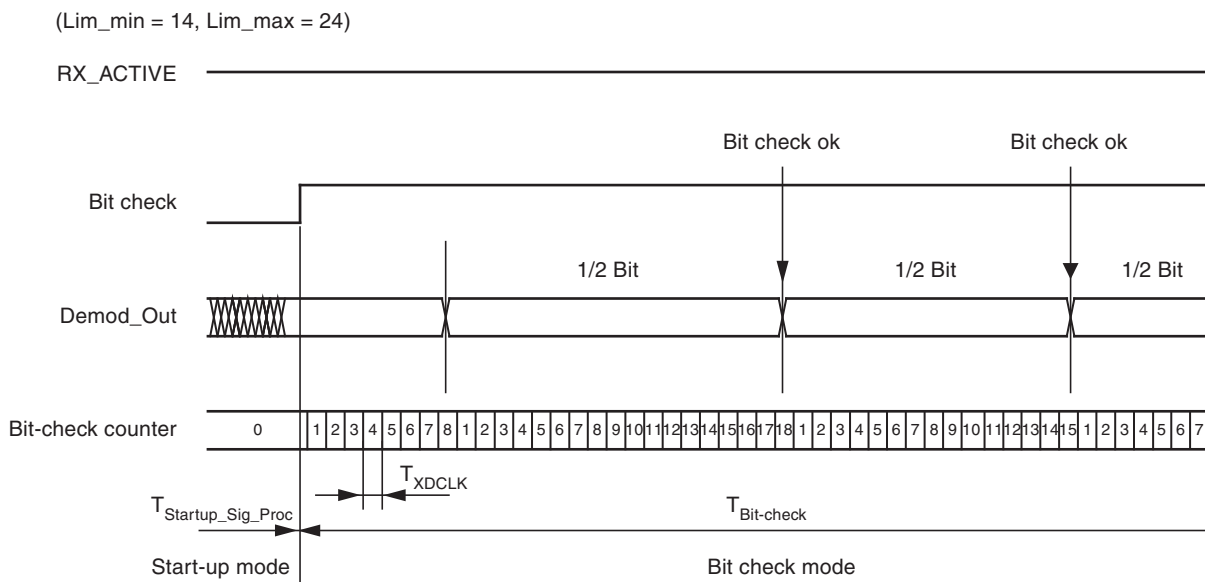
$Lim\_max$  is defined by the bits  $Lim\_max$  0 to  $Lim\_max$  5 in control register 6.

Using the above formulas,  $Lim\_min$  and  $Lim\_max$  can be determined according to the required  $T_{Lim\_min}$ ,  $T_{Lim\_max}$  and  $T_{XDCLK}$ . The time resolution defining  $T_{Lim\_min}$  and  $T_{Lim\_max}$  is  $T_{XDCLK}$ . The minimum edge-to-edge time  $t_{ee}$  is defined in the section “Receiving Mode” on page 52. The lower limit should be set to  $Lim\_min \geq 10$ . The maximum value of the upper limit is  $Lim\_max = 63$ .

Figure 9-5, Figure 9-6 on page 51, and Figure 9-7 on page 51 illustrate the bit check for the bit-check limits  $Lim\_min = 14$  and  $Lim\_max = 24$ . The signal processing circuits are enabled during  $T_{Startup\_PLL}$  and  $T_{Startup\_Sig\_Proc}$ . The output of the ASK/FSK demodulator (Demod\_Out) is undefined during that period. When the bit check becomes active, the bit-check counter is clocked with the cycle  $T_{XDCLK}$ .

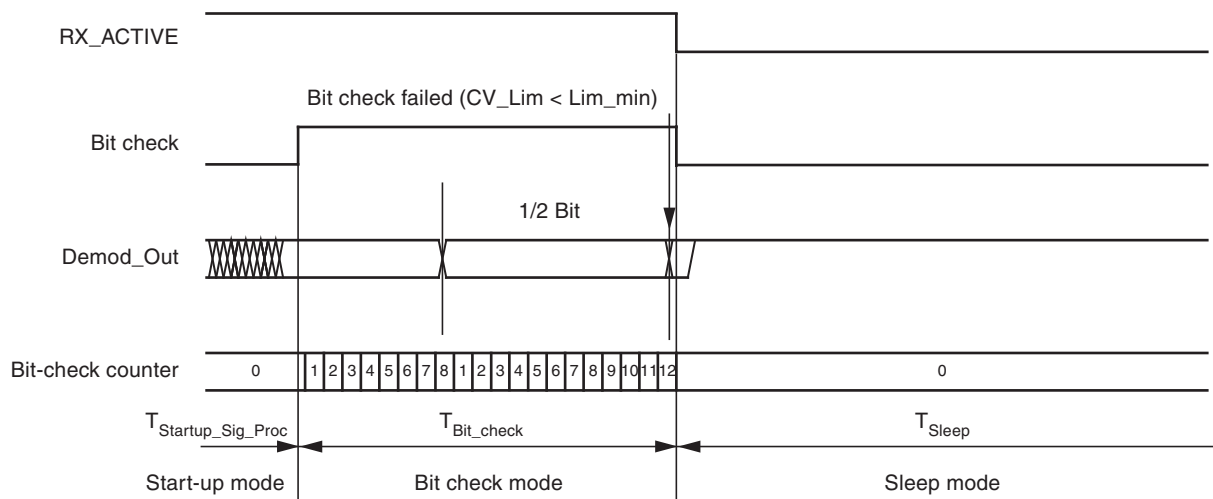
Figure 9-5 shows how the bit check proceeds if the bit-check counter value  $CV\_Lim$  is within the limits defined by  $Lim\_min$  and  $Lim\_max$  at the occurrence of a signal edge. In Figure 9-6 on page 51 the bit check fails because the value  $CV\_Lim$  is lower than the limit  $Lim\_min$ . The bit check also fails if  $CV\_Lim$  reaches  $Lim\_max$ . This is illustrated in Figure 9-7 on page 51.

**Figure 9-5. Timing Diagram During Bit Check**



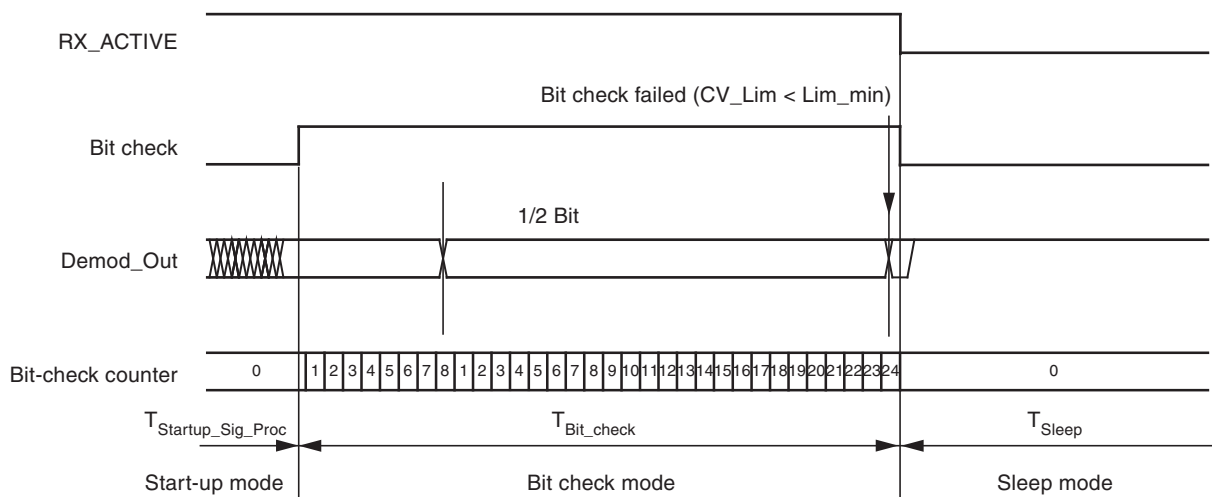
**Figure 9-6. Timing Diagram for Failed Bit Check (Condition  $CV\_Lim < Lim\_min$ )**

( $Lim\_min = 14$ ,  $Lim\_max = 24$ )



**Figure 9-7. Timing Diagram for Failed Bit Check (Condition:  $CV\_Lim \geq Lim\_max$ )**

( $Lim\_min = 14$ ,  $Lim\_max = 24$ )



### 9.1.6 Duration of the Bit Check

If no transmitter is present during the bit check, the output of the ASK/FSK demodulator delivers random signals. The bit check is a statistical process and  $T_{Bit\_check}$  varies for each check. Therefore, an average value for  $T_{Bit\_check}$  is given in the electrical characteristics.  $T_{Bit\_check}$  depends on the selected bit-rate range and on  $T_{XDCLK}$ . A higher bit-rate range causes a lower value for  $T_{Bit\_check}$ , resulting in a lower current consumption in RX polling mode.

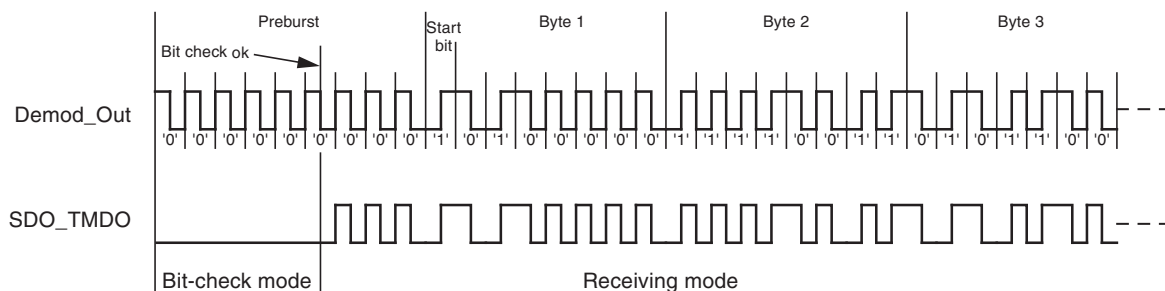
In the presence of a valid transmitter signal,  $T_{Bit\_check}$  is dependent on the frequency of that signal,  $f_{Signal}$ , and the count of the bits,  $N_{Bit\_check}$ . A higher value for  $N_{Bit\_check}$  therefore results in a longer period for  $T_{Bit\_check}$ , requiring a higher value for the transmitter pre-burst,  $T_{Preburst}$ .

### 9.1.7 Receiving Mode

If the bit check was successful for all bits specified by  $N_{\text{Bit-check}}$ , the transceiver switches to receiving mode. To activate a connected microcontroller, the bits VSOUT\_EN and CLK\_ON in control register 3 are set to “1”. An interrupt is issued at pin IRQ if the control bits T\_MODE = 0 and P\_MODE = 0.

If the transparent mode is active (T\_MODE = 1) and the level on pin CS is low (no data transfer via the serial interface), the RX data stream is available on pin SDO\_TMDO (Figure 9-8).

**Figure 9-8. Receiving Mode (TMODE = 1)**



If the transparent mode is inactive (T\_MODE = 0), the received data stream is buffered in the TX/RX data buffer (see Figure 9-9 on page 53). The TX/RX data buffer is only usable for Manchester and Bi-phase coded signals. It is always possible to transfer the data from the data buffer via the 4-wire serial interface to a microcontroller (see Figure 8-1 on page 42).

Buffering of the data stream:

After a successful bit check, the transceiver switches from bit-check mode to receiving mode. In receiving mode the TX/RX data buffer control logic is active and examines the incoming data stream. This is done, as in the bit check, by subsequent time frame checks where the distance between two edges is continuously compared to a programmable time window as illustrated in Figure 9-9 on page 53. Only two time differences between two edges in Manchester and Bi-phase coded signals are valid (T and 2T).

The limits for T are the same as used for the bit check. They can be programmed in control register 5 and 6 (Lim\_min, Lim\_max).

The limits for 2T are calculated as follows:

Lower limit of 2T:

$$\text{Lim\_min\_2T} = (\text{Lim\_min} + \text{Lim\_max}) - (\text{Lim\_max} - \text{Lim\_min})/2$$

$$T_{\text{Lim\_min\_2T}} = \text{Lim\_min\_2T} \times T_{\text{XDCLK}}$$

Upper limit of 2T:

$$\text{Lim\_max\_2T} = (\text{Lim\_min} + \text{Lim\_max}) + (\text{Lim\_max} - \text{Lim\_min})/2$$

$$T_{\text{Lim\_max\_2T}} = (\text{Lim\_max\_2T} - 1) \times T_{\text{XDCLK}}$$

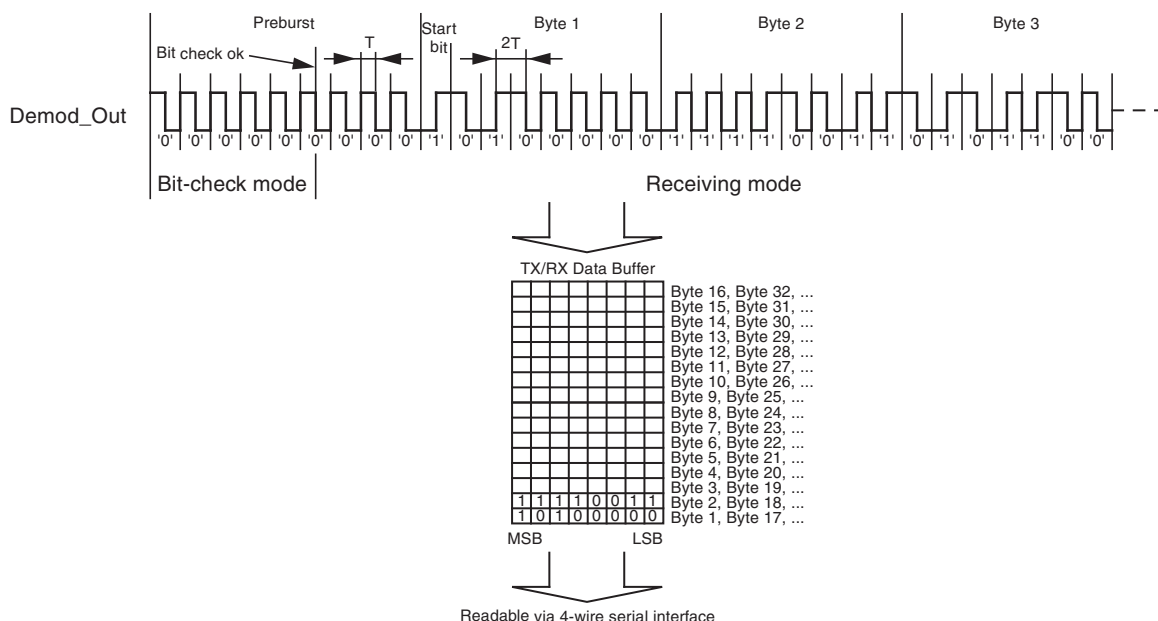
If the result of Lim\_min\_2T or Lim\_max\_2T is not an integer value, it will be rounded up.

If the TX/RX data buffer control logic detects the start bit, the data stream is written in the TX/RX data buffer byte by byte. The start bit is part of the first data byte and must be different from the bits of the preburst. If the preburst consists of a sequence of “00000...”, the start bit must be a “1”. If the preburst consists of a sequence of “11111...”, the start bit must be a “0”.

If the data stream consists of more than 16 bytes, a buffer overflow occurs and the TX/RX data buffer control logic overwrites the bytes already stored in the TX/RX data buffer. Therefore, it is very important to ensure that the data is read in time so that no buffer overflow occurs (see Figure 8-1 on page 42). There is a counter that indicates the number of received bytes in the TX/RX data buffer (see section “Transceiver Configuration” on page 42). If a byte is transferred to the microcontroller, the counter is decremented; if a byte is received, the counter is incremented. The counter value is available via the 4-wire serial interface.

An interrupt is issued if the counter (while counting up) reaches the value defined by the control bits IR0 and IR1 in control register 1.

**Figure 9-9. Receiving Mode (TMODE = 0)**



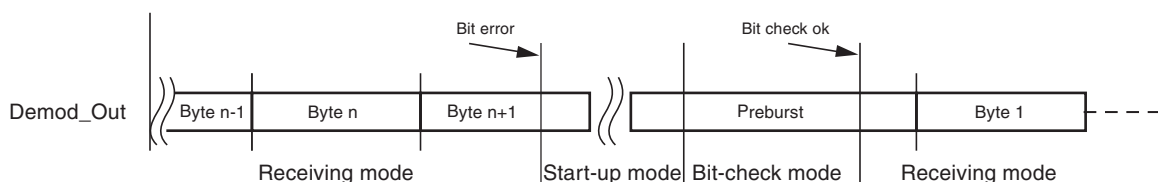
If the TX/RX data buffer control logic detects a bit error, an interrupt is issued and the transceiver is set back to the start-up mode (see [Figure 9-1 on page 47](#), [Figure 9-2 on page 48](#) and [Figure 9-10](#)).

Bit error: a)  $t_{ee} < T_{Lim\_min}$  or  $T_{Lim\_max} < t_{ee} < T_{Lim\_min\_2T}$  or  $t_{ee} > T_{Lim\_max\_2T}$   
b) Logical error (no edge detected in the bit center)

Note: The byte consisting of the bit error will not be stored in the TX/RX data buffer. Thus, it is not available via the 4-wire serial interface.

Writing the control register 1, 4, 5 or 6 during receiving mode resets the TX/RX data buffer control logic and the counter which indicates the number of received bytes. If the bits OPM0 and OPM1 are still "1" after writing to a control register, the transceiver changes to the start-up mode (start-up signal processing).

**Figure 9-10. Bit Error (TMODE = 0)**



**Table 9-2. RX Modulation Scheme**

| Mode | ASK/_NFSK | T_MODE | RF <sub>IN</sub>                                     | Bit in TX/RX Data Buffer | Level on Pin SD0_TMD0 |
|------|-----------|--------|------------------------------------------------------|--------------------------|-----------------------|
| RX   | 0         | 0      | $f_{FSK\_L} \rightarrow f_{FSK\_H}$                  | 1                        | X                     |
|      |           | 0      | $f_{FSK\_H} \rightarrow f_{FSK\_L}$                  | 0                        | X                     |
|      |           | 1      | $f_{FSK\_H}$                                         | —                        | 1                     |
|      |           | 1      | $f_{FSK\_L}$                                         | —                        | 0                     |
|      | 1         | 0      | $f_{ASK} \text{ off} \rightarrow f_{ASK} \text{ on}$ | 1                        | X                     |
|      |           | 0      | $f_{ASK} \text{ on} \rightarrow f_{ASK} \text{ off}$ | 0                        | X                     |
|      |           | 1      | $f_{ASK} \text{ on}$                                 | —                        | 1                     |
|      |           | 1      | $f_{ASK} \text{ off}$                                | —                        | 0                     |

### 9.1.8 Recommended Lim\_min and Lim\_max for Maximum Sensitivity

The sensitivity measurements in the section “Low-IF Receiver” in [Table 3-3 on page 11](#) and [Table 3-4 on page 11](#) have been done with the Lim\_min and Lim\_max values according to [Table 9-3](#). These values are optimized for maximum sensitivity. Note that since these limits are optimized for sensitivity, the number of checked bits,  $N_{\text{Bit-check}}$ , has to be at least 6 to prevent the circuit from waking up to often in polling mode due to noise.

**Table 9-3. Recommended Lim\_min and Lim\_max Values for Different Bit Rates**

| $f_{\text{RF}} (f_{\text{XTAL}})$<br>MHz | 1.0 Kbit/s<br>BR_Range_0<br>XLim = 1                     | 2.4 Kbit/s<br>BR_Range_0<br>XLim = 0                     | 5 Kbit/s<br>BR_Range_1<br>XLim = 0                      | 10 Kbit/s<br>BR_Range_2<br>XLim = 0                    | 20 Kbit/s<br>BR_Range_3<br>XLim = 0                    |
|------------------------------------------|----------------------------------------------------------|----------------------------------------------------------|---------------------------------------------------------|--------------------------------------------------------|--------------------------------------------------------|
| 433.92<br>(13.25311)                     | Lim_min = 13 (251 $\mu$ s)<br>Lim_max = 38 (715 $\mu$ s) | Lim_min = 12 (116 $\mu$ s)<br>Lim_max = 34 (319 $\mu$ s) | Lim_min = 11 (53 $\mu$ s)<br>Lim_max = 32 (150 $\mu$ s) | Lim_min = 11 (27 $\mu$ s)<br>Lim_max = 32 (75 $\mu$ s) | Lim_min = 11 (13 $\mu$ s)<br>Lim_max = 32 (37 $\mu$ s) |
| 868.3<br>(13.41191)                      | Lim_min = 13 (248 $\mu$ s)<br>Lim_max = 38 (706 $\mu$ s) | Lim_min = 12 (115 $\mu$ s)<br>Lim_max = 34 (315 $\mu$ s) | Lim_min = 11 (52 $\mu$ s)<br>Lim_max = 32 (148 $\mu$ s) | Lim_min = 11 (26 $\mu$ s)<br>Lim_max = 32 (74 $\mu$ s) | Lim_min = 11 (13 $\mu$ s)<br>Lim_max = 32 (37 $\mu$ s) |

## 9.2 TX Operation

The transceiver is set to TX operation by using the bits OPM0 and OPM1 in the control register 1.

**Table 9-4. Control Register 1**

| OPM1 | OPM0 | Function |
|------|------|----------|
| 0    | 1    | TX mode  |

Before activating TX mode, the TX parameters (bit rate, modulation scheme, etc.) must be selected as illustrated in [Figure 9-11 on page 55](#). The bit rate depends on Baud 0 and Baud 1 in control register 6, Lim\_min0 to Lim\_min5 in control register 5 and XLIM in control register 4 (see section “Control Register” on page 32). The modulation is selected with ASK/\_NFSK in control register 4. The FSK frequency deviation is fixed to about  $\pm 16$ kHz. If P\_Mode is set to “1”, the Manchester modulator is disabled and pattern mode is active (NRZ, see [Table 9-5 on page 57](#)).

After the transceiver is set to TX mode, the start-up mode is active and the PLL is enabled. If the PLL is locked, the TX mode is active.

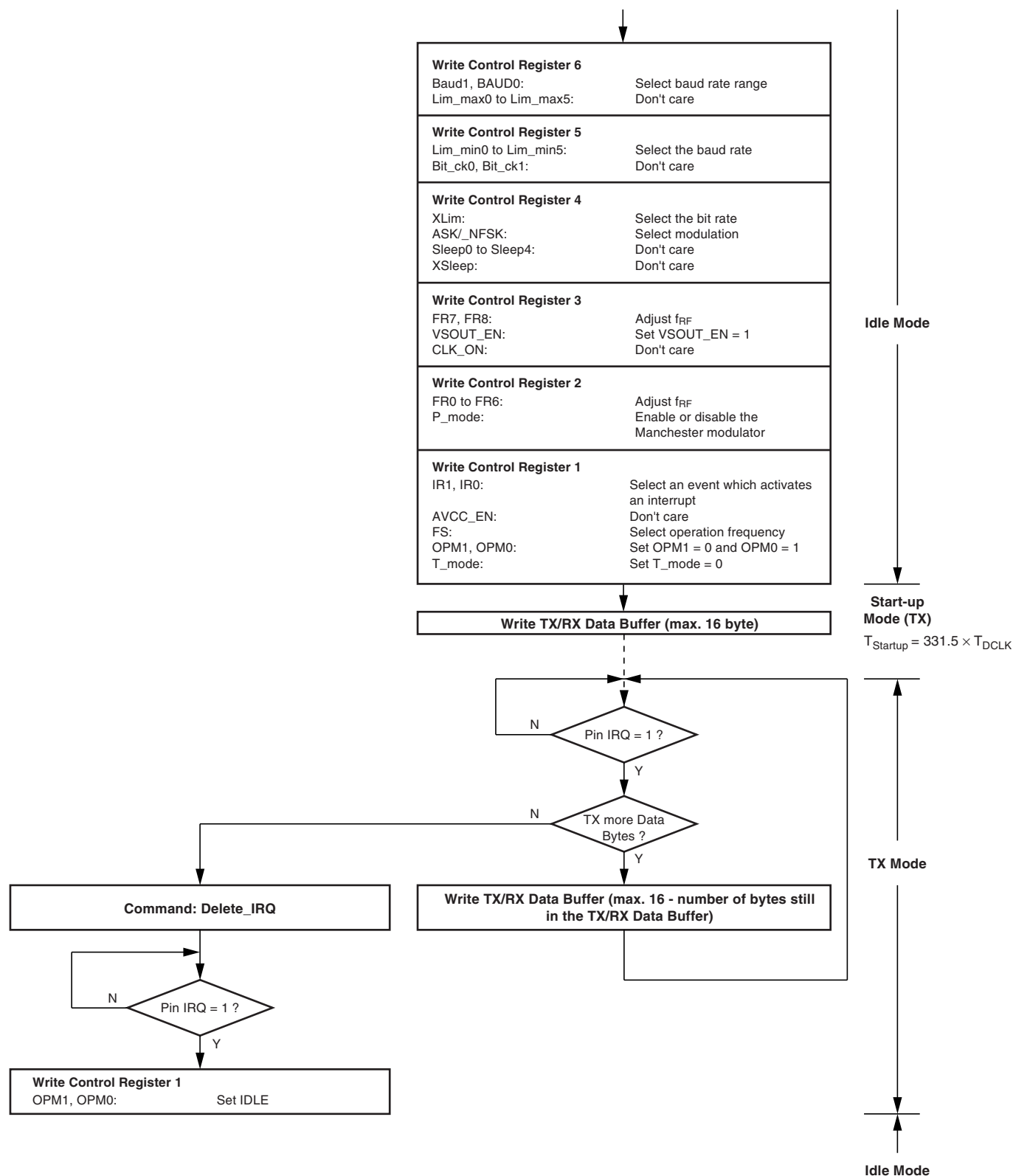
If the transceiver is in start-up or TX mode, the TX/RX data buffer can be loaded via the 4-wire serial interface. After the first byte is in the buffer and the TX mode is active, the transceiver starts transmitting automatically (beginning with the MSB). While transmitting it is always possible to load new data in the TX/RX data buffer. To prevent a buffer overflow or interruptions during transmitting, the user must ensure that data is loaded at the same speed as it is transmitted.

There is a counter that indicates the number of bytes to be transmitted (see section “Transceiver Configuration” on page 42). If a byte is loaded, the counter is incremented, if a byte is transmitted, the counter is decremented. The counter value is available via the 4-wire serial interface. An IRQ is issued if the counter (while counting down) reaches the value defined by the control bits IR0 and IR1 in control register 1.

**Note:** Writing to the control register 1, 4, 5 or 6 during TX mode resets the TX/RX data buffer and the counter which indicates the number of bytes to be transmitted.

If T\_Mode in control register 1 is set to “1”, the transceiver is in TX transparent mode. In this mode the TX/RX data buffer is disabled and the TX data stream must be applied on pin SDI\_TMDI. [Figure 9-11 on page 55](#) illustrates the flow chart of the TX transparent mode.

Figure 9-11. TX Operation (T\_MODE = 0)



**Figure 9-12. TX Transparent Mode (T\_MODE = 1)**

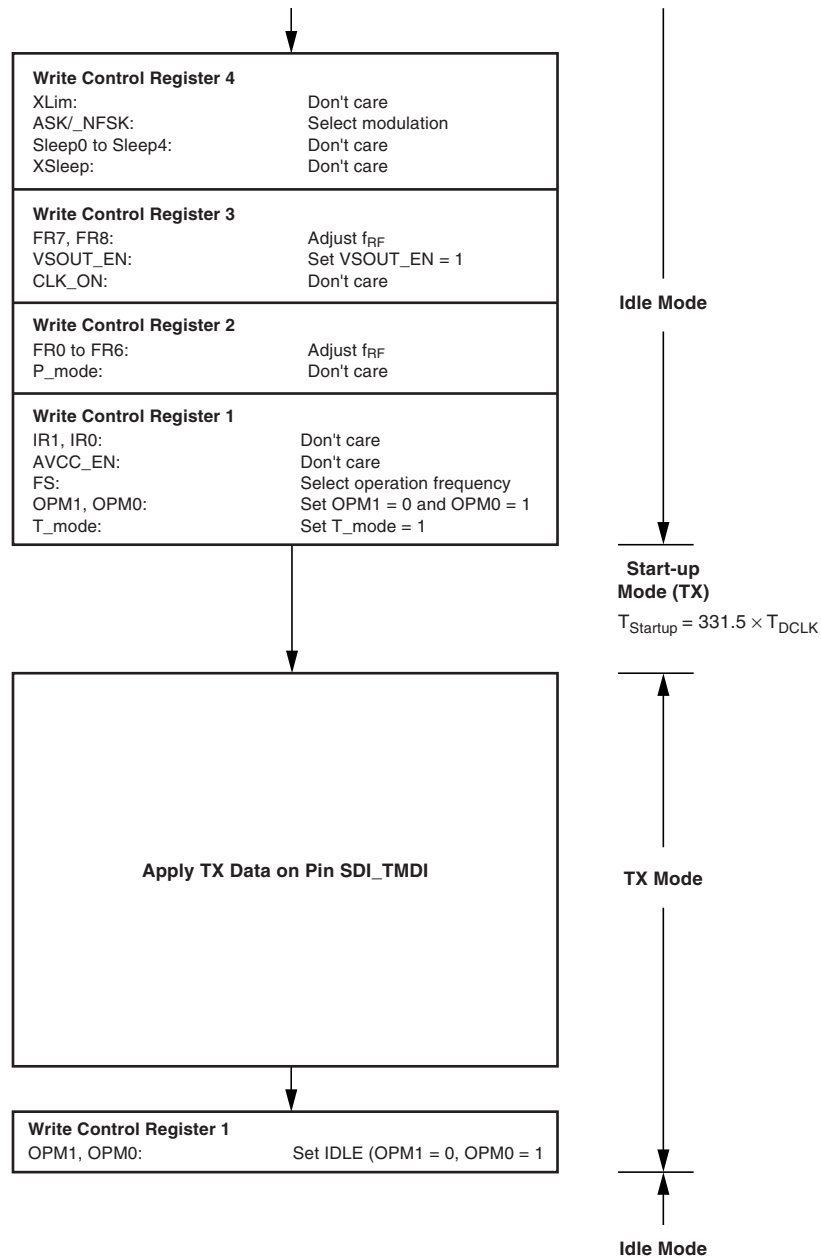


Table 9-5. TX Modulation Schemes

| Mode | ASK/_NFSK | P_Mode | T_Mode | Bit in TX/RX Data Buffer | Level on Pin SDI_TMDI | RF <sub>OUT</sub>                                    |
|------|-----------|--------|--------|--------------------------|-----------------------|------------------------------------------------------|
| TX   | 0         | 0      | 0      | 1                        | X                     | $f_{FSK\_L} \rightarrow f_{FSK\_H}$                  |
|      |           | 0      | 0      | 0                        | X                     | $f_{FSK\_H} \rightarrow f_{FSK\_L}$                  |
|      |           | 1      | 0      | 1                        | X                     | $f_{FSK\_H}$                                         |
|      |           | 1      | 0      | 0                        | X                     | $f_{FSK\_L}$                                         |
|      |           | X      | 1      | X                        | 1                     | $f_{FSK\_H}$                                         |
|      |           | X      | 1      | X                        | 0                     | $f_{FSK\_L}$                                         |
|      | 1         | 0      | 0      | 1                        | X                     | $f_{ASK} \text{ off} \rightarrow f_{ASK} \text{ on}$ |
|      |           | 0      | 0      | 0                        | X                     | $f_{ASK} \text{ on} \rightarrow f_{ASK} \text{ off}$ |
|      |           | 1      | 0      | 1                        | X                     | $f_{ASK} \text{ on}$                                 |
|      |           | 1      | 0      | 0                        | X                     | $f_{ASK} \text{ off}$                                |
|      |           | X      | 1      | X                        | 1                     | $f_{ASK} \text{ on}$                                 |
|      |           | X      | 1      | X                        | 0                     | $f_{ASK} \text{ off}$                                |

### 9.3 Interrupts

Via pin IRQ, the transceiver signals different operating conditions to a connected microcontroller. If a specific operating condition occurs, pin IRQ is set to high.

If an interrupt occurs, it is recommended to delete the interrupt immediately by reading the status register, so that a further potential interrupt doesn't get lost. If the Interrupt pin doesn't switch to low by reading the status register, the interrupt was triggered by the RX/TX data buffer. In this case read or write the RX/TX data buffer according to [Table 9-6](#).

Table 9-6. Interrupt Handling

| Operating Conditions Which Set Pin IRQ to High Level                                                                                 | Operations Which Set Pin IRQ to Low Level                                                                                                                                               |
|--------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Events in Status Register                                                                                                            |                                                                                                                                                                                         |
| State transition of status bit STn<br>(0 → 1; 1 → 0)                                                                                 | Read status register or<br>Command Delete IRQ                                                                                                                                           |
| Appearance of status bit Power_On<br>(0 → 1)                                                                                         |                                                                                                                                                                                         |
| Appearance of status bit P_On_Aux<br>(0 → 1)                                                                                         |                                                                                                                                                                                         |
| Events During TX Operation (T_MODE = 0)                                                                                              |                                                                                                                                                                                         |
| 4, 8 or 12 Bytes are in the TX data buffer or the TX data buffer is empty (depends on IR0 and IR1 in control register 1).            | Write TX data buffer or<br>Write control register 1 or<br>Write control register 4 or<br>Write control register 5 or<br>Write control register 6 or<br>Command delete IRQ               |
| Events During RX Operation (T_MODE = 0)                                                                                              |                                                                                                                                                                                         |
| 4, 8 or 12 received bytes are in the RX data buffer or a receiving error is occurred (depends on IR0 and IR1 in control register 1). | Read RX data buffer <sup>(1)</sup> or<br>Write control register 1 or<br>Write control register 4 or<br>Write control register 5 or<br>Write control register 6 or<br>Command delete IRQ |
| Successful bit check (P_MODE = 0)                                                                                                    |                                                                                                                                                                                         |

Note: 1. During reading of the RX/TX buffer, no IRQ is issued, due to the received bytes or a receiving error.

## 10. Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Parameters                                                                 | Symbol         | Min. | Max.  | Unit |
|----------------------------------------------------------------------------|----------------|------|-------|------|
| Junction temperature                                                       | $T_j$          |      | 150   | °C   |
| Storage temperature                                                        | $T_{stg}$      | −55  | +125  | °C   |
| Ambient temperature                                                        | $T_{amb}$      | −40  | +85   | °C   |
| Supply voltage VS2                                                         | $V_{MaxVS2}$   | −0.3 | +7.2  | V    |
| Supply voltage VS1                                                         | $V_{MaxVS1}$   | −0.3 | +4    | V    |
| Supply voltage VAUX                                                        | $V_{MaxVAUX}$  | −0.3 | +7.2  | V    |
| Supply voltage VSINT                                                       | $V_{MaxVSINT}$ | −0.3 | +5.5  | V    |
| ESD (Human Body Model ESD S 5.1)<br>every pin                              | HBM            | −1.5 | + 1.5 | kV   |
| ESD (Machine Model JEDEC A115A)<br>every pin                               | MM             | −200 | +200  | V    |
| ESD (Field Induced Charge Device Model ESD<br>STM 5.3.1–1999)<br>every pin | FCDM           | −1   | +1    | kV   |
| Maximum input level, input matched to 50 $\Omega$                          | $P_{in\_max}$  |      | 10    | dBm  |

## 11. Thermal Resistance

| Parameters       | Symbol     | Value | Unit |
|------------------|------------|-------|------|
| Junction ambient | $R_{thJA}$ | 25    | K/W  |

## 12. Electrical Characteristics: General

This device is manufactured with an industrial (not automotive) grade process and process controls. Although this device may meet certain automotive grade criteria in performance, Atmel can not recommend that this device be used in any automotive application. All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$  (1-battery application),  $V_{VS2} = 6.0\text{V}$  (2-battery application) and  $V_{VS2} = V_{VAUX} = 5.0\text{V}$  (Base-station Application). Typical values are given at  $f_{RF} = 433.92\text{ MHz}$  unless otherwise specified. Details about current consumption, timing and digital pin properties can be found in the specific sections of the “Electrical Characteristics”.

| No.      | Parameters                   | Test Conditions                                                                                                                                                                                                                        | Pin <sup>(1)</sup> | Symbol                                                                                     | Min.  | Typ. | Max.  | Unit          | Type* |
|----------|------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------------------------------------------------------------------------------|-------|------|-------|---------------|-------|
| <b>1</b> | <b>RtX_TX_IDLE Mode</b>      |                                                                                                                                                                                                                                        |                    |                                                                                            |       |      |       |               |       |
| 1.1      | RF operating frequency range | ATA5428<br>$V_{433\_N868} = AVCC$                                                                                                                                                                                                      | 4, 10              | $f_{RF}$                                                                                   | 431.5 |      | 436.5 | MHz           | A     |
|          |                              | ATA5428<br>$V_{433\_N868} = GND$                                                                                                                                                                                                       | 4, 10              | $f_{RF}$                                                                                   | 862   |      | 872   | MHz           | A     |
| 1.2      | Supply current OFF mode      | $V_{VS1} = V_{VS2} = 3\text{V}$ ,<br>$V_{VSINT} = 0\text{V}$<br>(1 battery) and<br>$V_{VS2} = 6\text{V}$ (2 battery)<br>OFF mode is not available if<br>$V_{VS2} = V_{VAUX} = 5\text{V}$<br>$V_{VSINT} = 0\text{V}$ (base station)     |                    | $I_{S\_OFF}$                                                                               |       | < 10 |       | nA            | A     |
| 1.3      | Supply current IDLE mode     | $V_{VSOUT}$ disabled,<br>XTO running<br>$V_{VS1} = V_{VS2} = 3\text{V}$<br>(1 battery)                                                                                                                                                 |                    | $I_{S\_IDLE}$                                                                              |       | 220  |       | $\mu\text{A}$ | B     |
|          |                              | $V_{VS2} = 6\text{V}$ (2 battery)                                                                                                                                                                                                      |                    | $I_{S\_IDLE}$                                                                              |       | 310  |       | $\mu\text{A}$ | B     |
|          |                              | $V_{VS2} = V_{VAUX} = 5\text{V}$<br>(base station)                                                                                                                                                                                     |                    | $I_{S\_IDLE}$                                                                              |       | 310  |       | $\mu\text{A}$ | B     |
| 1.4      | System start-up time         | From OFF mode to IDLE mode including reset and XTO start-up (see <a href="#">Figure 7-4 on page 40</a> )<br>XTAL: $C_m = 5\text{fF}$ ,<br>$C_0 = 1.8\text{pF}$ , $R_m = 15\Omega$                                                      |                    | $T_{PWR\_ON\_IRQ\_1}$                                                                      |       | 0.3  |       | ms            | C     |
| 1.5      | RX start-up time             | From IDLE mode to receiving mode<br>$N_{\text{Bit-check}} = 3$<br>Bit rate = 20Kbit/s,<br>BR_Range_3<br>(see <a href="#">Figure 9-1 on page 47</a> , <a href="#">Figure 9-2 on page 48</a> and <a href="#">Figure 9-3 on page 49</a> ) |                    | $T_{\text{Startup\_PLL}} +$<br>$T_{\text{Startup\_Sig\_Proc}} +$<br>$T_{\text{Bit-check}}$ |       | 1.39 |       | ms            | A     |
| 1.6      | TX start-up time             | From IDLE mode to TX mode (see <a href="#">Figure 9-11 on page 55</a> )                                                                                                                                                                |                    | $T_{\text{Startup}}$                                                                       |       | 0.4  |       | ms            | A     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

This device is manufactured with an industrial (not automotive) grade process and process controls. Although this device may meet certain automotive grade criteria in performance, Atmel can not recommend that this device be used in any automotive application. All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$  (1-battery application),  $V_{VS2} = 6.0\text{V}$  (2-battery application) and  $V_{VS2} = V_{VAUX} = 5.0\text{V}$  (Base-station Application). Typical values are given at  $f_{RF} = 433.92\text{ MHz}$  unless otherwise specified. Details about current consumption, timing and digital pin properties can be found in the specific sections of the “Electrical Characteristics”.

| No.                       | Parameters                                                                                        | Test Conditions                                                                                                                                                                                     | Pin <sup>(1)</sup> | Symbol              | Min.   | Typ.   | Max.   | Unit          | Type* |
|---------------------------|---------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------------|--------|--------|--------|---------------|-------|
| <b>2 Receiver/RX Mode</b> |                                                                                                   |                                                                                                                                                                                                     |                    |                     |        |        |        |               |       |
| 2.1                       | Supply current RX mode                                                                            | $f_{RF} = 433.92\text{MHz}$                                                                                                                                                                         | 17, 18             | $I_{S\_RX}$         |        | 10.5   |        | mA            | A     |
|                           |                                                                                                   | $f_{RF} = 868\text{MHz}$                                                                                                                                                                            | 17, 18             | $I_{S\_RX}$         |        | 10.3   |        | mA            | A     |
| 2.2                       | Supply current RX polling mode                                                                    | $T_{Sleep} = 49.45\text{ms}$<br>$X_{SLEEP} = 8$ , Sleep = 5<br>Bit rate = 20Kbit/s FSK,<br>$V_{VSOUT}$ disabled                                                                                     | 17, 18             | $I_P$               |        | 444    |        | $\mu\text{A}$ | B     |
| 2.3                       | Input sensitivity FSK<br>$f_{RF} = 433.92\text{MHz}$                                              | FSK deviation<br>$f_{DEV} = \pm 16\text{kHz}$<br>limits according to<br><a href="#">Table 9-3 on page 54</a> ,<br>$BER = 10^{-3}$<br>$T_{amb} = 25^{\circ}\text{C}$                                 |                    |                     |        |        |        |               |       |
|                           |                                                                                                   | Bit rate 20Kbit/s                                                                                                                                                                                   | (4)                | $P_{REF\_FSK}$      | -104.0 | -106.0 | -107.5 | dBm           | B     |
|                           |                                                                                                   | Bit rate 2.4bit/s                                                                                                                                                                                   | (4)                | $P_{REF\_FSK}$      | -107.5 | -109.5 | -111.0 | dBm           | B     |
| 2.4                       | Input sensitivity ASK<br>$f_{RF} = 433.92\text{MHz}$                                              | ASK 100%, level of<br>carrier limits according<br>to <a href="#">Table 9-3 on page 54</a> ,<br>$BER = 10^{-3}$<br>$T_{amb} = 25^{\circ}\text{C}$                                                    |                    |                     |        |        |        |               |       |
|                           |                                                                                                   | Bit rate 10Kbit/s                                                                                                                                                                                   | (4)                | $P_{REF\_ASK}$      | -110.5 | -112.5 | -114.0 | dBm           | B     |
|                           |                                                                                                   | Bit rate 2.4Kbit/s                                                                                                                                                                                  | (4)                | $P_{REF\_ASK}$      | -114.5 | -116.5 | -118.0 | dBm           | B     |
| 2.5                       | Sensitivity change at<br>$f_{RF} = 868.3\text{MHz}$<br>compared to<br>$f_{RF} = 433.92\text{MHz}$ | $f_{RF} = 433.92\text{ MHz}$<br>to $f_{RF} = 868.3\text{ MHz}$<br>$P = P_{REF\_ASK} + \Delta P_{REF1} + \Delta P_{REF2}$<br>$P = P_{REF\_FSK} + \Delta P_{REF1} + \Delta P_{REF2}$                  | (4)                | $\Delta P_{REF1}$   |        | +2.7   |        | dB            | B     |
| 2.6                       | Maximum frequency<br>offset in FSK mode                                                           | Maximum frequency<br>difference of $f_{RF}$<br>between receiver and<br>transmitter in FSK<br>mode ( $f_{RF}$ is the center<br>frequency of the FSK<br>signal with<br>$f_{DEV} = \pm 16\text{kHz}$ ) | (4)                | $\Delta f_{OFFSET}$ | -58    |        | +58    | kHz           | B     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

This device is manufactured with an industrial (not automotive) grade process and process controls. Although this device may meet certain automotive grade criteria in performance, Atmel can not recommend that this device be used in any automotive application. All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$  (1-battery application),  $V_{VS2} = 6.0\text{V}$  (2-battery application) and  $V_{VS2} = V_{VAUX} = 5.0\text{V}$  (Base-station Application). Typical values are given at  $f_{RF} = 433.92\text{ MHz}$  unless otherwise specified. Details about current consumption, timing and digital pin properties can be found in the specific sections of the “Electrical Characteristics”.

| No.  | Parameters                                                              | Test Conditions                                                                                                                                                                                                        | Pin <sup>(1)</sup> | Symbol        | Min.     | Typ.        | Max.     | Unit     | Type* |
|------|-------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|---------------|----------|-------------|----------|----------|-------|
| 2.7  | Supported FSK frequency deviation                                       | With up to 2dB loss of sensitivity.<br>Note that the tolerable frequency offset is for $f_{DEV} = \pm 22\text{kHz}$ , 6kHz lower than for $f_{DEV} = \pm 16\text{kHz}$ hence $\Delta f_{OFFSET} \leq \pm 52\text{kHz}$ | (4)                | $f_{DEV}$     | $\pm 14$ | $\pm 16$    | $\pm 22$ | kHz      | B     |
| 2.8  | System noise figure                                                     | $f_{RF} = 433.92\text{MHz}$                                                                                                                                                                                            | (4)                | NF            |          | 7.0         |          | dB       | B     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             | (4)                | NF            |          | 9.7         |          | dB       | B     |
| 2.9  | Intermediate frequency                                                  | $f_{RF} = 433.92\text{MHz}$                                                                                                                                                                                            |                    | $f_{IF}$      |          | 223         |          | kHz      | A     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             |                    | $f_{IF}$      |          | 226         |          | kHz      | A     |
| 2.10 | System bandwidth                                                        | This value is for information only!<br>Note that for crystal and system frequency offset calculations, $\Delta f_{OFFSET}$ must be used.                                                                               | (4)                | SBW           |          | 185         |          | kHz      | A     |
| 2.11 | System outband 2nd-order input intercept point with respect to $f_{IF}$ | $\Delta f_{meas1} = 1,800\text{MHz}$<br>$\Delta f_{meas2} = 2,026\text{MHz}$<br>$f_{IF} = \Delta f_{meas2} - \Delta f_{meas1}$                                                                                         | (4)                | IIP2          |          | +50         |          | dBm      | C     |
| 2.12 | System outband 3rd-order input intercept point                          | $\Delta f_{meas1} = 1.8\text{MHz}$<br>$\Delta f_{meas2} = 3.6\text{MHz}$<br>$f_{RF} = 433.92\text{MHz}$                                                                                                                | (4)                | IIP3          |          | -21         |          | dBm      | C     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             | (4)                | IIP3          |          | -17         |          | dBm      | C     |
| 2.13 | System outband input 1dB compression point                              | $\Delta f_{meas1} = 1\text{MHz}$<br>$f_{RF} = 433.92\text{MHz}$                                                                                                                                                        | (4)                | I1dBCP        |          | -30         |          | dBm      | C     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             | (4)                | I1dBCP        |          | -27         |          | dBm      | C     |
| 2.14 | LNA input impedance                                                     | $f_{RF} = 433.92\text{ MHz}$                                                                                                                                                                                           | 4                  | $Z_{in\_LNA}$ |          | (32 - j169) |          | $\Omega$ | C     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             | 4                  | $Z_{in\_LNA}$ |          | (21 - j78)  |          | $\Omega$ | C     |
| 2.15 | Allowable peak RF input level, ASK and FSK                              | $\text{BER} < 10^{-3}$ ,<br>ASK: 100%                                                                                                                                                                                  | (4)                | $P_{IN\_max}$ |          | +10         | -10      | dBm      | C     |
|      |                                                                         | FSK: $f_{DEV} = \pm 16\text{kHz}$                                                                                                                                                                                      | (4)                | $P_{IN\_max}$ |          | +10         | -10      | dBm      | C     |
| 2.16 | LO spurious emission at LNA_IN                                          | $f < 1\text{GHz}$                                                                                                                                                                                                      | (4)                |               |          |             | -57      | dBm      | C     |
|      |                                                                         | $f > 1\text{GHz}$                                                                                                                                                                                                      | (4)                |               |          |             | -47      | dBm      | C     |
|      |                                                                         | $f_{RF} = 433.92\text{MHz}$                                                                                                                                                                                            | (4)                |               |          | -97         |          | dBm      | C     |
|      |                                                                         | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                             | (4)                |               |          | -84         |          | dBm      | C     |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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| No.  | Parameters                                | Test Conditions                                                                                                             | Pin <sup>(1)</sup> | Symbol                       | Min.    | Typ.         | Max.       | Unit       | Type* |
|------|-------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|--------------------|------------------------------|---------|--------------|------------|------------|-------|
| 2.17 | Image rejection                           | Within the complete image band                                                                                              | (4)                |                              | 20      | 30           |            | dB         | A     |
| 2.18 | Useful signal to interfering signal ratio | Peak level of useful signal to peak level of interferer for $\text{BER} < 10^{-3}$ with any modulation scheme of interferer |                    |                              |         |              |            |            |       |
|      |                                           | FSK BR_Ranges 0, 1, 2                                                                                                       | (4)                | $\text{SNR}_{\text{FSK0-2}}$ |         | 2            | 3          | dB         | B     |
|      |                                           | FSK BR_Range_3                                                                                                              | (4)                | $\text{SNR}_{\text{FSK3}}$   |         | 4            | 6          | dB         | B     |
|      |                                           | ASK ( $P_{\text{RF}} < P_{\text{RFIN\_High}}$ )                                                                             | (4)                | $\text{SNR}_{\text{ASK}}$    |         | 10           | 12         | dB         | B     |
| 2.19 | RSSI output                               | Dynamic range                                                                                                               | (4), 36            | $D_{\text{RSSI}}$            |         | 70           |            | dB         | A     |
|      |                                           | Lower level of range<br>$f_{\text{RF}} = 433.92\text{MHz}$<br>$f_{\text{RF}} = 868.3\text{MHz}$                             | (4), 36            | $P_{\text{RFIN\_Low}}$       |         | -115<br>-112 |            | dBm<br>dBm | A     |
|      |                                           | Upper level of range<br>$f_{\text{RF}} = 433.92\text{ MHz}$<br>$f_{\text{RF}} = 868.3\text{ MHz}$                           | (4), 36            | $P_{\text{RFIN\_High}}$      |         | -45<br>-42   |            | dBm<br>dBm | A     |
|      |                                           | Gain                                                                                                                        | (4), 36            |                              | 5.5     | 8.0          | 10.5       | mV/dB      | A     |
|      |                                           | Output voltage range                                                                                                        | (4), 36            | $\text{OV}_{\text{RSSI}}$    | 400     |              | 1100       | mV         | A     |
| 2.20 | Output resistance RSSI pin                | RX mode<br>TX mode                                                                                                          | 36                 | $R_{\text{RSSI}}$            | 8<br>32 | 10<br>40     | 12.5<br>50 | k $\Omega$ | C     |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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| No.                              | Parameters                                 | Test Conditions                                                                                                                                                                                                                                                                                                                                                                                             | Pin <sup>(1)</sup> | Symbol             | Min. | Typ.                       | Max. | Unit | Type* |
|----------------------------------|--------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------|------|----------------------------|------|------|-------|
| 2.21                             | Blocking                                   | Sensitivity (BER = $10^{-3}$ ) is reduced by 6dB if a continuous wave blocking signal at $\pm\Delta f$ is $\Delta P_{Block}$ higher than the useful signal level (bit rate = 20 bit/s, FSK, $f_{DEV} \pm 16\text{kHz}$ , Manchester code)                                                                                                                                                                   |                    |                    |      |                            |      |      |       |
|                                  |                                            | $f_{RF} = 433.92\text{MHz}$<br>$\Delta f \pm 0.75\text{MHz}$<br>$\Delta f \pm 1.0\text{MHz}$<br>$\Delta f \pm 1.5\text{MHz}$<br>$\Delta f \pm 5\text{MHz}$<br>$\Delta f \pm 10\text{MHz}$                                                                                                                                                                                                                   | (4)                | $\Delta P_{Block}$ |      | 55<br>59<br>62<br>68<br>70 |      | dBC  | C     |
|                                  |                                            | $f_{RF} = 868.3\text{MHz}$<br>$\Delta f \pm 0.75\text{MHz}$<br>$\Delta f \pm 1.0\text{MHz}$<br>$\Delta f \pm 1.5\text{MHz}$<br>$\Delta f \pm 5\text{MHz}$<br>$\Delta f \pm 10\text{MHz}$                                                                                                                                                                                                                    | (4)                | $\Delta P_{Block}$ |      | 50<br>53<br>57<br>67<br>69 |      | dBC  | C     |
|                                  |                                            |                                                                                                                                                                                                                                                                                                                                                                                                             |                    |                    |      |                            |      |      |       |
| 2.22                             | CDEM                                       | Capacitor connected to pin 37 (CDEM)                                                                                                                                                                                                                                                                                                                                                                        | 37                 |                    | -5%  | 15                         | +5%  | nF   | D     |
| <b>3 Power Amplifier/TX Mode</b> |                                            |                                                                                                                                                                                                                                                                                                                                                                                                             |                    |                    |      |                            |      |      |       |
| 3.1                              | Supply current TX mode power amplifier OFF | $f_{RF} = 868.3\text{MHz}$                                                                                                                                                                                                                                                                                                                                                                                  |                    | $I_{S\_TX\_PAOFF}$ |      | 6.50                       |      | mA   | A     |
|                                  |                                            | $f_{RF} = 433.92\text{MHz}$                                                                                                                                                                                                                                                                                                                                                                                 |                    | $I_{S\_TX\_PAOFF}$ |      | 6.95                       |      | mA   | A     |
| 3.2                              | Output power 1                             | $V_{VS1} = V_{VS2} = 3\text{V}$<br>$T_{amb} = 25^{\circ}\text{C}$<br>$V_{PWR\_H} = 0\text{V}$<br><br>$f_{RF} = 433.92\text{MHz}$<br>$R_{R\_PWR} = 56\text{k}\Omega$<br>$R_{Lopt} = 2.3\text{k}\Omega$<br><br>$f_{RF} = 868.3\text{MHz}$<br>$R_{R\_PWR} = 30\text{k}\Omega$<br>$R_{Lopt} = 1.3\text{k}\Omega$<br><br>RF_OUT matched to $R_{Lopt} //$<br>$j/(2 \times \pi \times f_{RF} \times 1.0\text{pF})$ | (10)               | $P_{REF1}$         | -2.5 | 0                          | +2.5 | dBm  | B     |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50Ω according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50Ω according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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| No. | Parameters                                  | Test Conditions                                                                                                                                                                                                                                                                                                                                                                                               | Pin <sup>(1)</sup> | Symbol             | Min. | Typ. | Max. | Unit | Type* |
|-----|---------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|--------------------|------|------|------|------|-------|
| 3.3 | Supply current TX mode power amplifier ON 1 | PA on/0 dBm                                                                                                                                                                                                                                                                                                                                                                                                   |                    |                    |      |      |      |      |       |
|     |                                             | $f_{RF} = 433.92\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                  | 17, 18             | $I_{S\_TX\_PAON1}$ |      | 8.6  |      | mA   | B     |
|     |                                             | $f_{RF} = 868.3\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                   | 17, 18             | $I_{S\_TX\_PAON1}$ |      | 9.6  |      | mA   | B     |
| 3.4 | Output power 2                              | $V_{VS1} = V_{VS2} = 3\text{V}$<br>$T_{amb} = 25^{\circ}\text{C}$<br>$V_{PWR\_H} = 0\text{V}$<br><br>$f_{RF} = 433.92\text{ MHz}$<br>$R_{R\_PWR} = 27\text{ k}\Omega$<br>$R_{Lopt} = 1.1\text{ k}\Omega$<br><br>$f_{RF} = 868.3\text{ MHz}$<br>$R_{R\_PWR} = 16\text{ k}\Omega$<br>$R_{Lopt} = 0.5\text{ k}\Omega$<br><br>RF_OUT matched to $R_{Lopt} // j/(2 \times \pi \times f_{RF} \times 1.0\text{ pF})$ | (10)               | $P_{REF2}$         | 3.5  | 5.0  | 6.5  | dBm  | B     |
|     |                                             |                                                                                                                                                                                                                                                                                                                                                                                                               |                    |                    |      |      |      |      |       |
|     |                                             |                                                                                                                                                                                                                                                                                                                                                                                                               |                    |                    |      |      |      |      |       |
| 3.5 | Supply current TX mode power amplifier ON 2 | PA on/5 dBm                                                                                                                                                                                                                                                                                                                                                                                                   |                    |                    |      |      |      |      |       |
|     |                                             | $f_{RF} = 433.92\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                  | 17, 18             | $I_{S\_TX\_PAON2}$ |      | 10.5 |      | mA   | B     |
|     |                                             | $f_{RF} = 868.3\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                   | 17, 18             | $I_{S\_TX\_PAON2}$ |      | 11.2 |      | mA   | B     |
| 3.6 | Output power 3                              | $V_{VS1} = V_{VS2} = 3\text{V}$<br>$T_{amb} = 25^{\circ}\text{C}$<br>$V_{PWR\_H} = AVCC$<br><br>$f_{RF} = 433.92\text{ MHz}$<br>$R_{R\_PWR} = 27\text{ k}\Omega$<br>$R_{Lopt} = 0.36\text{ k}\Omega$<br><br>$f_{RF} = 868.3\text{ MHz}$<br>$R_{R\_PWR} = 20\text{ k}\Omega$<br>$R_{Lopt} = 0.22\text{ k}\Omega$<br><br>RF_OUT matched to $R_{Lopt} // j/(2 \times \pi \times f_{RF} \times 1.0\text{ pF})$    | (10)               | $P_{REF3}$         | 8.5  | 10   | 11.5 | dBm  | B     |
|     |                                             |                                                                                                                                                                                                                                                                                                                                                                                                               |                    |                    |      |      |      |      |       |
|     |                                             |                                                                                                                                                                                                                                                                                                                                                                                                               |                    |                    |      |      |      |      |       |
| 3.7 | Supply current TX mode power amplifier ON 3 | PA on/10dBm                                                                                                                                                                                                                                                                                                                                                                                                   |                    |                    |      |      |      |      |       |
|     |                                             | $f_{RF} = 433.92\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                  | 17, 18             | $I_{S\_TX\_PAON3}$ |      | 15.8 |      | mA   | B     |
|     |                                             | $f_{RF} = 868.3\text{ MHz}$                                                                                                                                                                                                                                                                                                                                                                                   | 17, 18             | $I_{S\_TX\_PAON3}$ |      | 17.3 |      | mA   | B     |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to  $50\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to  $50\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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| No.  | Parameters                                                           | Test Conditions                                                                                                                                              | Pin <sup>(1)</sup> | Symbol                | Min.        | Typ.         | Max.        | Unit          | Type* |
|------|----------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-----------------------|-------------|--------------|-------------|---------------|-------|
| 3.8  | Output power variation for full temperature and supply voltage range | $T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$<br>$P_{out} = P_{REFX} + \Delta P_{REFX}$<br>$X = 1, 2$ or $3$<br>$V_{VS1} = V_{VS2} = 3.0\text{V}$ | (10)               | $\Delta P_{REF}$      |             | -0.8         | -1.5        | dB            | B     |
|      |                                                                      | $V_{VS1} = V_{VS2} = 2.7\text{V}$                                                                                                                            | (10)               | $\Delta P_{REF}$      |             |              | -2.5        | dB            | B     |
|      |                                                                      | $V_{VS1} = V_{VS2} = 2.4\text{V}$                                                                                                                            | (10)               | $\Delta P_{REF}$      |             |              | -3.5        | dB            | B     |
| 3.9  | Impedance RF_OUT in RX mode                                          | $f_{RF} = 433.92\text{MHz}$                                                                                                                                  | 10                 | $Z_{RF\_OUT\_RX}$     |             | (19 – j366)  |             | $\Omega$      | C     |
|      |                                                                      | $f_{RF} = 868.3\text{MHz}$                                                                                                                                   | 10                 | $Z_{RF\_OUT\_RX}$     |             | (2.8 – j141) |             | $\Omega$      | C     |
| 3.10 | Noise floor power amplifier                                          | at $\pm 10\text{MHz}$ /at 5dBm                                                                                                                               |                    |                       |             |              |             |               |       |
|      |                                                                      | $f_{RF} = 433.92\text{MHz}$                                                                                                                                  | (10)               | $L_{TX10M}$           |             | -126         |             | dBc/Hz        | C     |
|      |                                                                      | $f_{RF} = 868.3\text{MHz}$                                                                                                                                   | (10)               | $L_{TX10M}$           |             | -125         |             | dBc/Hz        | C     |
| 3.11 | ASK modulation rate                                                  | This corresponds to 10Kbit/s Manchester coding and 20Kbit/s NRZ coding                                                                                       |                    | $f_{Data\_ASK}$       | 1           |              | 10          | kHz           | C     |
| 4    | XTO                                                                  |                                                                                                                                                              |                    |                       |             |              |             |               |       |
| 4.1  | Pulling XTO due to XTO, $C_{L1}$ and $C_{L2}$ tolerances             | Pulling at nominal temperature and supply voltage<br>$f_{XTAL}$ = resonant frequency of the XTAL<br>$C_0 \geq 1.0\text{pF}$<br>$R_m \leq 120\Omega$          | 24, 25             |                       |             |              |             |               | A     |
|      |                                                                      | $C_m \leq 7.0\text{fF}$<br>$C_m \leq 14\text{fF}$                                                                                                            |                    | $\Delta f_{XTO1}$     | -50<br>-100 | $f_{XTAL}$   | +50<br>+100 | ppm           |       |
| 4.2  | Transconductance XTO at start                                        | At start-up; after start-up the amplitude is regulated to $V_{PPXTAL}$                                                                                       | 24, 25             | $g_{m, XTO}$          |             | 19           |             | ms            | B     |
| 4.3  | XTO start-up time                                                    | $C_0 \leq 2.2\text{pF}$<br>$C_m < 14\text{fF}$<br>$R_m \leq 120\Omega$                                                                                       | 24, 25             | $T_{PWR\_ON\_IRQ\_1}$ |             | 300          | 800         | $\mu\text{s}$ | A     |
| 4.4  | Maximum $C_0$ of XTAL                                                | Required for stable operation with internal load capacitors                                                                                                  | 24, 25             | $C_{0max}$            |             |              | 3.8         | pF            | D     |
| 4.5  | Internal capacitors                                                  | $C_{L1}$ and $C_{L2}$                                                                                                                                        | 24, 25             | $C_{L1}, C_{L2}$      | 14.8        | 18           | 21.2        | pF            | B     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

This device is manufactured with an industrial (not automotive) grade process and process controls. Although this device may meet certain automotive grade criteria in performance, Atmel can not recommend that this device be used in any automotive application. All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$  (1-battery application),  $V_{VS2} = 6.0\text{V}$  (2-battery application) and  $V_{VS2} = V_{VAUX} = 5.0\text{V}$  (Base-station Application). Typical values are given at  $f_{RF} = 433.92\text{ MHz}$  unless otherwise specified. Details about current consumption, timing and digital pin properties can be found in the specific sections of the “Electrical Characteristics”.

| No.  | Parameters                                                                                                  | Test Conditions                                                                                                                                                   | Pin <sup>(1)</sup> | Symbol            | Min. | Typ.                  | Max.   | Unit              | Type* |
|------|-------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-------------------|------|-----------------------|--------|-------------------|-------|
| 4.6  | Pulling of radio frequency $f_{RF}$ due to XTO, $C_{L1}$ and $C_{L2}$ versus temperature and supply changes | $1.0\text{pF} \leq C_0 \leq 2.2\text{pF}$<br>$C_m \leq 14.0\text{fF}$<br>$R_m \leq 120\Omega$<br>PLL adjusted with FREQ at nominal temperature and supply voltage | 4, 10              | $\Delta f_{XTO2}$ | -2   |                       | +2     | ppm               | C     |
| 4.7  | Amplitude XTAL after start-up                                                                               | $C_m = 5\text{fF}$ , $C_0 = 1.8\text{pF}$<br>$R_m = 15\Omega$<br>$V(\text{XTAL1}, \text{XTAL2})$ peak-to-peak value                                               | 24, 25             | $V_{PPXTAL}$      |      | 700                   |        | mVpp              | C     |
|      |                                                                                                             | $V(\text{XTAL1})$ peak-to-peak value                                                                                                                              | 24, 25             | $V_{PPXTAL}$      |      | 350                   |        | mVpp              | C     |
| 4.8  | Real part of XTO impedance at start-up                                                                      | $C_0 \leq 2.2\text{pF}$ , small signal start impedance, this value is important for crystal oscillator startup                                                    | 24, 25             | $\text{Re}_{XTO}$ |      | -2,000                | -1,500 | $\Omega$          | B     |
| 4.9  | Maximum series resistance $R_m$ of XTAL after start-up                                                      | $C_0 \leq 2.2\text{pF}$<br>$C_m \leq 14\text{fF}$                                                                                                                 | 24, 25             | $R_{m\_max}$      |      | 15                    | 120    | $\Omega$          | B     |
| 4.10 | Nominal XTAL load resonant frequency                                                                        | $f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                                                                                                         | 24, 25             | $f_{XTAL}$        |      | 113.25311<br>13.41191 |        | MHz<br>MHz<br>MHz | D     |
| 4.11 | External CLK frequency                                                                                      | $f_{RF} = 433.92\text{MHz}$<br>CLK division ratio = 3<br>CLK has nominal 50% duty cycle                                                                           | 30                 | $f_{CLK}$         |      | 4.418                 |        | MHz               | D     |
|      |                                                                                                             | $f_{RF} = 868.3\text{MHz}$<br>CLK division ratio = 3<br>CLK has nominal 50% duty cycle                                                                            | 30                 | $f_{CLK}$         |      | 4.471                 |        | MHz               | D     |
| 4.12 | DC voltage after start-up                                                                                   | $V_{DC}(\text{XTAL1}, \text{XTAL2})$<br>XTO running (IDLE mode, RX mode and TX mode)                                                                              | 24, 25             | $V_{DCXTO}$       | -150 | -30                   |        | mV                | C     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to  $50\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to  $50\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

This device is manufactured with an industrial (not automotive) grade process and process controls. Although this device may meet certain automotive grade criteria in performance, Atmel can not recommend that this device be used in any automotive application. All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$  (1-battery application),  $V_{VS2} = 6.0\text{V}$  (2-battery application) and  $V_{VS2} = V_{VAUX} = 5.0\text{V}$  (Base-station Application). Typical values are given at  $f_{RF} = 433.92\text{ MHz}$  unless otherwise specified. Details about current consumption, timing and digital pin properties can be found in the specific sections of the “Electrical Characteristics”.

| No.      | Parameters                  | Test Conditions                                                                                    | Pin <sup>(1)</sup> | Symbol                 | Min. | Typ.                       | Max. | Unit   | Type* |
|----------|-----------------------------|----------------------------------------------------------------------------------------------------|--------------------|------------------------|------|----------------------------|------|--------|-------|
| <b>5</b> | <b>Synthesizer</b>          |                                                                                                    |                    |                        |      |                            |      |        |       |
| 5.1      | Spurious TX mode            | At $\pm f_{CLK}$ , CLK enabled<br>$f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$        |                    | $SP_{TX}$              |      | -68<br>-70                 |      | dBC    | C     |
|          |                             | At $\pm f_{XTO}$<br>$f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                      |                    | $SP_{TX}$              |      | -66<br>-60                 |      | dBC    | C     |
| 5.2      | Spurious RX mode            | At $\pm f_{CLK}$ , CLK enabled<br>$f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$        |                    | $SP_{RX}$              |      | < -75<br>< -75             |      | dBC    | C     |
|          |                             | At $\pm f_{XTO}$<br>$f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                      |                    | $SP_{RX}$              |      | -75<br>-68                 |      | dBC    | C     |
| 5.3      | In loop phase noise TX mode | Measured at 20kHz distance to carrier<br>$f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$ |                    | $L_{TX20k}$            |      | -80<br>-75                 |      | dBC/Hz | A     |
| 5.4      | Phase noise at 1M RX mode   | $f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                                          |                    | $L_{RX1M}$             |      | -120<br>-113               |      | dBC/Hz | C     |
| 5.5      | Phase noise at 1M TX mode   | $f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                                          |                    | $L_{TX1M}$             |      | -111<br>-107               |      | dBC/Hz | C     |
| 5.6      | Phase noise at 10M RX mode  | Noise floor PLL                                                                                    |                    | $L_{RX10M}$            |      | -135                       |      | dBC/Hz | C     |
| 5.7      | Loop bandwidth PLL TX mode  | Frequency where the absolute value loop gain is equal to 1                                         |                    | $f_{Loop\_PLL}$        |      | 70                         |      | kHz    | B     |
| 5.8      | Frequency deviation TX mode | $f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                                          |                    | $f_{DEV\_TX}$          |      | $\pm 16.17$<br>$\pm 16.37$ |      | kHz    | D     |
| 5.9      | Frequency resolution        | $f_{RF} = 433.92\text{MHz}$<br>$f_{RF} = 868.3\text{MHz}$                                          | 4, 10              | $\Delta f_{Step\_PLL}$ |      | 808.9<br>818.6             |      | Hz     | D     |
| 5.10     | FSK modulation rate         | This correspond to 20Kbit/s Manchester coding and 40Kbit/s NRZ coding                              |                    | $f_{Data\_FSK}$        | 1    |                            | 20   | kHz    | B     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50Ω according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50Ω according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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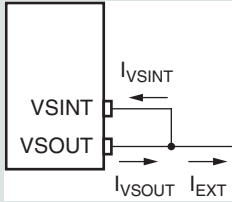
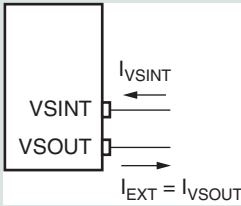
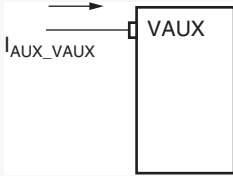
| No. | Parameters                                           | Test Conditions                                                                                                                                                          | Pin <sup>(1)</sup>                 | Symbol                 | Min.                                                                             | Typ.                         | Max. | Unit | Type* |
|-----|------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------|------------------------|----------------------------------------------------------------------------------|------------------------------|------|------|-------|
| 6   | RX/TX Switch                                         |                                                                                                                                                                          |                                    |                        |                                                                                  |                              |      |      |       |
| 6.1 | Impedance RX mode                                    | RX mode, pin 38 with short connection to GND, f <sub>RF</sub> = 0Hz (DC)                                                                                                 | 39                                 | Z <sub>Switch_RX</sub> |                                                                                  | 23000                        |      | Ω    | A     |
|     |                                                      | f <sub>RF</sub> = 433.92MHz<br>f <sub>RF</sub> = 868.3MHz                                                                                                                | 39                                 | Z <sub>Switch_RX</sub> |                                                                                  | (10.3 – j153)<br>(8.9 – j73) |      | Ω    | C     |
| 6.2 | Impedance TX mode                                    | TX mode, pin 38 with short connection to GND, f <sub>RF</sub> = 0Hz (DC)                                                                                                 | 39                                 | Z <sub>Switch_TX</sub> |                                                                                  | 5                            |      | Ω    | A     |
|     |                                                      | f <sub>RF</sub> = 433.92MHz<br>f <sub>RF</sub> = 868.3MHz                                                                                                                | 39                                 | Z <sub>Switch_RX</sub> |                                                                                  | (4.5 + j4.3)<br>(5 + j9)     |      | Ω    | C     |
| 7   | Microcontroller Interface                            |                                                                                                                                                                          |                                    |                        |                                                                                  |                              |      |      |       |
| 7.1 | Voltage range for microcontroller interface          | I <sub>VSINT</sub> < 10μA if CLK is disabled and all interface pins are in stable condition and unloaded                                                                 | 27, 28, 29, 30, 31, 32, 33, 34, 35 |                        | 2.4                                                                              |                              | 5.25 | V    | A     |
| 7.2 | CLK output rise and fall time                        | f <sub>CLK</sub> < 4.5MHz<br>C <sub>L</sub> = 10pF<br>C <sub>L</sub> = Load capacitance on pin CLK<br>2.4V ≤ V <sub>VSINT</sub> ≤ 5.25V<br>20% to 80% V <sub>VSINT</sub> | 30                                 | t <sub>rise</sub>      |                                                                                  | 20                           | 30   | ns   | B     |
|     |                                                      |                                                                                                                                                                          |                                    | t <sub>fall</sub>      |                                                                                  | 20                           | 30   | ns   |       |
| 7.4 | Current consumption of the microcontroller interface | CLK enabled<br>V <sub>VSOUT</sub> enabled                                                                                                                                | 27                                 | I <sub>VSINT</sub>     | I <sub>VSINT</sub> = $\frac{(C_{CLK} + C_L) \times V_{VSINT} \times f_{XTO}}{3}$ |                              |      |      |       |
|     |                                                      | CLK disabled<br>V <sub>VSOUT</sub> enabled                                                                                                                               |                                    |                        | < 10μA                                                                           |                              |      |      |       |
|     |                                                      | V <sub>VSOUT</sub> disabled                                                                                                                                              |                                    |                        | < 10μA                                                                           |                              |      |      |       |
|     |                                                      | C <sub>L</sub> = Load capacitance on pin CLK<br>(All interface pins, except pin CLK, are in stable condition and unloaded)                                               |                                    |                        |                                                                                  |                              |      |      |       |
| 7.5 | Internal equivalent capacitance                      | Used for current calculation                                                                                                                                             | 30, 27                             | C <sub>CLK</sub>       |                                                                                  | 8                            |      | pF   | B     |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

## 12. Electrical Characteristics: General (Continued)

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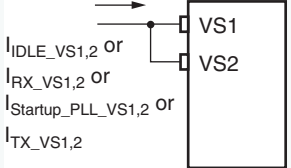
| No. | Parameters                                                       | Test Conditions                                                                                                                                                        | Pin <sup>(1)</sup> | Symbol          | Min. | Typ. | Max.                                                                                         | Unit                           | Type* |
|-----|------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-----------------|------|------|----------------------------------------------------------------------------------------------|--------------------------------|-------|
| 8   | Power Supply General Definitions and AUX Mode                    |                                                                                                                                                                        |                    |                 |      |      |                                                                                              |                                |       |
| 8.1 | Current consumption of an external device connected to pin VSOUT | <br> |                    | $I_{EXT}$       |      |      | $I_{EXT} = I_{VSOUT} - I_{VSINT}$<br>$I_{EXT} = I_{VSOUT}$                                   |                                |       |
| 8.2 | AUX mode                                                         |                                                                                                                                                                        |                    |                 |      |      |          |                                |       |
| 8.3 | Power supply output voltage                                      | AUX mode<br>$V_{VAUX} \geq 4\text{V}$<br>$I_{VSOUT} \leq 13.5\text{mA}$<br>(3.25V regulator mode, V_REG2, see <a href="#">Figure 5-1 on page 25</a> )                  | 22                 | $V_{VSOUT}$     | 2.7  |      | 3.5                                                                                          | V                              | A     |
| 8.4 | Current in AUX mode on pin VAUX                                  | $I_{VSOUT} = 0$<br>$V_{VAUX} = 6\text{V}$<br>$V_{VAUX} = 4\text{V to } 7\text{V}$                                                                                      | 19                 | $I_{AUX\_VAUX}$ |      | 380  | 500<br>500                                                                                   | $\mu\text{A}$<br>$\mu\text{A}$ | B     |
| 8.5 | Supply current AUX mode                                          | CLK enabled<br>$V_{VSOUT}$ enabled<br><br>CLK disabled<br>$V_{VSOUT}$ enabled                                                                                          | 19, 22,<br>27      | $I_{S\_AUX}$    |      |      | $I_{S\_AUX} = I_{AUX\_VAUX} + I_{VSINT} + I_{EXT}$<br>$I_{S\_AUX} = I_{AUX\_VAUX} + I_{EXT}$ |                                |       |
| 8.6 | Supported voltage range VAUX                                     |                                                                                                                                                                        | 19                 | $V_{VAUX}$      | 4    | 6    | 7                                                                                            | V                              |       |

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Note: 1. Pin numbers in brackets mean they were measured with RF\_IN matched to 50 $\Omega$  according to [Figure 3-1 on page 11](#) with component values according to [Table 3-2 on page 11](#) and RF\_OUT matched to 50 $\Omega$  according to [Figure 3-10 on page 18](#) with component values according to [Table 3-7 on page 19](#).

### 13. Electrical Characteristics: 1 Li Battery Application (3V)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$ . Application according to [Figure 2-1 on page 7](#).  
 $f_{RF} = 433.92\text{MHz}/868.3\text{MHz}$  unless otherwise specified

| No. | Parameters                                                     | Test Conditions                                                                                                                                                                                                                                                                                                            | Pin               | Symbol                                                                             | Min. | Typ. | Max.      | Unit | Type* |
|-----|----------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|------------------------------------------------------------------------------------|------|------|-----------|------|-------|
| 9   | 1 Li Battery Application (3V)                                  |                                                                                                                                                                                                                                                                                                                            |                   |  |      |      |           |      |       |
| 9.1 | Supported voltage range (every mode except high power TX mode) | 1 Li battery application (3V)<br>PWR_H = GND                                                                                                                                                                                                                                                                               | 17, 18            | $V_{VS1}, V_{VS2}$                                                                 | 2.4  |      | 3.6       | V    | A     |
| 9.2 | Supported voltage range (high power TX mode)                   | 1 Li battery application (3V)<br>PWR_H = AVCC                                                                                                                                                                                                                                                                              | 17, 18            | $V_{VS1}, V_{VS2}$                                                                 | 2.7  |      | 3.6       | V    | A     |
| 9.3 | Power supply output voltage                                    | 1 Li battery application (3V)<br>$V_{VS1} = V_{VS2} \geq 2.6V$<br>VAUX open <sup>(1)</sup><br>$I_{VSOUT} \leq 13.5mA$<br>(no voltage regulator to stabilize $V_{VSOUT}$ )<br><br>$V_{VS1} = V_{VS2} \geq 2.425V$<br>VAUX open <sup>(1)</sup><br>$I_{VSOUT} \leq 1.5mA$<br>(no voltage regulator to stabilize $V_{VSOUT}$ ) | 22                | $V_{VSOUT}$                                                                        | 2.4  |      | $V_{VS1}$ | V    | B     |
| 9.4 | Supply voltage for microcontroller interface                   |                                                                                                                                                                                                                                                                                                                            | 27                | $V_{VSINT}$                                                                        | 2.4  |      | 5.25      | V    | A     |
| 9.5 | Threshold hysteresis                                           | $V_{Thres\_2} - V_{Thres\_1}$                                                                                                                                                                                                                                                                                              | 22                | $\Delta V_{Thres}$                                                                 | 60   | 80   | 100       | mV   | B     |
| 9.6 | Reset threshold voltage at pin VSOUT (N_RESET)                 |                                                                                                                                                                                                                                                                                                                            | 22                | $V_{Thres\_1}$                                                                     | 2.18 | 2.3  | 2.42      | V    | A     |
| 9.7 | Reset threshold voltage at pin VSOUT (Low_Batt)                |                                                                                                                                                                                                                                                                                                                            | 22                | $V_{Thres\_2}$                                                                     | 2.26 | 2.38 | 2.5       | V    | A     |
| 9.8 | Supply current OFF mode                                        | $V_{VS1} = V_{VS2} \leq 3.6V$<br>$V_{VSINT} = 0V$                                                                                                                                                                                                                                                                          | 17, 18,<br>22, 27 | $I_{S\_OFF}$                                                                       |      | 2    | 350       | nA   | A     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. The voltage of VAUX may rise up to 2V. The current  $I_{VAUX}$  may not exceed 100 $\mu$ A.

### 13. Electrical Characteristics: 1 Li Battery Application (3V) (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS1} = V_{VS2} = 3.0\text{V}$ . Application according to [Figure 2-1 on page 7](#).  
 $f_{RF} = 433.92\text{MHz}/868.3\text{MHz}$  unless otherwise specified

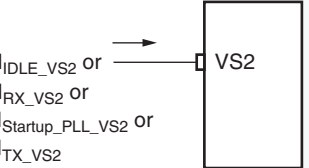
| No.  | Parameters                                           | Test Conditions                                                                                                                                                                                                                           | Pin            | Symbol                     | Min.                                                   | Typ. | Max. | Unit    | Type* |
|------|------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------|----------------------------|--------------------------------------------------------|------|------|---------|-------|
| 9.9  | Current in IDLE mode on pin VS1 and VS2              | $V_{VS1} = V_{VS2} \leq 3V$<br>$I_{VSOUT} = 0$                                                                                                                                                                                            | 17, 18         | $I_{IDLE\_VS1, 2}$         |                                                        |      |      |         |       |
|      |                                                      | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                        |                |                            |                                                        | 312  | 430  | $\mu A$ | A     |
|      |                                                      | CLK disabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                       |                |                            |                                                        | 260  | 370  | $\mu A$ | B     |
|      |                                                      | $V_{VSOUT}$ disabled                                                                                                                                                                                                                      |                |                            |                                                        | 225  | 320  | $\mu A$ | B     |
| 9.10 | Supply current IDLE mode                             |                                                                                                                                                                                                                                           | 17, 18, 22, 27 | $I_{S\_IDLE}$              | $I_{S\_IDLE} = I_{IDLE\_VS1, 2} + I_{VSINT} + I_{EXT}$ |      |      |         |       |
| 9.11 | Current in RX mode on pin VS1and VS2                 | $V_{VS1} = V_{VS2} \leq 3V$<br>$I_{VSOUT} = 0$                                                                                                                                                                                            | 17, 18         | $I_{RX\_VS1, 2}$           |                                                        | 10.5 | 14   | mA      | A     |
| 9.12 | Supply current RX mode                               | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                        | 17, 18, 22, 27 | $I_{S\_RX}$                | $I_{S\_RX} = I_{RX\_VS1, 2} + I_{VSINT} + I_{EXT}$     |      |      |         |       |
| 9.13 | Current during $T_{Startup\_PLL}$ on pin VS1 and VS2 | $V_{VS1} = V_{VS2} \leq 3V$<br>$I_{VSOUT} = 0$                                                                                                                                                                                            | 17, 18         | $I_{Startup\_PLL\_VS1, 2}$ |                                                        | 8.8  | 11.5 | mA      | C     |
| 9.14 | Current in RX polling mode on pin VS1 and VS2        | $I_P = \frac{I_{IDLE\_VS1, 2} \times T_{SLEEP} + I_{Startup\_PLL\_VS1, 2} \times T_{Startup\_PLL} + I_{RX\_VS1, 2} \times (T_{Startup\_Sig\_Proc} + T_{Bitcheck})}{T_{Sleep} + T_{Startup\_PLL} + T_{Startup\_Sig\_Proc} + T_{Bitcheck}}$ |                |                            |                                                        |      |      |         |       |
| 9.15 | Supply current RX polling mode                       | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                        | 17, 18, 22, 27 | $I_{S\_Poll}$              | $I_{S\_Poll} = I_P + I_{VSINT} + I_{EXT}$              |      |      |         |       |
|      |                                                      | CLK disabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                       |                |                            | $I_{S\_Poll} = I_P + I_{EXT}$                          |      |      |         |       |
|      |                                                      | $V_{VSOUT}$ disabled                                                                                                                                                                                                                      |                |                            | $I_{S\_Poll} = I_P$                                    |      |      |         |       |
| 9.16 | Current in TX mode on pin VS1 and VS2                | $V_{VS1} = V_{VS2} \leq 3V$<br>$I_{VSOUT} = 0$<br>Pout = 5dBm/10dBm                                                                                                                                                                       | 17, 18         | $I_{TX\_VS1\_VS2}$         |                                                        |      |      | mA      | B     |
|      |                                                      | 433.92MHz/5dBm                                                                                                                                                                                                                            |                |                            |                                                        | 10.4 | 13.5 |         |       |
|      |                                                      | 433.92MHz/10dBm                                                                                                                                                                                                                           |                |                            |                                                        | 15.8 | 20.6 |         |       |
|      |                                                      | 868.3MHz/5dBm                                                                                                                                                                                                                             |                |                            |                                                        | 10.5 | 13.5 |         |       |
|      |                                                      | 868.3MHz/10dBm                                                                                                                                                                                                                            |                |                            |                                                        | 15.8 | 20.5 |         |       |
|      |                                                      |                                                                                                                                                                                                                                           |                |                            |                                                        | 11.2 | 14.5 |         |       |
|      | 17.3                                                 | 22.5                                                                                                                                                                                                                                      |                |                            |                                                        |      |      |         |       |
| 9.17 | Supply current TX mode                               | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                        | 17, 18, 22, 27 | $I_{S\_TX}$                | $I_{S\_TX} = I_{TX\_VS1, 2} + I_{VSINT} + I_{EXT}$     |      |      |         |       |
|      |                                                      | CLK disabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                                       |                |                            | $I_{S\_TX} = I_{TX\_VS1, 2} + I_{EXT}$                 |      |      |         |       |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. The voltage of VAUX may rise up to 2V. The current  $I_{VAUX}$  may not exceed 100 $\mu\text{A}$ .

#### 14. Electrical Characteristics: 2 Li Battery Application (6V)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS2} = 6.0\text{V}$ . Application according to [Figure 2-3 on page 9](#)  
 $f_{RF} = 433.92\text{MHz}/868.3\text{MHz}$  unless otherwise specified

| No.  | Parameters                                      | Test Conditions                                                                                                                                                                 | Pin           | Symbol                                                                             | Min.                                                                                | Typ. | Max. | Unit | Type* |
|------|-------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------|------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|------|------|------|-------|
| 10   | 2 Li Battery Application (6V)                   |                                                                                                                                                                                 |               |  |                                                                                     |      |      |      |       |
| 10.1 | Supported voltage range                         | 2 Li battery application (6V)                                                                                                                                                   | 17            | V <sub>VS2</sub>                                                                   | 4.4                                                                                 |      | 6.6  | V    | A     |
| 10.2 | Power supply output voltage                     | 2 Li battery application (6V)<br>V <sub>VS2</sub> ≥ 4.4V<br>VAUX open <sup>(1)</sup><br>I <sub>VSOUT</sub> ≤ 13.5mA<br>(3.3V regulator mode, V_REG1, see Figure 5-1 on page 25) | 22            | V <sub>VSOUT</sub>                                                                 | 3.0                                                                                 |      | 3.5  | V    | A     |
| 10.3 | Supply voltage for microcontroller interface    |                                                                                                                                                                                 | 27            | V <sub>VSINT</sub>                                                                 | 2.4                                                                                 |      | 5.25 | V    | A     |
| 10.4 | Threshold hysteresis                            | V <sub>Thres_2</sub> – V <sub>Thres_1</sub>                                                                                                                                     | 22            | ΔV <sub>Thres</sub>                                                                | 60                                                                                  | 80   | 100  | mV   | B     |
| 10.5 | Reset threshold voltage at pin VSOUT (N_RESET)  |                                                                                                                                                                                 | 22            | V <sub>Thres_1</sub>                                                               | 2.18                                                                                | 2.3  | 2.42 | V    | A     |
| 10.6 | Reset threshold voltage at pin VSOUT (Low_Batt) |                                                                                                                                                                                 | 22            | V <sub>Thres_2</sub>                                                               | 2.26                                                                                | 2.38 | 2.5  | V    | A     |
| 10.7 | Supply current OFF mode                         | V <sub>VS2</sub> ≤ 6.6V<br>V <sub>VSINT</sub> = 0V                                                                                                                              | 17,<br>22, 27 | I <sub>S_OFF</sub>                                                                 |                                                                                     | 10   | 350  | nA   | A     |
| 10.8 | Current in IDLE mode on pin VS2                 | V <sub>VS2</sub> ≤ 6V<br>I <sub>VSOUT</sub> = 0                                                                                                                                 | 17            | I <sub>IDLE_VS2</sub>                                                              |                                                                                     |      |      |      |       |
|      |                                                 | CLK enabled<br>V <sub>VSOUT</sub> enabled                                                                                                                                       |               |                                                                                    |                                                                                     |      | 410  | 560  | μA    |
|      |                                                 | CLK disabled<br>V <sub>VSOUT</sub> enabled                                                                                                                                      |               |                                                                                    |                                                                                     |      | 348  | 490  | μA    |
|      |                                                 | V <sub>VSOUT</sub> disabled                                                                                                                                                     |               |                                                                                    |                                                                                     |      | 309  | 430  | μA    |
| 10.9 | Supply current IDLE mode                        |                                                                                                                                                                                 | 17,<br>22, 27 | I <sub>S_IDLE</sub>                                                                | I <sub>S_IDLE</sub> = I <sub>IDLE_VS2</sub> + I <sub>VSINT</sub> + I <sub>EXT</sub> |      |      |      |       |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. The voltage of VAUX may rise up to 2V. The current  $I_{VAUX}$  may not exceed 100 $\mu$ A.

## 14. Electrical Characteristics: 2 Li Battery Application (6V) (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS2} = 6.0\text{V}$ . Application according to [Figure 2-3 on page 9](#)  
 $f_{RF} = 433.92\text{MHz}/868.3\text{MHz}$  unless otherwise specified

| No.   | Parameters                                   | Test Conditions                                                                                                                                                                                                                  | Pin        | Symbol                  | Min.                                            | Typ.                         | Max.                         | Unit | Type* |
|-------|----------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------|-------------------------|-------------------------------------------------|------------------------------|------------------------------|------|-------|
| 10.10 | Current in RX mode on pin VS2                | $I_{VSOUT} = 0$                                                                                                                                                                                                                  | 17         | $I_{RX\_VS2}$           |                                                 | 10.8                         | 14.5                         | mA   | B     |
| 10.11 | Supply current RX mode                       | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                               | 17, 22, 27 | $I_{S\_RX}$             | $I_{S\_RX} = I_{RX\_VS2} + I_{VSINT} + I_{EXT}$ |                              |                              |      |       |
| 10.12 | Current during $T_{Startup\_PLL}$ on pin VS2 | $I_{VSOUT} = 0$                                                                                                                                                                                                                  | 17         | $I_{Startup\_PLL\_VS2}$ |                                                 | 9.1                          | 12                           | mA   | C     |
| 10.13 | Current in RX polling mode on pin VS2        | $I_P = \frac{I_{IDLE\_VS2} \times T_{SLEEP} + I_{Startup\_PLL\_VS2} \times T_{Startup\_PLL} + I_{RX\_VS2} \times (T_{Startup\_Sig\_Proc} + T_{Bitcheck})}{T_{Sleep} + T_{Startup\_PLL} + T_{Startup\_Sig\_Proc} + T_{Bitcheck}}$ |            |                         |                                                 |                              |                              |      |       |
| 10.14 | Supply current RX polling mode               | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                               | 17, 22, 27 | $I_{S\_Poll}$           | $I_{S\_Poll} = I_P + I_{VSINT} + I_{EXT}$       |                              |                              |      |       |
|       |                                              | CLK disabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                              |            |                         | $I_{S\_Poll} = I_P + I_{EXT}$                   |                              |                              |      |       |
|       |                                              | $V_{VSOUT}$ disabled                                                                                                                                                                                                             |            |                         | $I_{S\_Poll} = I_P$                             |                              |                              |      |       |
| 10.15 | Current in TX mode on pin VS2                | $I_{VSOUT} = 0$<br>$P_{out} = 5\text{dBm}/10\text{dBm}$<br>433.92MHz/5dBm<br>433.92MHz/10dBm<br>868.3MHz/5dBm<br>868.3MHz/10dBm                                                                                                  | 17, 19     | $I_{TX\_VS2}$           |                                                 | 10.9<br>16.3<br>11.6<br>17.8 | 14.0<br>21.0<br>15.0<br>23.0 | mA   | B     |
| 10.16 | Supply current TX mode                       | CLK enabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                               | 17, 22, 27 | $I_{S\_TX}$             | $I_{S\_TX} = I_{TX\_VS2} + I_{VSINT} + I_{EXT}$ |                              |                              |      |       |
|       |                                              | CLK disabled<br>$V_{VSOUT}$ enabled                                                                                                                                                                                              |            |                         | $I_{S\_TX} = I_{TX\_VS2} + I_{EXT}$             |                              |                              |      |       |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. The voltage of VAUX may rise up to 2V. The current  $I_{VAUX}$  may not exceed 100 $\mu\text{A}$ .



## 15. Electrical Characteristics: Base-station Application (5V) (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ ,  $V_{VS2} = 5.0\text{V}$ . Application according to [Figure 2.2 on page 8](#)  
 $f_{RF} = 433.92\text{MHz}/868.3\text{MHz}$  unless otherwise specified.

| No.   | Parameters                                                                                                                                                                                                                                                                                           | Test Conditions                                                                                                                  | Pin            | Symbol              | Min. | Typ.                                                                                                      | Max.                         | Unit | Type* |
|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------|----------------|---------------------|------|-----------------------------------------------------------------------------------------------------------|------------------------------|------|-------|
| 11.12 | Current in RX_Polling_Mode on pin VS2 and VAUX<br>$I_P = \frac{I_{IDLE\_VS2\_VAUX} \times T_{SLEEP} + I_{Startup\_PLL\_VS2\_VAUX} \times T_{Startup\_PLL} + I_{RX\_VS2\_VAUX} \times (T_{Startup\_Sig\_Proc} + T_{Bitcheck})}{T_{Sleep} + T_{Startup\_PLL} + T_{Startup\_Sig\_Proc} + T_{Bitcheck}}$ |                                                                                                                                  |                |                     |      |                                                                                                           |                              |      |       |
| 11.13 | Supply current in RX polling mode                                                                                                                                                                                                                                                                    | CLK enabled<br>$V_{VSOUT}$ enabled<br><br>CLK disabled<br>$V_{VSOUT}$ enabled<br><br>$V_{VSOUT}$ disabled                        | 17, 19, 22, 27 | $I_{S\_Poll}$       |      | $I_{S\_Poll} = I_P + I_{VSINT} + I_{EXT}$<br><br>$I_{S\_Poll} = I_P + I_{EXT}$<br><br>$I_{S\_Poll} = I_P$ |                              |      |       |
| 11.14 | Current in TX mode on pin VS2 and VAUX                                                                                                                                                                                                                                                               | $I_{VSOUT} = 0$<br>$P_{out} = 5\text{dBm}/10\text{dBm}$<br>433.92MHz/5dBm<br>433.92MHz/10dBm<br>868.3MHz/10dBm<br>868.3MHz/10dBm | 17, 19         | $I_{TX\_VS2\_VAUX}$ |      | 10.9<br>16.3<br>11.6<br>17.8                                                                              | 14.0<br>21.0<br>15.0<br>23.0 | mA   | B     |
| 11.15 | Supply current in TX mode                                                                                                                                                                                                                                                                            | CLK enabled<br>$V_{VSOUT}$ enabled<br>CLK disabled<br>$V_{VSOUT}$ enabled                                                        | 17, 19, 22, 27 | $I_{S\_TX}$         |      | $I_{S\_TX} = I_{TX\_VS2\_VAUX} + I_{VSINT} + I_{EXT}$<br><br>$I_{S\_TX} = I_{TX\_VS2\_VAUX} + I_{EXT}$    |                              |      |       |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## 16. Digital Timing Characteristics

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ .  $V_{VS1} = V_{S2} = 3.0\text{V}$  (1 Li battery application (3V)),  $V_{VS2} = 6.0\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 5.0\text{V}$  (Base-station Application(5V)) unless otherwise specified.

| No.       | Parameters                                        | Test Conditions                                                                                                                                                                                                                                                                                                                                                                       | Pin | Symbol                   | Min.                                                                       | Typ.                    | Max.                                                                       | Unit          | Type* |
|-----------|---------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|--------------------------|----------------------------------------------------------------------------|-------------------------|----------------------------------------------------------------------------|---------------|-------|
| <b>12</b> | <b>Basic Clock Cycle of the Digital Circuitry</b> |                                                                                                                                                                                                                                                                                                                                                                                       |     |                          |                                                                            |                         |                                                                            |               |       |
| 12.1      | Basic clock cycle                                 |                                                                                                                                                                                                                                                                                                                                                                                       |     | $T_{DCLK}$               | $16/f_{XTO}$                                                               |                         | $16/f_{XTO}$                                                               | $\mu\text{s}$ | A     |
| 12.2      | Extended basic clock cycle                        | XLIM = 0<br><br>BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3<br><br>XLIM = 1<br><br>BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3                                                                                                                                                                                                                                      |     | $T_{XDCLK}$              | 8<br>4<br>2<br>1<br>$\times T_{DCLK}$                                      |                         | 8<br>4<br>2<br>1<br>$\times T_{DCLK}$                                      | $\mu\text{s}$ | A     |
| <b>13</b> | <b>RX Mode/RX Polling Mode</b>                    |                                                                                                                                                                                                                                                                                                                                                                                       |     |                          |                                                                            |                         |                                                                            |               |       |
| 13.1      | Sleep time                                        | Sleep and XSleep are defined in control register 4                                                                                                                                                                                                                                                                                                                                    |     | $T_{Sleep}$              | $\text{Sleep} \times$<br>$X_{Sleep} \times$<br>$1024 \times$<br>$T_{DCLK}$ |                         | $\text{Sleep} \times$<br>$X_{Sleep} \times$<br>$1024 \times$<br>$T_{DCLK}$ | ms            | A     |
| 13.2      | Start-up PLL RX mode                              | from IDLE mode                                                                                                                                                                                                                                                                                                                                                                        |     | $T_{Startup\_PLL}$       |                                                                            | $798.5 \times T_{DCLK}$ | $798.5 \times T_{DCLK}$                                                    | $\mu\text{s}$ | A     |
| 13.3      | Start-up signal processing                        | BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3                                                                                                                                                                                                                                                                                                                                  |     | $T_{Startup\_Sig\_Proc}$ | 882<br>498<br>306<br>210<br>$\times T_{DCLK}$                              |                         | 882<br>498<br>306<br>210<br>$\times T_{DCLK}$                              |               | A     |
| 13.4      | Time for bit check                                | Average time during polling. No RF signal applied.<br>$f_{Signal} = 1/(2 \times t_{ee})$<br>Signal data rate<br>Manchester<br>(Lim_min and Lim_max up to $\pm 50\%$ of $t_{ee}$ , see <a href="#">Figure 9-4 on page 49</a> )<br><br>Bit-check time for a valid input signal $f_{Signal}$<br>$N_{Bit-check} = 0$<br>$N_{Bit-check} = 3$<br>$N_{Bit-check} = 6$<br>$N_{Bit-check} = 9$ |     | $T_{Bit\_check}$         | $3/f_{Signal}$<br>$6/f_{Signal}$<br>$9/f_{Signal}$                         | $1/f_{Signal}$          | $3.5/f_{Signal}$<br>$6.5/f_{Signal}$<br>$9.5/f_{Signal}$                   | ms            | C     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## 16. Digital Timing Characteristics (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ .  $V_{VS1} = V_{S2} = 3.0\text{V}$  (1 Li battery application (3V)),  $V_{VS2} = 6.0\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 5.0\text{V}$  (Base-station Application(5V)) unless otherwise specified.

| No.       | Parameters                                                                  | Test Conditions                                                                                                                                  | Pin    | Symbol             | Min.                     | Typ.                    | Max.                       | Unit          | Type* |
|-----------|-----------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------|--------|--------------------|--------------------------|-------------------------|----------------------------|---------------|-------|
| 13.5      | Bit-rate range                                                              | BR_Range =<br>BR_Range0<br>BR_Range1<br>BR_Range2<br>BR_Range3                                                                                   |        | BR_Range           | 1.0<br>2.0<br>4.0<br>8.0 |                         | 2.5<br>5.0<br>10.0<br>20.0 | Kbit/s        | A     |
| 13.6      | Minimum time period between edges at pin SDO_TMDO in RX transparent mode    | XLIM = 0<br><br>BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3<br><br>XLIM = 1<br><br>BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3 | 31     | $T_{DATA\_min}$    | $10 \times T_{XDCLK}$    |                         |                            | $\mu\text{s}$ | A     |
| 13.7      | Edge-to-edge time period of the data signal for full sensitivity in RX mode | BR_Range_0<br>BR_Range_1<br>BR_Range_2<br>BR_Range_3                                                                                             |        | $T_{DATA}$         | 200<br>100<br>50<br>25   |                         | 500<br>250<br>125<br>62.5  | $\mu\text{s}$ | B     |
| <b>14</b> | <b>TX Mode</b>                                                              |                                                                                                                                                  |        |                    |                          |                         |                            |               |       |
| 14.1      | Start-up time                                                               | From IDLE mode                                                                                                                                   |        | $T_{Startup}$      |                          | $331.5 \times T_{DCLK}$ | $331.5 \times T_{DCLK}$    | $\mu\text{s}$ | A     |
| <b>15</b> | <b>Configuration of the Transceiver with 4-wire Serial Interface</b>        |                                                                                                                                                  |        |                    |                          |                         |                            |               |       |
| 15.1      | CS set-up time to rising edge of SCK                                        |                                                                                                                                                  | 33, 35 | $T_{CS\_setup}$    | $1.5 \times T_{DCLK}$    |                         |                            | $\mu\text{s}$ | A     |
| 15.2      | SCK cycle time                                                              |                                                                                                                                                  | 33     | $T_{Cycle}$        | 2                        |                         |                            | $\mu\text{s}$ | A     |
| 15.3      | SDI_TMDO set-up time to rising edge of SCK                                  |                                                                                                                                                  | 32, 33 | $T_{Setup}$        | 250                      |                         |                            | ns            | C     |
| 15.4      | SDI_TMDO hold time from rising edge of SCK                                  |                                                                                                                                                  | 32, 33 | $T_{Hold}$         | 250                      |                         |                            | ns            | C     |
| 15.5      | SDO_TMDO enable time from rising edge of CS                                 |                                                                                                                                                  | 31, 35 | $T_{Out\_enable}$  |                          |                         | 250                        | ns            | C     |
| 15.6      | SDO_TMDO output delay from falling edge of SCK                              | $C_L = 10\text{ pF}$                                                                                                                             | 31, 35 | $T_{Out\_delay}$   |                          |                         | 250                        | ns            | C     |
| 15.7      | SDO_TMDO disable time from falling edge of CS                               |                                                                                                                                                  | 31, 33 | $T_{Out\_disable}$ |                          |                         | 250                        | ns            | C     |
| 15.8      | CS disable time period                                                      |                                                                                                                                                  | 35     | $T_{CS\_disable}$  | $1.5 \times T_{DCLK}$    |                         |                            | $\mu\text{s}$ | A     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## 16. Digital Timing Characteristics (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ .  $V_{VS1} = V_{S2} = 3.0\text{V}$  (1 Li battery application (3V)),  $V_{VS2} = 6.0\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 5.0\text{V}$  (Base-station Application(5V)) unless otherwise specified.

| No.       | Parameters                                                                                                                                               | Test Conditions                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | Pin    | Symbol                      | Min. | Typ. | Max. | Unit | Type* |
|-----------|----------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------|-----------------------------|------|------|------|------|-------|
| 15.9      | Time period SCK low to CS high                                                                                                                           |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | 33, 35 | $T_{\text{SCK\_setup1}}$    | 250  |      |      | ns   | C     |
| 15.10     | Time period SCK low to CS low                                                                                                                            |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | 33, 35 | $T_{\text{SCK\_setup2}}$    | 250  |      |      | ns   | C     |
| 15.11     | Time period CS low to SCK high                                                                                                                           |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | 33, 35 | $T_{\text{SCK\_hold}}$      | 250  |      |      | ns   | C     |
| <b>16</b> | <b>Start Time Push Button <math>T_n</math> and <math>\text{PWR\_ON}</math><br/>Timing of Wake-up via <math>\text{PWR\_ON}</math> or <math>T_n</math></b> |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |        |                             |      |      |      |      |       |
| 16.1      | $\text{PWR\_ON}$ high to positive edge on pin IRQ (see Figure 7-4 on page 40)                                                                            | <p>From OFF mode to IDLE mode, applications according to Figure 2-1 on page 7, Figure 2.2 on page 8 and Figure 2-3 on page 9</p> <p>XTAL:<br/> <math>C_m &lt; 14\text{fF}</math> (typ. 5fF)<br/> <math>C_0 &lt; 2.2\text{pF}</math> (typ. 1.8pF)<br/> <math>R_m \leq 120\Omega</math> (typ. 15<math>\Omega</math>)</p> <p>1 Li battery application (3V)<br/> <math>C_1 = C_2 = 68\text{nF}</math><br/> <math>C_3 = C_4 = 68\text{nF}</math><br/> <math>C_5 = 10\text{nF}</math></p> <p>2 Li battery application (6V)<br/> <math>C_1 = C_4 = 68\text{nF}</math><br/> <math>C_2 = C_3 = 2.2\mu\text{F}</math><br/> <math>C_5 = 10\text{nF}</math></p> <p>Base-station Application (5V)<br/> <math>C_1 = C_3 = C_4 = 68\text{nF}</math><br/> <math>C_2 = C_{12} = 2.2\mu\text{F}</math><br/> <math>C_5 = 10\text{nF}</math></p> | 29, 40 | $T_{\text{PWR\_ON\_IRQ}_1}$ |      | 0.3  | 0.8  | ms   | B     |
|           |                                                                                                                                                          |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |        |                             |      | 0.45 | 1.3  | ms   |       |
|           |                                                                                                                                                          |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |        |                             |      | 0.45 | 1.3  | ms   |       |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## 16. Digital Timing Characteristics (Continued)

All parameters refer to GND and are valid for  $T_{amb} = 25^{\circ}\text{C}$ .  $V_{VS1} = V_{S2} = 3.0\text{V}$  (1 Li battery application (3V)),  $V_{VS2} = 6.0\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 5.0\text{V}$  (Base-station Application(5V)) unless otherwise specified.

| No.  | Parameters                                                                           | Test Conditions                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 | Pin                    | Symbol                | Min.                   | Typ. | Max.                   | Unit          | Type* |
|------|--------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|-----------------------|------------------------|------|------------------------|---------------|-------|
| 16.2 | PWR_ON high to positive edge on pin IRQ (see <a href="#">Figure 7-4 on page 40</a> ) | Every mode except OFF mode                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | 29, 40                 | $T_{PWR\_ON\_IRQ\_2}$ |                        |      | $2 \times T_{DCLK}$    | $\mu\text{s}$ | A     |
| 16.3 | Tn low to positive edge on pin IRQ (see <a href="#">Figure 7-2 on page 38</a> )      | From OFF mode to IDLE mode, applications according to <a href="#">Figure 2-1 on page 7</a> , <a href="#">Figure 2.2 on page 8</a> and <a href="#">Figure 2-3 on page 9</a><br>XTAL:<br>$C_m < 14\text{ fF}$ (typ 5 fF)<br>$C_0 < 2.2\text{ pF}$ (typ 1.8 pF)<br>$R_m \leq 120\Omega$ (typ 15 $\Omega$ )<br><br>1 Li battery application (3V)<br>$C_1 = C_2 = 68\text{ nF}$<br>$C_3 = C_4 = 68\text{ nF}$<br>$C_5 = 10\text{ nF}$<br><br>2 Li battery application (6V)<br>$C_1 = C_4 = 68\text{ nF}$<br>$C_2 = C_3 = 2.2\text{ }\mu\text{F}$<br>$C_5 = 10\text{ nF}$<br><br>Base-station Application (5V)<br>$C_1 = C_3 = C_4 = 68\text{ nF}$<br>$C_2 = C_{12} = 2.2\text{ }\mu\text{F}$<br>$C_5 = 10\text{ nF}$ | 29, 41, 42, 43, 44, 45 | $T_{Tn\_IRQ}$         |                        | 0.3  | 0.8                    | ms            | B     |
|      |                                                                                      |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |                        |                       |                        | 0.45 | 1.3                    | ms            |       |
|      |                                                                                      |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |                        |                       |                        | 0.45 | 1.3                    | ms            |       |
| 16.4 | Push button debounce time                                                            | Every mode except OFF mode                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | 29, 41, 42, 43, 44, 45 | $T_{Debounce}$        | $8195 \times T_{DCLK}$ |      | $8195 \times T_{DCLK}$ | $\mu\text{s}$ | A     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

## 17. Digital Port Characteristics

All parameters refer to GND and are valid for  $T_{amb} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{VS1} = V_{S2} = 2.4\text{V}$  to  $3.6\text{V}$  (1 Li battery application (3V)) and  $V_{VS2} = 4.4\text{V}$  to  $6.6\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 4.75\text{V}$  to  $5.25\text{V}$  (Base-station Application (5V)). Typical values at  $V_{VS1} = V_{VS2} = 3\text{V}$  and  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified.

| No.                     | Parameters                                | Test Conditions                                                                             | Pin                | Symbol   | Min.                           | Typ. | Max.                   | Unit          | Type* |
|-------------------------|-------------------------------------------|---------------------------------------------------------------------------------------------|--------------------|----------|--------------------------------|------|------------------------|---------------|-------|
| <b>17 Digital Ports</b> |                                           |                                                                                             |                    |          |                                |      |                        |               |       |
| 17.1                    | CS input<br>Low level input voltage       | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 35                 | $V_{ll}$ |                                |      | $0.2 \times V_{VSINT}$ | V             | A     |
|                         | High level input voltage                  | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 35                 | $V_{lh}$ | $0.8 \times V_{VSINT}$         |      | $V_{VSINT}$            | V             | A     |
| 17.2                    | SCK input<br>Low level input voltage      | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 33                 | $V_{ll}$ |                                |      | $0.2 \times V_{VSINT}$ | V             | A     |
|                         | High level input voltage                  | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 33                 | $V_{lh}$ | $0.8 \times V_{VSINT}$         |      | $V_{VSINT}$            | V             | A     |
| 17.3                    | SDI_TMDI input<br>Low level input voltage | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 32                 | $V_{ll}$ |                                |      | $0.2 \times V_{VSINT}$ | V             | A     |
|                         | High level input voltage                  | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$                                                 | 32                 | $V_{lh}$ | $0.8 \times V_{VSINT}$         |      | $V_{VSINT}$            | V             | A     |
| 17.4                    | TEST1 input                               | TEST1 input must always be directly connected to GND                                        | 20                 |          | 0                              |      | 0                      | V             |       |
| 17.5                    | TEST2 input                               | TEST2 input must always be direct connected to GND                                          | 23                 |          | 0                              |      | 0                      | V             |       |
| 17.6                    | PWR_ON input<br>Low level input voltage   | Internal pull-down with series connection of $40\text{k}\Omega \pm 20\%$ resistor and diode | 40                 | $V_{ll}$ |                                |      | 0.4                    | V             | A     |
|                         | High level input voltage <sup>(1)</sup>   | Internal pull-down with series connection of $40\text{k}\Omega \pm 20\%$ resistor and diode | 40                 | $V_{lh}$ | $0.8 \times V_{VS2}$           |      |                        | V             | A     |
| 17.7                    | Tn input<br>Low level input voltage       | Internal pull-up resistor of $50\text{k}\Omega \pm 20\%$                                    | 41, 42, 43, 44, 45 | $V_{ll}$ |                                |      | $0.2 \times V_{VS2}$   | V             | A     |
|                         | High level input voltage <sup>(1)</sup>   | Internal pull-up resistor of $50\text{k}\Omega \pm 20\%$                                    | 41, 42, 43, 44, 45 | $V_{lh}$ | $\times V_{VS2} - 0.5\text{V}$ |      |                        | V             | A     |
| 17.8                    | 433_N868 input<br>Low level input voltage |                                                                                             | 6                  | $V_{ll}$ |                                |      | 0.25                   | V             | A     |
|                         | Input current low                         |                                                                                             | 6                  | $I_{ll}$ |                                |      | -5                     | $\mu\text{A}$ | A     |
|                         | High level input voltage                  |                                                                                             | 6                  | $V_{lh}$ | 1.7                            |      | AVCC                   | V             | A     |
|                         | Input current high                        |                                                                                             | 6                  | $I_{lh}$ |                                |      | 1                      | $\mu\text{A}$ | A     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. If a logic high level is applied to this pin, a minimum serial impedance of  $100\Omega$  must be ensured for proper operation over full temperature range.

## 17. Digital Port Characteristics (Continued)

All parameters refer to GND and are valid for  $T_{amb} = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{VS1} = V_{S2} = 2.4\text{V}$  to  $3.6\text{V}$  (1 Li battery application (3V)) and  $V_{VS2} = 4.4\text{V}$  to  $6.6\text{V}$  (2 Li battery application (6V)) and  $V_{VS2} = 4.75\text{V}$  to  $5.25\text{V}$  (Base-station Application (5V)). Typical values at  $V_{VS1} = V_{VS2} = 3\text{V}$  and  $T_{amb} = 25^{\circ}\text{C}$  unless otherwise specified.

| No.   | Parameters                                 | Test Conditions                                                                                                                                                             | Pin | Symbol   | Min.              | Typ.               | Max. | Unit          | Type* |
|-------|--------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|----------|-------------------|--------------------|------|---------------|-------|
| 17.9  | PWR_H input<br>Low level input voltage     |                                                                                                                                                                             | 9   | $V_{ll}$ |                   |                    | 0.25 | V             | A     |
|       | Input current low                          |                                                                                                                                                                             | 9   | $I_{ll}$ |                   |                    | -5   | $\mu\text{A}$ | A     |
|       | High level input voltage                   |                                                                                                                                                                             | 9   | $V_{lh}$ | 1.7               |                    | AVCC | V             | A     |
|       | Input current high                         |                                                                                                                                                                             | 9   | $I_{lh}$ |                   |                    | 1    | $\mu\text{A}$ | A     |
| 17.10 | SDO_TMDO output<br>Saturation voltage low  | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{SDO\_TMDO} = 250\mu\text{A}$                                                                                             | 31  | $V_{ol}$ |                   | 0.15               | 0.4  | V             | B     |
|       | Saturation voltage high                    | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{SDO\_TMDO} = -250\mu\text{A}$                                                                                            | 31  | $V_{oh}$ | $V_{VSINT} - 0.4$ | $V_{VSINT} - 0.15$ |      | V             | B     |
| 17.11 | IRQ output<br>Saturation voltage low       | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{IRQ} = 250\mu\text{A}$                                                                                                   | 29  | $V_{ol}$ |                   | 0.15               | 0.4  | V             | B     |
|       | Saturation voltage high                    | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{IRQ} = -250\mu\text{A}$                                                                                                  | 29  | $V_{oh}$ | $V_{VSINT} - 0.4$ | $V_{VSINT} - 0.15$ |      | V             | B     |
| 17.12 | CLK output<br>Saturation voltage low       | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{CLK} = 100\mu\text{A}$<br>internal series resistor<br>of $1\text{k}\Omega$ for spurious<br>emission reduction in<br>PLL  | 30  | $V_{ol}$ |                   | 0.15               | 0.4  | V             | B     |
|       | Saturation voltage high                    | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{CLK} = -100\mu\text{A}$<br>internal series resistor<br>of $1\text{k}\Omega$ for spurious<br>emission reduction in<br>PLL | 30  | $V_{oh}$ | $V_{VSINT} - 0.4$ | $V_{VSINT} - 0.15$ |      | V             | B     |
| 17.13 | N_RESET output<br>Saturation voltage low   | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{N\_RESET} = 250\mu\text{A}$                                                                                              | 28  | $V_{ol}$ |                   | 0.15               | 0.4  | V             | B     |
|       | Saturation voltage high                    | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{N\_RESET} = -250\mu\text{A}$                                                                                             | 28  | $V_{oh}$ | $V_{VSINT} - 0.4$ | $V_{VSINT} - 0.15$ |      | V             | B     |
| 17.14 | RX_ACTIVE output<br>Saturation voltage low | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{RX\_ACTIVE} = 25\mu\text{A}$                                                                                             | 46  | $V_{ol}$ |                   | 0.25               | 0.4  | V             | B     |
|       | Saturation voltage high                    | $V_{VSINT} = 2.4\text{V}$ to $5.25\text{V}$<br>$I_{RX\_ACTIVE} = -1500\mu\text{A}$                                                                                          | 46  | $V_{oh}$ | $V_{AVCC} - 0.5$  | $V_{AVCC} - 0.15$  |      | V             | B     |
| 17.15 | DEM_OUT output<br>Saturation voltage low   | Open drain output<br>$I_{DEM\_OUT} = 250\mu\text{A}$                                                                                                                        | 34  | $V_{ol}$ |                   | 0.15               | 0.4  | V             | B     |

\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

Note: 1. If a logic high level is applied to this pin, a minimum serial impedance of  $100\Omega$  must be ensured for proper operation over full temperature range.

## 18. Ordering Information

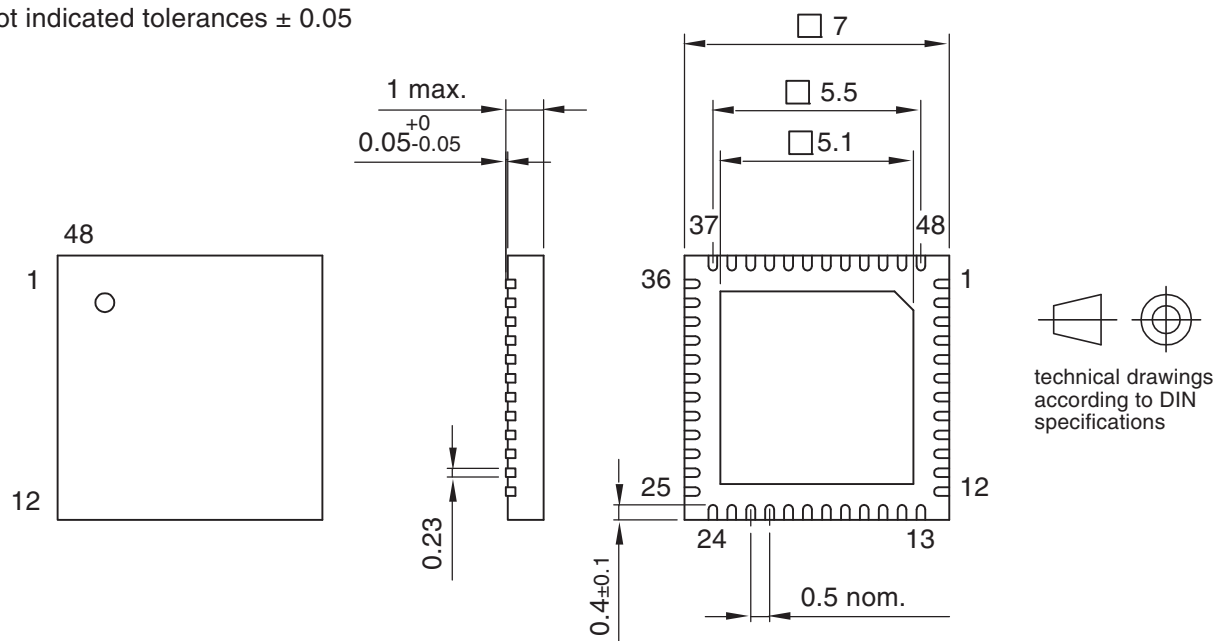
| Extended Type Number     | Package | Remarks     | Delivery                    |
|--------------------------|---------|-------------|-----------------------------|
| ATA5428-PLQW             | QFN48   | 7 mm × 7 mm | Taped and reeled + Dry pack |
| ATA5428-PLSW             | QFN48   | 7 mm × 7 mm | Tubes + Dry pack            |
| Note: W = RoHS compliant |         |             |                             |

## 19. Package Information

Package: QFN 48 - 7 x 7  
Exposed pad 5.1 x 5.1

Dimensions in mm

Not indicated tolerances  $\pm 0.05$



Drawing-No.: 6.543-5089.02-4

Issue: 1; 14.01.03

## 20. Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

| Revision No.     | History                                                                                                                                                                                                                   |
|------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 4841E-WIRE-03/12 | <ul style="list-style-type: none"><li>• Put datasheet in a new template</li><li>• Deleted all the cancelled Parts (ATA5423, ATA5425, ATA5429)</li></ul>                                                                   |
| 4841D-WIRE-10/07 | <ul style="list-style-type: none"><li>• Put datasheet in a new template</li></ul>                                                                                                                                         |
| 4841C-WIRE-05/06 | <ul style="list-style-type: none"><li>• Put datasheet in a new template</li><li>• kBaud replaced through Kbit/s</li><li>• Baud replaced through bit</li><li>• Table 9-6 "Interrupt Handling" on page 65 changed</li></ul> |

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**Atmel Corporation**

2325 Orchard Parkway  
San Jose, CA 95131  
USA

**Tel:** (+1) (408) 441-0311

**Fax:** (+1) (408) 487-2600

[www.atmel.com](http://www.atmel.com)

**Atmel Asia Limited**

Unit 01-5 & 16, 19F  
BEA Tower, Millennium City 5  
418 Kwun Tong Roa  
Kwun Tong, Kowloon  
HONG KONG

**Tel:** (+852) 2245-6100

**Fax:** (+852) 2722-1369

**Atmel Munich GmbH**

Business Campus  
Parking 4  
D-85748 Garching b. Munich  
GERMANY

**Tel:** (+49) 89-31970-0

**Fax:** (+49) 89-3194621

**Atmel Japan G.K.**

16F Shin-Osaki Kangyo Building  
1-6-4 Osaki  
Shinagawa-ku, Tokyo 141-0032  
JAPAN

**Tel:** (+81) (3) 6417-0300

**Fax:** (+81) (3) 6417-0370

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